



## MPC5646C



176-pin LQFP  
(24 mm x 24 mm)



208-pin LQFP  
(28 mm x 28 mm)



256 MAPBGA  
(17 mm x 17 mm)

# MPC5646C Microcontroller Datasheet

On-chip modules available within the family include the following features:

- e200z4d dual issue, 32-bit core Power Architecture® compliant CPU
  - Up to 120 MHz
  - 4 KB, 2/4-Way Set Associative Instruction Cache
  - Variable length encoding (VLE)
  - Embedded floating-point (FPU) unit
  - Supports Nexus3+
- e200z0h single issue, 32-bit core Power Architecture compliant CPU
  - Up to 80 MHz
  - Variable length encoding (VLE)
  - Supports Nexus3+
- Up to 3 MB on-chip flash memory: flash page buffers to improve access time
- Up to 256 KB on-chip SRAM
- 64 KB on-chip data flash memory to support EEPROM emulation
- Up to 16 semaphores across all slave ports
- User selectable MBIST
- Low-power modes supported: STOP, HALT, STANDBY
- 16 region Memory Protection Unit (MPU)
- Dual-core Interrupt Controller (INTC). Interrupt sources can be routed to e200z4d, e200z0h, or both
- Crossbar switch architecture for concurrent access to peripherals, flash memory, and SRAM from multiple bus masters
- 32 channel eDMA controller with DMAMUX
- Timer supports input/output channels providing 16-bit input capture, output compare, and PWM functions (eMIOS)
- 2 analog-to-digital converters (ADC): one 10-bit and one 12-bit
- Cross Trigger Unit (CTU) to enable synchronization of ADC conversions with a timer event from the eMIOS or from the PIT
- Up to 8 serial peripheral interface (DSPI) modules
- Up to 10 serial communication interface (LINFlex) modules
- Up to 6 full CAN (FlexCAN) modules with 64 MBs each
- CAN Sampler to catch ID of CAN message
- 1 inter IC communication interface ( $I^2C$ ) module
- Up to 177 (LQFP) or 199 (BGA) configurable general purpose I/O pins
- System clocks sources
  - 4–40 MHz external crystal oscillator
  - 16 MHz internal RC oscillator
  - FMPLL
  - Additionally, there are two low power oscillators: 128 kHz internal RC oscillator, 32 kHz external crystal oscillator

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# Table of Contents

1	Introduction . . . . .	.3	4.11.2 Electromagnetic interference (EMI) . . . . .	.63	
1.1	Document Overview . . . . .	.3	4.11.3 Absolute maximum ratings (electrical sensitivity)	.63	
1.2	Description . . . . .	.3	4.12 Fast external crystal oscillator (4–40 MHz)		
2	Block diagram . . . . .	.6	electrical characteristics . . . . .	.64	
3	Package pinouts and signal descriptions . . . . .	.9	4.13 Slow external crystal oscillator (32 kHz)		
3.1	Pad types . . . . .	.11	electrical characteristics . . . . .	.66	
3.2	System pins . . . . .	.12	4.14 FMPLL electrical characteristics . . . . .	.69	
3.3	Functional ports . . . . .	.12	4.15 Fast internal RC oscillator (16 MHz)		
4	Electrical Characteristics . . . . .	.38	electrical characteristics . . . . .	.69	
4.1	Parameter classification . . . . .	.38	4.16 Slow internal RC oscillator (128 kHz)		
4.2	NVUSRO register . . . . .	.39	electrical characteristics . . . . .	.70	
4.2.1	NVUSRO [PAD3V5V(0)] field description . . . . .	.39	4.17 ADC electrical characteristics . . . . .	.71	
4.2.2	NVUSRO [PAD3V5V(1)] field description . . . . .	.39	4.17.1 Introduction . . . . .	.71	
4.3	Absolute maximum ratings . . . . .	.39	4.18 Fast Ethernet Controller . . . . .	.81	
4.4	Recommended operating conditions . . . . .	.41	4.18.1 MII Receive Signal Timing (RXD[3:0], RX_DV, RX_ER, and RX_CLK) . . . . .	.81	
4.5	Thermal characteristics . . . . .	.44	4.18.2 MII Transmit Signal Timing (TXD[3:0], TX_EN, TX_ER, TX_CLK) . . . . .	.81	
4.5.1	Package thermal characteristics . . . . .	.44	4.18.3 MII Async Inputs Signal Timing (CRS and COL) . . . . .	.82	
4.5.2	Power considerations . . . . .	.44	4.18.4 MII Serial Management Channel Timing (MDIO and MDC) . . . . .	.82	
4.6	I/O pad electrical characteristics . . . . .	.45	4.19 On-chip peripherals . . . . .	.84	
4.6.1	I/O pad types . . . . .	.45	4.19.1 Current consumption . . . . .	.84	
4.6.2	I/O input DC characteristics . . . . .	.45	4.19.2 DSPI characteristics . . . . .	.86	
4.6.3	I/O output DC characteristics . . . . .	.46	4.19.3 Nexus characteristics . . . . .	.94	
4.6.4	Output pin transition times . . . . .	.49	4.19.4 JTAG characteristics . . . . .	.96	
4.6.5	I/O pad current specification . . . . .	.50	5	Package characteristics . . . . .	.98
4.7	RESET electrical characteristics . . . . .	.52	5.1	Package mechanical data . . . . .	.98
4.8	Power management electrical characteristics . . . . .	.54	5.1.1	176 LQFP package mechanical drawing . . . . .	.98
4.8.1	Voltage regulator electrical characteristics . . . . .	.54	5.1.2	208 LQFP package mechanical drawing . . . . .	.101
4.8.2	VDD_BV options . . . . .	.55	5.1.3	256 MAPBGA package mechanical drawing . . . . .	.106
4.8.3	Voltage monitor electrical characteristics . . . . .	.56	6	Ordering information . . . . .	.108
4.9	Low voltage domain power consumption . . . . .	.57	7	Revision history . . . . .	.109
4.10	Flash memory electrical characteristics . . . . .	.59			
4.10.1	Program/Erase characteristics . . . . .	.59			
4.10.2	Flash memory power supply DC characteristics	.61			
4.10.3	Flash memory start-up/switch-off timings . . . . .	.62			
4.11	Electromagnetic compatibility (EMC) characteristics . . . . .	.62			
4.11.1	Designing hardened software to avoid noise problems . . . . .	.62			

# 1 Introduction

## 1.1 Document Overview

This document describes the features of the family and options available within the family members, and highlights important electrical and physical characteristics of the MPC5646C device. To ensure a complete understanding of the device functionality, refer also to the MPC5646C Reference Manual.

## 1.2 Description

The MPC5646C is a new family of next generation microcontrollers built on the Power Architecture embedded category. This document describes the features of the family and options available within the family members, and highlights important electrical and physical characteristics of the device.

The MPC5646C family expands the range of the MPC560xB microcontroller family. It provides the scalability needed to implement platform approaches and delivers the performance required by increasingly sophisticated software architectures. The advanced and cost-efficient host processor core of the MPC5646C automotive controller family complies with the Power Architecture embedded category, which is 100 percent user-mode compatible with the original Power Architecture user instruction set architecture (UISA). It operates at speeds of up to 120 MHz and offers high performance processing optimized for low power consumption. It also capitalizes on the available development infrastructure of current Power Architecture devices and is supported with software drivers, operating systems and configuration code to assist with users implementations.

**Table 1. MPC5646C family comparison<sup>1</sup>**

Feature	MPC5644B			MPC5644C			MPC5645B		MPC5645C			MPC5646B			MPC5646C																
Package	176 LQFP	208 LQFP	176 LQFP	208 LQFP	256 BGA	176 LQFP	208 LQFP	176 LQFP	208 LQFP	256 BGA	176 LQFP	208 LQFP	176 LQFP	208 LQFP	256 BGA																
CPU	e200z4d	e200z4d + e200z0h			e200z4d	e200z4d + e200z0h			e200z4d	e200z4d + e200z0h			e200z4d	e200z4d + e200z0h																	
Execution speed <sup>2</sup>	Up to 120 MHz (e200z4d)		Up to 120 MHz (e200z4d) Up to 80 MHz (e200z0h) <sup>3</sup>		Up to 120 MHz (e200z4d)		Up to 120 MHz (e200z4d) Up to 80 MHz (e200z0h) <sup>3</sup>		Up to 120 MHz (e200z4d)		Up to 120 MHz (e200z4d) Up to 80 MHz (e200z0h) <sup>3</sup>		Up to 120 MHz (e200z4d) Up to 80 MHz (e200z0h) <sup>3</sup>																		
Code flash memory	1.5 MB				2 MB				3 MB																						
Data flash memory	4 x16 KB																														
SRAM	128 KB		192 KB			160 KB		256 KB			192 KB		256 KB																		
MPU	16-entry																														
eDMA <sup>4</sup>	32 ch																														
10-bit ADC	dedicated <sup>5,6</sup>	27 ch	33 ch	27 ch	33 ch	27 ch	33 ch	27 ch	33 ch	27 ch	33 ch	27 ch	33 ch	27 ch	33 ch	33 ch															
shared with 12-bit ADC <sup>7</sup>		19 ch																													
12-bit ADC	dedicated <sup>8</sup>	5 ch	10 ch	5 ch	10 ch	5 ch	10 ch	5 ch	10 ch	5 ch	10 ch	5 ch	10 ch	5 ch	10 ch	10 ch															
shared with 10-bit ADC <sup>7</sup>		19 ch																													
CTU	64 ch																														
Total timer I/O <sup>9</sup> eMIOS	64 ch, 16-bit																														
SCI (LINFlexD)	10																														
SPI (DSPI)	8																														
CAN (FlexCAN) <sup>10</sup>	6																														
FlexRay	Yes																														
STCU <sup>11</sup>	Yes																														
Ethernet	No	Yes			No	Yes			No	Yes																					

**Table 1. MPC5646C family comparison<sup>1</sup> (continued)**

Feature	MPC5644B			MPC5644C			MPC5645B			MPC5645C			MPC5646B			MPC5646C		
Package	176 LQFP	208 LQFP	176 LQFP	208 LQFP	256 BGA	176 LQFP	208 LQFP	176 LQFP	208 LQFP	256 BGA	176 LQFP	208 LQFP	176 LQFP	208 LQFP	176 LQFP	208 LQFP	256 BGA	
I <sup>2</sup> C																	1	
32 kHz oscillator (SXOSC)																	Yes	
GPIO <sup>12</sup>	147	177	147	177	199	147	177	147	177	199	147	177	147	177	147	177	199	
Debug	JTAG				Nexus 3+	JTAG				Nexus 3+	JTAG				Nexus 3+			
Cryptographic Services Engine (CSE)	Optional																	

<sup>1</sup> Feature set dependent on selected peripheral multiplexing; table shows example.

<sup>2</sup> Based on 125 °C ambient operating temperature and subject to full device characterization.

<sup>3</sup> The e200z0h can run at speeds up to 80 MHz. However, if system frequency is >80 MHz (e.g., e200z4d running at 120 MHz) the e200z0h needs to run at 1/2 system frequency. There is a configurable e200z0 system clock divider for this purpose.

<sup>4</sup> DMAMUX also included that allows for software selection of 32 out of a possible 57 sources.

<sup>5</sup> Not shared with 12-bit ADC, but possibly shared with other alternate functions.

<sup>6</sup> There are 23 dedicated ANS plus 4 dedicated ANX channels on LQPF176. For higher pin count packages, there are 29 dedicated ANS plus 4 dedicated ANX channels.

<sup>7</sup> 16x precision channels (ANP) and 3x standard (ANS).

<sup>8</sup> Not shared with 10-bit ADC, but possibly shared with other alternate functions.

<sup>9</sup> As a minimum, all timer channels can function as PWM or Input Capture and Output Control. Refer to the eMOS section of the device reference manual for information on the channel configuration and functions.

<sup>10</sup> CAN Sampler also included that allows ID of CAN message to be captured when in low power mode.

<sup>11</sup> STCU controls MBIST activation and reporting.

<sup>12</sup> Estimated I/O count for proposed packages based on multiplexing with peripherals.

## 2 Block diagram

Figure 1 shows the detailed block diagram of the MPC5646C.

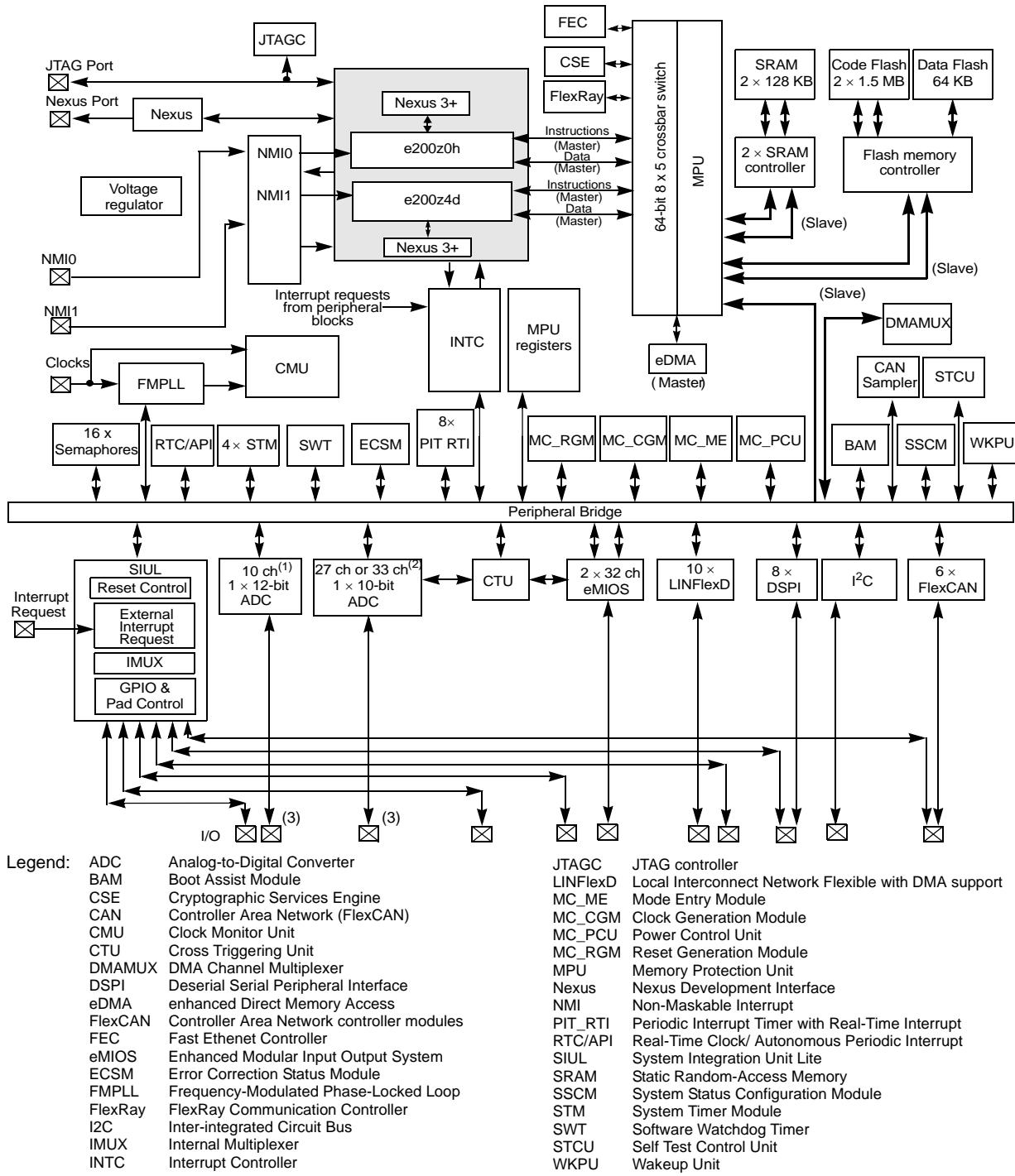


Figure 1. MPC5646C block diagram

Table 2 summarizes the functions of the blocks present on the MPC5646C.

**Table 2. MPC5646C series block summary**

Block	Function
Analog-to-digital converter (ADC)	Converts analog voltages to digital values
Boot assist module (BAM)	A block of read-only memory containing VLE code which is executed according to the boot mode of the device
Clock monitor unit (CMU)	Monitors clock source (internal and external) integrity
Cross triggering unit (CTU)	Enables synchronization of ADC conversions with a timer event from the eMOS or from the PIT
Cryptographic Security Engine (CSE)	Supports the encoding and decoding of any kind of data
Crossbar (XBAR) switch	Supports simultaneous connections between two master ports and three slave ports. The crossbar supports a 32-bit address bus width and a 64-bit data bus width
DMA Channel Multiplexer (DMAMUX)	Allows to route DMA sources (called slots) to DMA channels
Deserial serial peripheral interface (DSPI)	Provides a synchronous serial interface for communication with external devices
Error Correction Status Module (ECSM)	Provides a myriad of miscellaneous control functions for the device including program-visible information about configuration and revision levels, a reset status register, wakeup control for exiting sleep modes, and optional features such as information on memory errors reported by error-correcting codes
Enhanced Direct Memory Access (eDMA)	Performs complex data transfers with minimal intervention from a host processor via "n" programmable channels.
Enhanced modular input output system (eMOS)	Provides the functionality to generate or measure events
Flash memory	Provides non-volatile storage for program code, constants and variables
FlexCAN (controller area network)	Supports the standard CAN communications protocol
FMPLL (frequency-modulated phase-locked loop)	Generates high-speed system clocks and supports programmable frequency modulation
FlexRay (FlexRay communication controller)	Provides high-speed distributed control for advanced automotive applications
Fast Ethernet Controller (FEC)	Ethernet Media Access Controller (MAC) designed to support both 10 and 100 Mbps Ethernet/IEEE 802.3 networks
Internal multiplexer (IMUX) SIUL subblock	Allows flexible mapping of peripheral interface on the different pins of the device
Inter-integrated circuit ( $I^2C$ <sup>TM</sup> ) bus	A two wire bidirectional serial bus that provides a simple and efficient method of data exchange between devices
Interrupt controller (INTC)	Provides priority-based preemptive scheduling of interrupt requests for both e200z0h and e200z4d cores
JTAG controller	Provides the means to test chip functionality and connectivity while remaining transparent to system logic when not in test mode

## Block diagram

**Table 2. MPC5646C series block summary (continued)**

Block	Function
LinFlexD (Local Interconnect Network Flexible with DMA support)	Manages a high number of LIN (Local Interconnect Network protocol) messages efficiently with a minimum of CPU load
Memory protection unit (MPU)	Provides hardware access control for all memory references generated in a device
Clock generation module (MC_CGM)	Provides logic and control required for the generation of system and peripheral clocks
Power control unit (MC_PCU)	Reduces the overall power consumption by disconnecting parts of the device from the power supply via a power switching device; device components are grouped into sections called “power domains” which are controlled by the PCU
Reset generation module (MC_RGM)	Centralizes reset sources and manages the device reset sequence of the device
Mode entry module (MC_ME)	Provides a mechanism for controlling the device operational mode and mode transition sequences in all functional states; also manages the power control unit, reset generation module and clock generation module, and holds the configuration, control and status registers accessible for applications
Non-Maskable Interrupt (NMI)	Handles external events that must produce an immediate response, such as power down detection
Nexus Development Interface (NDI)	Provides real-time development capabilities for e200z0h and e200z4d core processor
Periodic interrupt timer/ Real Time Interrupt Timer (PIT RTI)	Produces periodic interrupts and triggers
Real-time counter (RTC/API)	A free running counter used for time keeping applications, the RTC can be configured to generate an interrupt at a predefined interval independent of the mode of operation (run mode or low-power mode). Supports autonomous periodic interrupt (API) function to generate a periodic wakeup request to exit a low power mode or an interrupt request
Static random-access memory (SRAM)	Provides storage for program code, constants, and variables
System integration unit lite (SIUL)	Provides control over all the electrical pad controls and up 32 ports with 16 bits of bidirectional, general-purpose input and output signals and supports up to 32 external interrupts with trigger event configuration
System status and configuration module (SSCM)	Provides system configuration and status data (such as memory size and status, device mode and security status), device identification data, debug status port enable and selection, and bus and peripheral abort enable/disable
System timer module (STM)	Provides a set of output compare events to support AutoSAR and operating system tasks
Semaphores	Provides the hardware support needed in multi-core systems for sharing resources and provides a simple mechanism to achieve lock/unlock operations via a single write access.
Wake Unit (WKPU)	Supports external sources that can generate interrupts or wakeup events, of which can cause non-maskable interrupt requests or wakeup events.

### 3 Package pinouts and signal descriptions

The available LQFP pinouts and the MAPBGA ballmaps are provided in the following figures. For functional port pin description, see [Table 4](#).

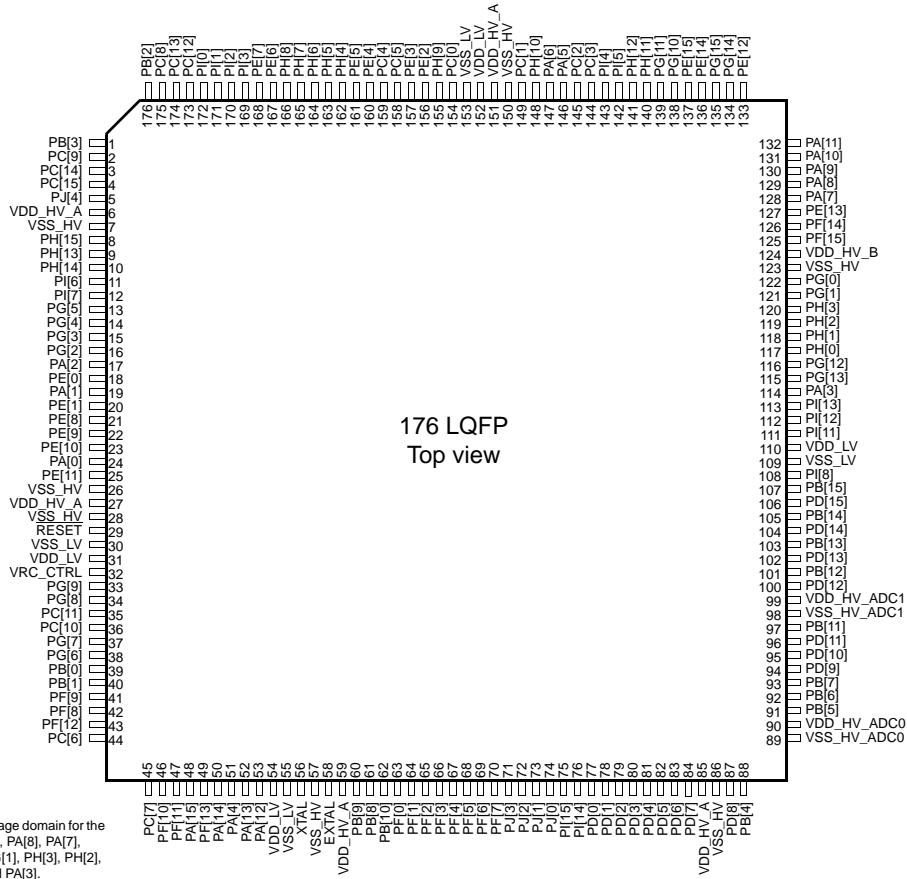
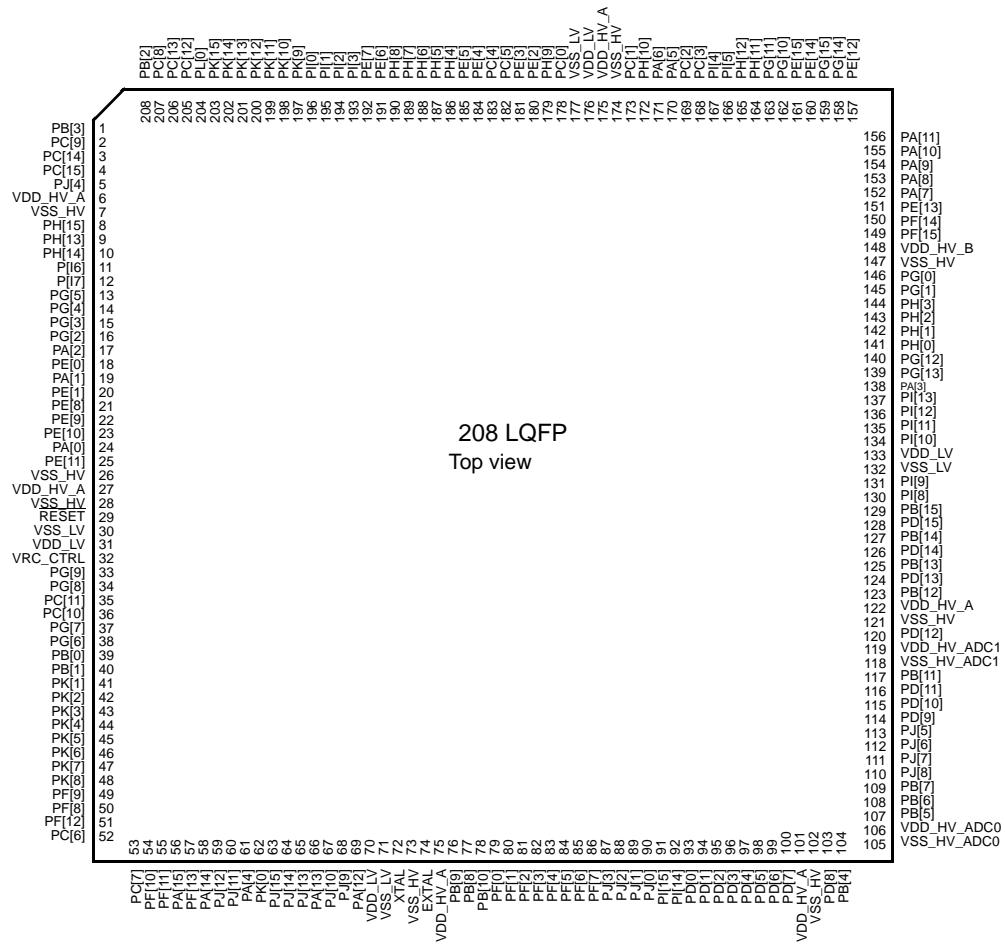


Figure 2. 176-pin LQFP configuration

## Package pinouts and signal descriptions



### NOTE

- 1) VDD\_HV\_B supplies the IO voltage domain for the pins PE[12], PA[11], PA[10], PA[9], PA[8], PA[7], PE[13], PF[14], PF[15], PG[0], PG[1], PH[3], PH[2], PH[1], PH[0], PG[12], PG[13], and PA[3].
- 2) Availability of port pin alternate functions depends on product selection.

Figure 3. 208-pin LQFP configuration

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	
A	PC[15]	PB[2]	PC[13]	PI[1]	PE[7]	PH[8]	PE[2]	PE[4]	PC[4]	PE[3]	PH[9]	PI[4]	PH[11]	PE[14]	PA[10]	PG[11]	A
B	PH[13]	PC[14]	PC[8]	PC[12]	PI[3]	PE[6]	PH[5]	PE[5]	PC[5]	PC[0]	PC[2]	PH[12]	PG[10]	PA[11]	PA[9]	PA[8]	B
C	PH[14]	VDD_HV_A	PC[9]	PL[0]	PI[0]	PH[7]	PH[6]	VSS_LV	VDD_HV_A	PA[5]	PC[3]	PE[15]	PG[14]	PE[12]	PA[7]	PE[13]	C
D	PG[5]	PI[6]	PJ[4]	PB[3]	PK[15]	PI[2]	PH[4]	VDD_LV	PC[1]	PH[10]	PA[6]	PI[5]	PG[15]	PF[14]	PF[15]	PH[2]	D
E	PG[3]	PI[7]	PH[15]	PG[2]	VDD_LV	VSS_LV	PK[10]	PK[9]	PM[1]	PM[0]	PL[15]	PL[14]	PG[0]	PG[1]	PH[0]	VDD_HV_A	E
F	PA[2]	PG[4]	PA[1]	PE[1]	PL[2]	PM[6]	PL[1]	PK[11]	PM[5]	PL[13]	PL[12]	PM[2]	PH[1]	PH[3]	PG[12]	PG[13]	F
G	PE[8]	PE[0]	PE[10]	PA[0]	PL[3]	VSS_HV	VSS_HV	VSS_HV	VSS_HV	VSS_HV	VSS_HV	PK[12]	VDD_HV_B	PI[13]	PI[12]	PA[3]	G
H	PE[9]	VDD_HV_A	PE[11]	PK[1]	PL[4]	VSS_LV	VSS_LV	VSS_HV	VSS_HV	VSS_HV	VSS_HV	PK[13]	VDD_HV_A	VDD_LV	VSS_LV	PI[11]	H
J	VSS_HV	VRC_CTR_L	VDD_LV	PG[9]	PL[5]	VSS_LV	VSS_LV	VSS_HV	VSS_HV	VSS_HV	VSS_HV	PK[14]	PD[15]	PI[8]	PI[9]	PI[10]	J
K	RESET	VSS_LV	PG[8]	PC[11]	PL[6]	VSS_LV	VSS_LV	VSS_LV	VSS_LV	VDD_LV	VDD_LV	PM[3]	PD[14]	PD[13]	PB[14]	PB[15]	K
L	PC[10]	PG[7]	PB[0]	PK[2]	PL[7]	VSS_LV	VSS_LV	VSS_LV	VDD_LV	VDD_LV	PM[4]	PD[12]	PB[12]	PB[13]	VDD_HV_ADC1	L	
M	PG[6]	PB[1]	PK[4]	PF[9]	PK[5]	PK[6]	PK[7]	PK[8]	PL[8]	PL[9]	PL[10]	PL[11]	PB[11]	PD[10]	PD[11]	VSS_HV_ADC1	M
N	PK[3]	PF[8]	PC[6]	PC[7]	PJ[13]	VDD_HV_A	PB[10]	PF[6]	VDD_HV_A	PJ[1]	PD[2]	PJ[5]	PB[5]	PB[6]	PJ[6]	PD[9]	N
P	PF[12]	PF[10]	PF[13]	PA[14]	PJ[9]	PA[12]	PF[0]	PF[5]	PF[7]	PJ[3]	PJ[15]	PD[4]	PD[7]	PD[8]	PJ[8]	PJ[7]	P
R	PF[11]	PA[15]	PJ[11]	PJ[15]	PA[13]	PF[2]	PF[3]	PF[4]	VDD_LV	PJ[2]	PJ[0]	PD[0]	PD[3]	PD[6]	VDD_HV_ADC0	PB[7]	R
T	PJ[12]	PA[4]	PK[0]	PJ[14]	PJ[10]	PF[1]	XTAL	EXTAL	VSS_LV	PB[9]	PB[8]	PI[14]	PD[1]	PD[5]	VSS_HV_ADC0	PB[4]	T
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	

#### Notes:

- 1) VDD\_HV\_B supplies the IO voltage domain for the pins PE[12], PA[11], PA[10], PA[9], PA[8], PA[7], PE[13], PF[14], PF[15], PG[0], PG[1], PH[3], PH[2], PH[1], PH[0], PG[12], PG[13], and PA[3].
- 2) Availability of port pin alternate functions depends on product selection.

**Figure 4. 256-pin BGA configuration**

### 3.1 Pad types

In the device the following types of pads are available for system pins and functional port pins:

S = Slow<sup>1</sup>

M = Medium<sup>1, 2</sup>

1. See the I/O pad electrical characteristics in the device data sheet for details.
2. All medium and fast pads are in slow configuration by default at reset and can be configured as fast or medium. For example, Fast/Medium pad will be Medium by default at reset. Similarly, Slow/Medium pad will be Slow by default. Only exception is PC[1] which is in medium configuration by default (refer to PCR.SRC in the reference manual, Pad Configuration Registers (PCR0—PCR198)).

## Package pinouts and signal descriptions

F = Fast<sup>1, 2</sup>

I = Input only with analog feature<sup>1</sup>

A = Analog

## 3.2 System pins

The system pins are listed in [Table 3](#).

**Table 3. System pin descriptions**

Port pin	Function	I/O direction	Pad type	RESET config.	Pin number		
					176 LQFP	208 LQFP	256 MAPBGA
RESET	Bidirectional reset with Schmitt-Trigger characteristics and noise filter.	I/O	M	Input, weak pull-up only after PHASE2	29	29	K1
EXTAL	Analog input of the oscillator amplifier circuit. Needs to be grounded if oscillator bypass mode is used.	I	A <sup>1</sup>	—	58	74	T8
XTAL	Analog output of the oscillator amplifier circuit, when the oscillator is not in bypass mode. Analog input for the clock generator when the oscillator is in bypass mode.	I/O	A <sup>1</sup>	—	56	72	T7

<sup>1</sup> For analog pads, it is not recommended to enable IBE if APC is enabled to avoid extra current in middle range voltage.

## 3.3 Functional ports

The functional port pins are listed in [Table 4](#).

**Table 4. Functional port pin descriptions**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PA[0]	PCR[0]	AF0 AF1 AF2 AF3 — —	GPIO[0] E0UC[0] CLKOUT E0UC[13] WKPU[19] CAN1RX	SIUL eMIOS_0 MC_CGM eMIOS_0 WKPU FlexCAN_1	I/O I/O O I/O — —	M/S	Tristate	24	24	G4

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PA[1]	PCR[1]	AF0 AF1 AF2 AF3 — — —	GPIO[1] E0UC[1] — — WKPU[2] CAN3RX NMI[0] <sup>3</sup>	SIUL eMIOS_0 — — WKPU FlexCAN_3 WKPU	I/O I/O — — — — —	S	Tristate	19	19	F3
PA[2]	PCR[2]	AF0 AF1 AF2 AF3 — —	GPIO[2] E0UC[2] — MA[2] WKPU[3] NMI[1] <sup>3</sup>	SIUL eMIOS_0 — ADC_0 WKPU WKPU	I/O I/O — O — —	S	Tristate	17	17	F1
PA[3]	PCR[3]	AF0 AF1 AF2 AF3 — — —	GPIO[3] E0UC[3] LIN5TX CS4_1 RX_ER_CLK EIRQ[0] ADC1_S[0]	SIUL eMIOS_0 LINFlexD_5 DSPI_1 FEC SIUL ADC_1	I/O I/O O O — — —	M/S	Tristate	114	138	G16
PA[4]	PCR[4]	AF0 AF1 AF2 AF3 — —	GPIO[4] E0UC[4] — CS0_1 LIN5RX WKPU[9]	SIUL eMIOS_0 — DSPI_1 LINFlexD_5 WKPU	I/O I/O — I/O — —	S	Tristate	51	61	T2
PA[5]	PCR[5]	AF0 AF1 AF2	GPIO[5] E0UC[5] LIN4TX	SIUL eMIOS_0 LINFlexD_4	I/O I/O O	M/S	Tristate	146	170	C10
PA[6]	PCR[6]	AF0 AF1 AF2 AF3 — —	GPIO[6] E0UC[6] — CS1_1 LIN4RX EIRQ[1]	SIUL eMIOS_0 — DSPI_1 LINFlexD_4 SIUL	I/O I/O — O — —	S	Tristate	147	171	D11
PA[7]	PCR[7]	AF0 AF1 AF2 AF3 — — —	GPIO[7] E0UC[7] LIN3TX — RXD[2] EIRQ[2] ADC1_S[1]	SIUL eMIOS_0 LINFlexD_3 — FEC SIUL ADC_1	I/O I/O — — I — —	M/S	Tristate	128	152	C15

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PA[8]	PCR[8]	AF0 AF1 AF2 AF3 — — — —	GPIO[8] E0UC[8] E0UC[14] — RXD[1] EIRQ[3] ABS[0] LIN3RX	SIUL eMIOS_0 eMIOS_0 — FEC SIUL MC_RGM LINFlexD_3	I/O I/O I/O — — — — —	M/S	Input, weak pull-up	129	153	B16
PA[9]	PCR[9]	AF0 AF1 AF2 AF3 — —	GPIO[9] E0UC[9] — CS2_1 RXD[0] FAB	SIUL eMIOS_0 — DSPI1 FEC MC_RGM	I/O I/O — O — —	M/S	Pull- down	130	154	B15
PA[10]	PCR[10]	AF0 AF1 AF2 AF3 — — —	GPIO[10] E0UC[10] SDA LIN2TX COL ADC1_S[2] SIN_1	SIUL eMIOS_0 I <sup>2</sup> C LINFlexD_2 FEC ADC_1 DSPI_1	I/O I/O I/O O — — —	M/S	Tristate	131	155	A15
PA[11]	PCR[11]	AF0 AF1 AF2 AF3 — — — —	GPIO[11] E0UC[11] SCL — RX_ER EIRQ[16] LIN2RX ADC1_S[3]	SIUL eMIOS_0 I <sup>2</sup> C — FEC SIUL LINFlexD_2 ADC_1	I/O I/O I/O — — — — —	M/S	Tristate	132	156	B14
PA[12]	PCR[12]	AF0 AF1 AF2 AF3 — —	GPIO[12] — E0UC[28] CS3_1 EIRQ[17] SIN_0	SIUL — eMIOS_0 DSPI1 SIUL DSPI_0	I/O — I/O O — —	S	Tristate	53	69	P6
PA[13]	PCR[13]	AF0 AF1 AF2 AF3	GPIO[13] SOUT_0 E0UC[29] —	SIUL DSPI_0 eMIOS_0 —	I/O O I/O —	M/S	Tristate	52	66	R5
PA[14]	PCR[14]	AF0 AF1 AF2 AF3 —	GPIO[14] SCK_0 CS0_0 E0UC[0] EIRQ[4]	SIUL DSPI_0 DSPI_0 eMIOS_0 SIUL	I/O I/O I/O I/O I	M/S	Tristate	50	58	P4

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PA[15]	PCR[15]	AF0 AF1 AF2 AF3 —	GPIO[15] CS0_0 SCK_0 E0UC[1] WKPU[10]	SIUL DSPI_0 DSPI_0 eMIOS_0 WKPU	I/O I/O I/O I/O I	M/S	Tristate	48	56	R2
PB[0]	PCR[16]	AF0 AF1 AF2 AF3	GPIO[16] CAN0TX E0UC[30] LIN0TX	SIUL FlexCAN_0 eMIOS_0 LINFlexD_0	I/O O I/O I	M/S	Tristate	39	39	L3
PB[1]	PCR[17]	AF0 AF1 AF2 — — —	GPIO[17] — E0UC[31] LIN0RX WKPU[4] CAN0RX	SIUL — eMIOS_0 LINFlexD_0 WKPU FlexCAN_0	I/O — I/O I I	S	Tristate	40	40	M2
PB[2]	PCR[18]	AF0 AF1 AF2 AF3	GPIO[18] LIN0TX SDA E0UC[30]	SIUL LINFlexD_0 I <sup>2</sup> C eMIOS_0	I/O O I/O I/O	M/S	Tristate	176	208	A2
PB[3]	PCR[19]	AF0 AF1 AF2 AF3 — —	GPIO[19] E0UC[31] SCL — WKPU[11] LIN0RX	SIUL eMIOS_0 I <sup>2</sup> C — WKPU LINFlexD_0	I/O I/O I/O — —	S	Tristate	1	1	D4
PB[4]	PCR[20]	AF0 AF1 AF2 AF3 — —	GPI[20] — — — ADC0_P[0] ADC1_P[0]	SIUL — — — ADC_0 ADC_1	I — — — I	I	Tristate	88	104	T16
PB[5]	PCR[21]	AF0 AF1 AF2 AF3 — —	GPI[21] — — — ADC0_P[1] ADC1_P[1]	SIUL — — — ADC_0 ADC_1	I — — — I	I	Tristate	91	107	N13
PB[6]	PCR[22]	AF0 AF1 AF2 AF3 — —	GPI[22] — — — ADC0_P[2] ADC1_P[2]	SIUL — — — ADC_0 ADC_1	I — — — I	I	Tristate	92	108	N14

## Package pinouts and signal descriptions

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PB[7]	PCR[23]	AF0 AF1 AF2 AF3 — —	GPI[23] — — — ADC0_P[3] ADC1_P[3]	SIUL — — — ADC_0 ADC_1	— — — — —	I	Tristate	93	109	R16
PB[8]	PCR[24]	AF0 AF1 AF2 AF3 — — — —	GPI[24] — — — ADC0_S[0] ADC1_S[4] WKPU[25] OSC32k_XTAL <sup>4</sup>	SIUL — — — ADC_0 ADC_1 WKPU SXOSC	— — — — — — —	I	—	61	77	T11
PB[9] <sup>5</sup>	PCR[25]	AF0 AF1 AF2 AF3 — — — —	GPI[25] — — — ADC0_S[1] ADC1_S[5] WKPU[26] OSC32k_EXTAL <sup>4</sup>	SIUL — — — ADC_0 ADC_1 WKPU SXOSC	— — — — — — —	I	—	60	76	T10
PB[10]	PCR[26]	AF0 AF1 AF2 AF3 — — —	GPIO[26] SOUT_1 CAN3TX — ADC0_S[2] ADC1_S[6] WKPU[8]	SIUL DSPI_1 FlexCAN_3 — ADC_0 ADC_1 WKPU	I/O O — — — — —	S	Tristate	62	78	N7
PB[11]	PCR[27]	AF0 AF1 AF2 AF3 —	GPIO[27] E0UC[3] — CS0_0 ADC0_S[3]	SIUL eMIOS_0 — DSPI_0 ADC_0	I/O I/O — I/O I	S	Tristate	97	117	M13
PB[12]	PCR[28]	AF0 AF1 AF2 AF3 —	GPIO[28] E0UC[4] — CS1_0 ADC0_X[0]	SIUL eMIOS_0 — DSPI_0 ADC_0	I/O I/O — O I	S	Tristate	101	123	L14
PB[13]	PCR[29]	AF0 AF1 AF2 AF3 —	GPIO[29] E0UC[5] — CS2_0 ADC0_X[1]	SIUL eMIOS_0 — DSPI_0 ADC_0	I/O I/O — O I	S	Tristate	103	125	L15

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PB[14]	PCR[30]	AF0 AF1 AF2 AF3 —	GPIO[30] E0UC[6] — CS3_0 ADC0_X[2]	SIUL eMIOS_0 — DSPI_0 ADC_0	I/O I/O — O I	S	Tristate	105	127	K15
PB[15]	PCR[31]	AF0 AF1 AF2 AF3 —	GPIO[31] E0UC[7] — CS4_0 ADC0_X[3]	SIUL eMIOS_0 — DSPI_0 ADC_0	I/O I/O — O I	S	Tristate	107	129	K16
PC[0] <sup>6</sup>	PCR[32]	AF0 AF1 AF2 AF3	GPIO[32] — TDI —	SIUL — JTAGC —	I/O — — —	M/S	Input, weak pull-up	154	178	B10
PC[1] <sup>6</sup>	PCR[33]	AF0 AF1 AF2 AF3	GPIO[33] — TDO —	SIUL — JTAGC —	I/O — O —	F/M	Tristate	149	173	D9
PC[2]	PCR[34]	AF0 AF1 AF2 AF3 —	GPIO[34] SCK_1 CAN4TX — EIRQ[5]	SIUL DSPI_1 FlexCAN_4 — SIUL	I/O I/O O — I	M/S	Tristate	145	169	B11
PC[3]	PCR[35]	AF0 AF1 AF2 AF3 — — —	GPIO[35] CS0_1 MA[0] — CAN1RX CAN4RX EIRQ[6]	SIUL DSPI_1 ADC_0 — FlexCAN_1 FlexCAN_4 SIUL	I/O I/O O — I I I	S	Tristate	144	168	C11
PC[4]	PCR[36]	AF0 AF1 AF2 AF3 ALT4 — — —	GPIO[36] E1UC[31] — FR_B_TX_EN SIN_1 CAN3RX EIRQ[18]	SIUL eMIOS_1 — Flexray DSPI_1 FlexCAN_3 SIUL	I/O I/O — O — — I	M/S	Tristate	159	183	A9
PC[5]	PCR[37]	AF0 AF1 AF2 AF3 ALT4 —	GPIO[37] SOUT_1 CAN3TX — FR_A_TX EIRQ[7]	SIUL DSPI_1 FlexCAN_3 — Flexray SIUL	I/O O O — O I	M/S	Tristate	158	182	B9

## Package pinouts and signal descriptions

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PC[6]	PCR[38]	AF0 AF1 AF2 AF3 —	GPIO[38] LIN1TX E1UC[28] —	SIUL LINFlexD_1 eMIOS_1 —	I/O O I/O —	S	Tristate	44	52	N3
PC[7]	PCR[39]	AF0 AF1 AF2 AF3 — —	GPIO[39] — E1UC[29] — LIN1RX WKPU[12]	SIUL — eMIOS_1 — LINFlexD_1 WKPU	I/O — I/O — — —	S	Tristate	45	53	N4
PC[8]	PCR[40]	AF0 AF1 AF2 AF3 —	GPIO[40] LIN2TX E0UC[3] —	SIUL LINFlexD_2 eMIOS_0 —	I/O O I/O —	S	Tristate	175	207	B3
PC[9]	PCR[41]	AF0 AF1 AF2 AF3 — —	GPIO[41] — E0UC[7] — LIN2RX WKPU[13]	SIUL — eMIOS_0 — LINFlexD_2 WKPU	I/O — I/O — — —	S	Tristate	2	2	C3
PC[10]	PCR[42]	AF0 AF1 AF2 AF3 —	GPIO[42] CAN1TX CAN4TX MA[1]	SIUL FlexCAN_1 FlexCAN_4 ADC_0	I/O O O O	M/S	Tristate	36	36	L1
PC[11]	PCR[43]	AF0 AF1 AF2 AF3 — — —	GPIO[43] — — MA[2] CAN1RX CAN4RX WKPU[5]	SIUL — — ADC_0 FlexCAN_1 FlexCAN_4 WKPU	I/O — — O — — —	S	Tristate	35	35	K4
PC[12]	PCR[44]	AF0 AF1 AF2 AF3 ALT4 — —	GPIO[44] E0UC[12] — — FR_DBG[0] SIN_2 EIRQ[19]	SIUL eMIOS_0 — — Flexray DSPI_2 SIUL	I/O I/O — — O — —	M/S	Tristate	173	205	B4
PC[13]	PCR[45]	AF0 AF1 AF2 AF3 ALT4	GPIO[45] E0UC[13] SOUT_2 — FR_DBG[1]	SIUL eMIOS_0 DSPI_2 — Flexray	I/O I/O O — O	M/S	Tristate	174	206	A3

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PC[14]	PCR[46]	AF0 AF1 AF2 AF3 ALT4 —	GPIO[46] E0UC[14] SCK_2 — FR_DBG[2] EIRQ[8]	SIUL eMIOS_0 DSPI_2 — Flexray SIUL	I/O I/O I/O — O I	M/S	Tristate	3	3	B2
PC[15]	PCR[47]	AF0 AF1 AF2 AF3 ALT4	GPIO[47] E0UC[15] CS0_2 — FR_DBG[3] EIRQ[20]	SIUL eMIOS_0 DSPI_2 — Flexray SIUL	I/O I/O I/O — O I	M/S	Tristate	4	4	A1
PD[0]	PCR[48]	AF0 AF1 AF2 AF3 — — —	GPI[48] — — — ADC0_P[4] ADC1_P[4] WKPU[27]	SIUL — — — ADC_0 ADC_1 WKPU	— — — — — —	I	Tristate	77	93	R12
PD[1]	PCR[49]	AF0 AF1 AF2 AF3 — — —	GPI[49] — — — ADC0_P[5] ADC1_P[5] WKPU[28]	SIUL — — — ADC_0 ADC_1 WKPU	— — — — — —	I	Tristate	78	94	T13
PD[2]	PCR[50]	AF0 AF1 AF2 AF3 — —	GPI[50] — — — ADC0_P[6] ADC1_P[6]	SIUL — — — ADC_0 ADC_1	— — — — — —	I	Tristate	79	95	N11
PD[3]	PCR[51]	AF0 AF1 AF2 AF3 — —	GPI[51] — — — ADC0_P[7] ADC1_P[7]	SIUL — — — ADC_0 ADC_1	— — — — — —	I	Tristate	80	96	R13
PD[4]	PCR[52]	AF0 AF1 AF2 AF3 — —	GPI[52] — — — ADC0_P[8] ADC1_P[8]	SIUL — — — ADC_0 ADC_1	— — — — — —	I	Tristate	81	97	P12

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PD[5]	PCR[53]	AF0 — AF1 — AF2 — AF3 — —	GPI[53] — ADC0_P[9] ADC1_P[9]	SIUL — ADC_0 ADC_1	— — — — —	I — — — — —	Tristate	82	98	T14
PD[6]	PCR[54]	AF0 — AF1 — AF2 — AF3 — —	GPI[54] — ADC0_P[10] ADC1_P[10]	SIUL — ADC_0 ADC_1	I — — — — —	I — — — — —	Tristate	83	99	R14
PD[7]	PCR[55]	AF0 — AF1 — AF2 — AF3 — —	GPI[55] — ADC0_P[11] ADC1_P[11]	SIUL — ADC_0 ADC_1	I — — — — —	I — — — — —	Tristate	84	100	P13
PD[8]	PCR[56]	AF0 — AF1 — AF2 — AF3 — —	GPI[56] — ADC0_P[12] ADC1_P[12]	SIUL — ADC_0 ADC_1	I — — — — —	I — — — — —	Tristate	87	103	P14
PD[9]	PCR[57]	AF0 — AF1 — AF2 — AF3 — —	GPI[57] — ADC0_P[13] ADC1_P[13]	SIUL — ADC_0 ADC_1	I — — — — —	I — — — — —	Tristate	94	114	N16
PD[10]	PCR[58]	AF0 — AF1 — AF2 — AF3 — —	GPI[58] — ADC0_P[14] ADC1_P[14]	SIUL — ADC_0 ADC_1	I — — — — —	I — — — — —	Tristate	95	115	M14
PD[11]	PCR[59]	AF0 — AF1 — AF2 — AF3 — —	GPI[59] — ADC0_P[15] ADC1_P[15]	SIUL — ADC_0 ADC_1	I — — — — —	I — — — — —	Tristate	96	116	M15

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PD[12]	PCR[60]	AF0 AF1 AF2 AF3 —	GPIO[60] CS5_0 E0UC[24] — ADC0_S[4]	SIUL DSPI_0 eMIOS_0 — ADC_0	I/O O I/O — I	S	Tristate	100	120	L13
PD[13]	PCR[61]	AF0 AF1 AF2 AF3 —	GPIO[61] CS0_1 E0UC[25] — ADC0_S[5]	SIUL DSPI_1 eMIOS_0 — ADC_0	I/O I/O I/O — I	S	Tristate	102	124	K14
PD[14]	PCR[62]	AF0 AF1 AF2 AF3 ALT4 —	GPIO[62] CS1_1 E0UC[26] — FR_DBG[0] ADC0_S[6]	SIUL DSPI_1 eMIOS_0 — Flexray ADC_0	I/O O I/O — O I	S	Tristate	104	126	K13
PD[15]	PCR[63]	AF0 AF1 AF2 AF3 ALT4 —	GPIO[63] CS2_1 E0UC[27] — FR_DBG[1] ADC0_S[7]	SIUL DSPI_1 eMIOS_0 — Flexray ADC_0	I/O O I/O — O I	S	Tristate	106	128	J13
PE[0]	PCR[64]	AF0 AF1 AF2 AF3 — —	GPIO[64] E0UC[16] — — CAN5RX WKPU[6]	SIUL eMIOS_0 — — FlexCAN_5 WKPU	I/O I/O — — — I	S	Tristate	18	18	G2
PE[1]	PCR[65]	AF0 AF1 AF2 AF3	GPIO[65] E0UC[17] CAN5TX —	SIUL eMIOS_0 FlexCAN_5 —	I/O I/O O —	M/S	Tristate	20	20	F4
PE[2]	PCR[66]	AF0 AF1 AF2 AF3 ALT4 — —	GPIO[66] E0UC[18] — — FR_A_TX_EN SIN_1 EIRQ[21]	SIUL eMIOS_0 — — Flexray DSPI_1 SIUL	I/O I/O — — O I I	M/S	Tristate	156	180	A7

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PE[3]	PCR[67]	AF0 AF1 AF2 AF3 — —	GPIO[67] E0UC[19] SOUT_1 — FR_A_RX WKPU[29]	SIUL eMIOS_0 DSPI_1 — Flexray WKPU	I/O I/O O — — —	M/S	Tristate	157	181	A10
PE[4]	PCR[68]	AF0 AF1 AF2 AF3 ALT4 —	GPIO[68] E0UC[20] SCK_1 — FR_B_TX EIRQ[9]	SIUL eMIOS_0 DSPI_1 — Flexray SIUL	I/O I/O I/O — O —	M/S	Tristate	160	184	A8
PE[5]	PCR[69]	AF0 AF1 AF2 AF3 — —	GPIO[69] E0UC[21] CS0_1 MA[2] FR_B_RX WKPU[30]	SIUL eMIOS_0 DSPI_1 ADC_0 Flexray WKPU	I/O I/O I/O O — —	M/S	Tristate	161	185	B8
PE[6]	PCR[70]	AF0 AF1 AF2 AF3 —	GPIO[70] E0UC[22] CS3_0 MA[1] EIRQ[22]	SIUL eMIOS_0 DSPI_0 ADC_0 SIUL	I/O I/O O O I	M/S	Tristate	167	191	B6
PE[7]	PCR[71]	AF0 AF1 AF2 AF3 —	GPIO[71] E0UC[23] CS2_0 MA[0] EIRQ[23]	SIUL eMIOS_0 DSPI_0 ADC_0 SIUL	I/O I/O O O I	M/S	Tristate	168	192	A5
PE[8]	PCR[72]	AF0 AF1 AF2 AF3	GPIO[72] CAN2TX E0UC[22] CAN3TX	SIUL FlexCAN_2 eMIOS_0 FlexCAN_3	I/O O I/O O	M/S	Tristate	21	21	G1
PE[9]	PCR[73]	AF0 AF1 AF2 AF3 — — —	GPIO[73] — E0UC[23] — WKPU[7] CAN2RX CAN3RX	SIUL — eMIOS_0 — WKPU FlexCAN_2 FlexCAN_3	I/O — I/O — I — I	S	Tristate	22	22	H1
PE[10]	PCR[74]	AF0 AF1 AF2 AF3 —	GPIO[74] LIN3TX CS3_1 E1UC[30] EIRQ[10]	SIUL LINFlexD_3 DSPI_1 eMIOS_1 SIUL	I/O O O I/O I	S	Tristate	23	23	G3

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PE[11]	PCR[75]	AF0 AF1 AF2 AF3 — —	GPIO[75] E0UC[24] CS4_1 — LIN3RX WKPU[14]	SIUL eMIOS_0 DSPI_1 — LINFlexD_3 WKPU	I/O I/O O — — —	S	Tristate	25	25	H3
PE[12]	PCR[76]	AF0 AF1 AF2 AF3 — — — —	GPIO[76] — E1UC[19] — CRS SIN_2 EIRQ[11] ADC1_S[7]	SIUL — eMIOS_1 — FEC DSPI_2 SIUL ADC_1	I/O — I/O — — — — —	M/S	Tristate	133	157	C14
PE[13]	PCR[77]	AF0 AF1 AF2 AF3 —	GPIO[77] SOUT_2 E1UC[20] — RXD[3]	SIUL DSPI_2 eMIOS_1 — FEC	I/O O I/O — —	M/S	Tristate	127	151	C16
PE[14]	PCR[78]	AF0 AF1 AF2 AF3 —	GPIO[78] SCK_2 E1UC[21] — EIRQ[12]	SIUL DSPI_2 eMIOS_1 — SIUL	I/O I/O I/O — —	M/S	Tristate	136	160	A14
PE[15]	PCR[79]	AF0 AF1 AF2 AF3	GPIO[79] CS0_2 E1UC[22] SCK_6	SIUL DSPI_2 eMIOS_1 DSPI_6	I/O I/O I/O I/O	M/S	Tristate	137	161	C12
PF[0]	PCR[80]	AF0 AF1 AF2 AF3 —	GPIO[80] E0UC[10] CS3_1 — ADC0_S[8]	SIUL eMIOS_0 DSPI_1 — ADC_0	I/O I/O O — —	S	Tristate	63	79	P7
PF[1]	PCR[81]	AF0 AF1 AF2 AF3 —	GPIO[81] E0UC[11] CS4_1 — ADC0_S[9]	SIUL eMIOS_0 DSPI_1 — ADC_0	I/O I/O O — —	S	Tristate	64	80	T6
PF[2]	PCR[82]	AF0 AF1 AF2 AF3 —	GPIO[82] E0UC[12] CS0_2 — ADC0_S[10]	SIUL eMIOS_0 DSPI_2 — ADC_0	I/O I/O I/O — —	S	Tristate	65	81	R6

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PF[3]	PCR[83]	AF0 AF1 AF2 AF3 —	GPIO[83] E0UC[13] CS1_2 — ADC0_S[11]	SIUL eMIOS_0 DSPI_2 — ADC_0	I/O I/O O — I	S	Tristate	66	82	R7
PF[4]	PCR[84]	AF0 AF1 AF2 AF3 —	GPIO[84] E0UC[14] CS2_2 — ADC0_S[12]	SIUL eMIOS_0 DSPI_2 — ADC_0	I/O I/O O — I	S	Tristate	67	83	R8
PF[5]	PCR[85]	AF0 AF1 AF2 AF3 —	GPIO[85] E0UC[22] CS3_2 — ADC0_S[13]	SIUL eMIOS_0 DSPI_2 — ADC_0	I/O I/O O — I	S	Tristate	68	84	P8
PF[6]	PCR[86]	AF0 AF1 AF2 AF3 —	GPIO[86] E0UC[23] CS1_1 — ADC0_S[14]	SIUL eMIOS_0 DSPI_1 — ADC_0	I/O I/O O — I	S	Tristate	69	85	N8
PF[7]	PCR[87]	AF0 AF1 AF2 AF3 —	GPIO[87] — CS2_1 — ADC0_S[15]	SIUL — DSPI_1 — ADC_0	I/O — O — I	S	Tristate	70	86	P9
PF[8]	PCR[88]	AF0 AF1 AF2 AF3	GPIO[88] CAN3TX CS4_0 CAN2TX	SIUL FlexCAN_3 DSPI_0 FlexCAN_2	I/O O O O	M/S	Tristate	42	50	N2
PF[9]	PCR[89]	AF0 AF1 AF2 AF3 — — —	GPIO[89] E1UC[1] CS5_0 — CAN2RX CAN3RX WKPU[22]	SIUL eMIOS_1 DSPI_0 — FlexCAN_2 FlexCAN_3 WKPU	I/O I/O O — I — I	S	Tristate	41	49	M4
PF[10]	PCR[90]	AF0 AF1 AF2 AF3	GPIO[90] CS1_0 LIN4TX E1UC[2]	SIUL DSPI_0 LINFlexD_4 eMIOS_1	I/O O O I/O	M/S	Tristate	46	54	P2

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PF[11]	PCR[91]	AF0 AF1 AF2 AF3 — —	GPIO[91] CS2_0 E1UC[3] — LIN4RX WKPU[15]	SIUL DSPI_0 eMIOS_1 — LINFlexD_4 WKPU	I/O O I/O — I I	S	Tristate	47	55	R1
PF[12]	PCR[92]	AF0 AF1 AF2 AF3	GPIO[92] E1UC[25] LIN5TX —	SIUL eMIOS_1 LINFlexD_5 —	I/O I/O O —	M/S	Tristate	43	51	P1
PF[13]	PCR[93]	AF0 AF1 AF2 AF3 — —	GPIO[93] E1UC[26] — — LIN5RX WKPU[16]	SIUL eMIOS_1 — — LINFlexD_5 WKPU	I/O I/O — — I I	S	Tristate	49	57	P3
PF[14]	PCR[94]	AF0 AF1 AF2 AF3 ALT4	GPIO[94] CAN4TX E1UC[27] CAN1TX MDIO	SIUL FlexCAN_4 eMIOS_1 FlexCAN_1 FEC	I/O O I/O O I/O	M/S	Tristate	126	150	D14
PF[15]	PCR[95]	AF0 AF1 AF2 AF3 — — — — —	GPIO[95] E1UC[4] — — RX_DV CAN1RX CAN4RX EIRQ[13]	SIUL eMIOS_1 — — FEC FlexCAN_1 FlexCAN_4 SIUL	I/O I/O — — — — I	M/S	Tristate	125	149	D15
PG[0]	PCR[96]	AF0 AF1 AF2 AF3 ALT4	GPIO[96] CAN5TX E1UC[23] — MDC	SIUL FlexCAN_5 eMIOS_1 — FEC	I/O O I/O — O	F	Tristate	122	146	E13
PG[1]	PCR[97]	AF0 AF1 AF2 AF3 — — —	GPIO[97] — E1UC[24] — TX_CLK CAN5RX EIRQ[14]	SIUL — eMIOS_1 — FEC FlexCAN_5 SIUL	I/O — I/O — I I	M	Tristate	121	145	E14

## Package pinouts and signal descriptions

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PG[2]	PCR[98]	AF0 AF1 AF2 AF3 —	GPIO[98] E1UC[11] SOUT_3 —	SIUL eMIOS_1 DSPI_3 —	I/O I/O O —	M/S	Tristate	16	16	E4
PG[3]	PCR[99]	AF0 AF1 AF2 AF3 —	GPIO[99] E1UC[12] CS0_3 — WKPU[17]	SIUL eMIOS_1 DSPI_3 — WKPU	I/O I/O I/O — I	S	Tristate	15	15	E1
PG[4]	PCR[100]	AF0 AF1 AF2 AF3 —	GPIO[100] E1UC[13] SCK_3 —	SIUL eMIOS_1 DSPI_3 —	I/O I/O I/O —	M/S	Tristate	14	14	F2
PG[5]	PCR[101]	AF0 AF1 AF2 AF3 — —	GPIO[101] E1UC[14] — — WKPU[18] SIN_3	SIUL eMIOS_1 — — WKPU DSPI_3	I/O I/O — — I I	S	Tristate	13	13	D1
PG[6]	PCR[102]	AF0 AF1 AF2 AF3 —	GPIO[102] E1UC[15] LIN6TX —	SIUL eMIOS_1 LINFlexD_6 —	I/O I/O O —	M/S	Tristate	38	38	M1
PG[7]	PCR[103]	AF0 AF1 AF2 AF3 — —	GPIO[103] E1UC[16] E1UC[30] — LIN6RX WKPU[20]	SIUL eMIOS_1 eMIOS_1 — LINFlexD_6 WKPU	I/O I/O I/O — I I	S	Tristate	37	37	L2
PG[8]	PCR[104]	AF0 AF1 AF2 AF3 —	GPIO[104] E1UC[17] LIN7TX CS0_2 EIRQ[15]	SIUL eMIOS_1 LINFlexD_7 DSPI_2 SIUL	I/O I/O O I/O I	S	Tristate	34	34	K3
PG[9]	PCR[105]	AF0 AF1 AF2 AF3 — —	GPIO[105] E1UC[18] — SCK_2 LIN7RX WKPU[21]	SIUL eMIOS_1 — DSPI_2 LINFlexD_7 WKPU	I/O I/O — I/O I I	S	Tristate	33	33	J4

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PG[10]	PCR[106]	AF0 AF1 AF2 AF3 —	GPIO[106] E0UC[24] E1UC[31] — SIN_4	SIUL eMIOS_0 eMIOS_1 — DSPI_4	I/O I/O I/O — I	S	Tristate	138	162	B13
PG[11]	PCR[107]	AF0 AF1 AF2 AF3	GPIO[107] E0UC[25] CS0_4 CS0_6	SIUL eMIOS_0 DSPI_4 DSPI_6	I/O I/O I/O I/O	M/S	Tristate	139	163	A16
PG[12]	PCR[108]	AF0 AF1 AF2 AF3 ALT4	GPIO[108] E0UC[26] SOUT_4 — TXD[2]	SIUL eMIOS_0 DSPI_4 — FEC	I/O I/O O — O	M/S	Tristate	116	140	F15
PG[13]	PCR[109]	AF0 AF1 AF2 AF3 ALT4	GPIO[109] E0UC[27] SCK_4 — TXD[3]	SIUL eMIOS_0 DSPI_4 — FEC	I/O I/O I/O — O	M/S	Tristate	115	139	F16
PG[14]	PCR[110]	AF0 AF1 AF2 AF3 —	GPIO[110] E1UC[0] LIN8TX — SIN_6	SIUL eMIOS_1 LINFlexD_8 — DSPI_6	I/O I/O O — I	S	Tristate	134	158	C13
PG[15]	PCR[111]	AF0 AF1 AF2 AF3 —	GPIO[111] E1UC[1] SOUT_6 — LIN8RX	SIUL eMIOS_1 DSPI_6 — LINFlexD_8	I/O I/O O — I	M/S	Tristate	135	159	D13
PH[0]	PCR[112]	AF0 AF1 AF2 AF3 ALT4 —	GPIO[112] E1UC[2] — — TXD[1] SIN_1	SIUL eMIOS_1 — — FEC DSPI_1	I/O I/O — — O I	M/S	Tristate	117	141	E15
PH[1]	PCR[113]	AF0 AF1 AF2 AF3 ALT4	GPIO[113] E1UC[3] SOUT_1 — TXD[0]	SIUL eMIOS_1 DSPI_1 — FEC	I/O I/O O — O	M/S	Tristate	118	142	F13

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PH[2]	PCR[114]	AF0 AF1 AF2 AF3 ALT4	GPIO[114] E1UC[4] SCK_1 — TX_EN	SIUL eMIOS_1 DSPI_1 — FEC	I/O I/O I/O — O	M/S	Tristate	119	143	D16
PH[3]	PCR[115]	AF0 AF1 AF2 AF3 ALT4	GPIO[115] E1UC[5] CS0_1 — TX_ER	SIUL eMIOS_1 DSPI_1 — FEC	I/O I/O I/O — O	M/S	Tristate	120	144	F14
PH[4]	PCR[116]	AF0 AF1 AF2 AF3	GPIO[116] E1UC[6] SOUT_7 —	SIUL eMIOS_1 DSPI_7 —	I/O I/O O —	M/S	Tristate	162	186	D7
PH[5]	PCR[117]	AF0 AF1 AF2 AF3 —	GPIO[117] E1UC[7] — — SIN_7	SIUL eMIOS_1 — — DSPI_7	I/O I/O — — I	S	Tristate	163	187	B7
PH[6]	PCR[118]	AF0 AF1 AF2 AF3	GPIO[118] E1UC[8] SCK_7 MA[2]	SIUL eMIOS_1 DSPI_7 ADC_0	I/O I/O I/O O	M/S	Tristate	164	188	C7
PH[7]	PCR[119]	AF0 AF1 AF2 AF3 ALT4	GPIO[119] E1UC[9] CS3_2 MA[1] CS0_7	SIUL eMIOS_1 DSPI_2 ADC_0 DSPI_7	I/O I/O O O I/O	M/S	Tristate	165	189	C6
PH[8]	PCR[120]	AF0 AF1 AF2 AF3	GPIO[120] E1UC[10] CS2_2 MA[0]	SIUL eMIOS_1 DSPI_2 ADC_0	I/O I/O O O	M/S	Tristate	166	190	A6
PH[9] <sup>6</sup>	PCR[121]	AF0 AF1 AF2 AF3 —	GPIO[121] — — — TCK	SIUL — — — JTAGC	I/O — — — I	S	Input, weak pull-up	155	179	A11
PH[10] <sup>6</sup>	PCR[122]	AF0 AF1 AF2 AF3 —	GPIO[122] — — — TMS	SIUL — — — JTAGC	I/O — — — I	M/S	Input, weak pull-up	148	172	D10

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PH[11]	PCR[123]	AF0 AF1 AF2 AF3	GPIO[123] SOUT_3 CS0_4 E1UC[5]	SIUL DSPI_3 DSPI_4 eMIOS_1	I/O O I/O I/O	M/S	Tristate	140	164	A13
PH[12]	PCR[124]	AF0 AF1 AF2 AF3	GPIO[124] SCK_3 CS1_4 E1UC[25]	SIUL DSPI_3 DSPI_4 eMIOS_1	I/O I/O O I/O	M/S	Tristate	141	165	B12
PH[13]	PCR[125]	AF0 AF1 AF2 AF3	GPIO[125] SOUT_4 CS0_3 E1UC[26]	SIUL DSPI_4 DSPI_3 eMIOS_1	I/O O I/O I/O	M/S	Tristate	9	9	B1
PH[14]	PCR[126]	AF0 AF1 AF2 AF3	GPIO[126] SCK_4 CS1_3 E1UC[27]	SIUL DSPI_4 DSPI_3 eMIOS_1	I/O I/O O I/O	M/S	Tristate	10	10	C1
PH[15]	PCR[127]	AF0 AF1 AF2 AF3	GPIO[127] SOUT_5 — E1UC[17]	SIUL DSPI_5 — eMIOS_1	I/O O — I/O	M/S	Tristate	8	8	E3
PI[0]	PCR[128]	AF0 AF1 AF2 AF3	GPIO[128] E0UC[28] LIN8TX —	SIUL eMIOS_0 LINFlexD_8 —	I/O I/O O —	S	Tristate	172	196	C5
PI[1]	PCR[129]	AF0 AF1 AF2 AF3 — —	GPIO[129] E0UC[29] — — WKPU[24] LIN8RX	SIUL eMIOS_0 — — WKPU LINFlexD_8	I/O I/O — — — I	S	Tristate	171	195	A4
PI[2]	PCR[130]	AF0 AF1 AF2 AF3	GPIO[130] E0UC[30] LIN9TX —	SIUL eMIOS_0 LINFlexD_9 —	I/O I/O O —	S	Tristate	170	194	D6
PI[3]	PCR[131]	AF0 AF1 AF2 AF3 — —	GPIO[131] E0UC[31] — — WKPU[23] LIN9RX	SIUL eMIOS_0 — — WKPU LINFlexD_9	I/O I/O — — — I	S	Tristate	169	193	B5

## Package pinouts and signal descriptions

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PI[4]	PCR[132]	AF0 AF1 AF2 AF3	GPIO[132] E1UC[28] SOUT_4 —	SIUL eMIOS_1 DSPI_4 —	I/O I/O O —	M/S	Tristate	143	167	A12
PI[5]	PCR[133]	AF0 AF1 AF2 AF3 ALT4	GPIO[133] E1UC[29] SCK_4 CS2_5 CS2_6	SIUL eMIOS_1 DSPI_4 DSPI_5 DSPI_6	I/O I/O I/O O O	M/S	Tristate	142	166	D12
PI[6]	PCR[134]	AF0 AF1 AF2 AF3 ALT4	GPIO[134] E1UC[30] CS0_4 CS0_5 CS0_6	SIUL eMIOS_1 DSPI_4 DSPI_5 DSPI_6	I/O I/O I/O I/O I/O	S	Tristate	11	11	D2
PI[7]	PCR[135]	AF0 AF1 AF2 AF3 ALT4	GPIO[135] E1UC[31] CS1_4 CS1_5 CS1_6	SIUL eMIOS_1 DSPI_4 DSPI_5 DSPI_6	I/O I/O O O O	S	Tristate	12	12	E2
PI[8]	PCR[136]	AF0 AF1 AF2 AF3 —	GPIO[136] — — — ADC0_S[16]	SIUL — — — ADC_0	I/O — — — —	S	Tristate	108	130	J14
PI[9]	PCR[137]	AF0 AF1 AF2 AF3 —	GPIO[137] — — — ADC0_S[17]	SIUL — — — ADC_0	I/O — — — —	S	Tristate	—	131	J15
PI[10]	PCR[138]	AF0 AF1 AF2 AF3 —	GPIO[138] — — — ADC0_S[18]	SIUL — — — ADC_0	I/O — — — —	S	Tristate	—	134	J16
PI[11]	PCR[139]	AF0 AF1 AF2 AF3 — —	GPIO[139] — — — ADC0_S[19] SIN_3	SIUL — — — ADC_0 DSPI_3	I/O — — — — —	S	Tristate	111	135	H16

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PI[12]	PCR[140]	AF0 AF1 AF2 AF3 —	GPIO[140] CS0_3 CS0_2 — ADC0_S[20]	SIUL DSPI_3 DSPI_2 — ADC_0	I/O I/O I/O — I	S	Tristate	112	136	G15
PI[13]	PCR[141]	AF0 AF1 AF2 AF3 —	GPIO[141] CS1_3 CS1_2 — ADC0_S[21]	SIUL DSPI_3 DSPI_2 — ADC_0	I/O O O — I	S	Tristate	113	137	G14
PI[14]	PCR[142]	AF0 AF1 AF2 AF3 — —	GPIO[142] — — — ADC0_S[22] SIN_4	SIUL — — — ADC_0 DSPI_4	I/O — — — — I	S	Tristate	76	92	T12
PI[15]	PCR[143]	AF0 AF1 AF2 AF3 —	GPIO[143] CS0_4 CS2_2 — ADC0_S[23]	SIUL DSPI_4 DSPI_2 — ADC_0	I/O I/O O — I	S	Tristate	75	91	P11
PJ[0]	PCR[144]	AF0 AF1 AF2 AF3 —	GPIO[144] CS1_4 CS3_2 — ADC0_S[24]	SIUL DSPI_4 DSPI_2 — ADC_0	I/O O O — I	S	Tristate	74	90	R11
PJ[1]	PCR[145]	AF0 AF1 AF2 AF3 — —	GPIO[145] — — — ADC0_S[25] SIN_5	SIUL — — — ADC_0 DSPI_5	I/O — — — I I	S	Tristate	73	89	N10
PJ[2]	PCR[146]	AF0 AF1 AF2 AF3 —	GPIO[146] CS0_5 CS0_6 CS0_7 ADC0_S[26]	SIUL DSPI_5 DSPI_6 DSPI_7 ADC_0	I/O I/O I/O I/O I	S	Tristate	72	88	R10
PJ[3]	PCR[147]	AF0 AF1 AF2 AF3 —	GPIO[147] CS1_5 CS1_6 CS1_7 ADC0_S[27]	SIUL DSPI_5 DSPI_6 DSPI_7 ADC_0	I/O O O O I	S	Tristate	71	87	P10

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PJ[4]	PCR[148]	AF0 AF1 AF2 AF3	GPIO[148] SCK_5 E1UC[18] —	SIUL DSPI_5 eMIOS_1 —	I/O I/O I/O —	M/S	Tristate	5	5	D3
PJ[5]	PCR[149]	AF0 AF1 AF2 AF3 —	GPIO[149] — — — ADC0_S[28]	SIUL — — — ADC_0	I/O — — — I	S	Tristate	—	113	N12
PJ[6]	PCR[150]	AF0 AF1 AF2 AF3 —	GPIO[150] — — — ADC0_S[29]	SIUL — — — ADC_0	I/O — — — —	S	Tristate	—	112	N15
PJ[7]	PCR[151]	AF0 AF1 AF2 AF3 —	GPIO[151] — — — ADC0_S[30]	SIUL — — — ADC_0	I/O — — — I	S	Tristate	—	111	P16
PJ[8]	PCR[152]	AF0 AF1 AF2 AF3 —	GPIO[152] — — — ADC0_S[31]	SIUL — — — ADC_0	I/O — — — —	S	Tristate	—	110	P15
PJ[9]	PCR[153]	AF0 AF1 AF2 AF3 —	GPIO[153] — — — ADC1_S[8]	SIUL — — — ADC_1	I/O — — — I	S	Tristate	—	68	P5
PJ[10]	PCR[154]	AF0 AF1 AF2 AF3 —	GPIO[154] — — — ADC1_S[9]	SIUL — — — ADC_1	I/O — — — —	S	Tristate	—	67	T5
PJ[11]	PCR[155]	AF0 AF1 AF2 AF3 —	GPIO[155] — — — ADC1_S[10]	SIUL — — — ADC_1	I/O — — — I	S	Tristate	—	60	R3

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PJ[12]	PCR[156]	AF0 — AF1 — AF2 — AF3 —	GPIO[156] — — — ADC1_S[11]	SIUL — — — ADC_1	I/O — — — — I	S	Tristate	—	59	T1
PJ[13]	PCR[157]	AF0 AF1 AF2 AF3 — — — —	GPIO[157] — CS1_7 — CAN4RX ADC1_S[12] CAN1RX WKPU[31]	SIUL — DSPI_7 — FlexCAN_4 ADC_1 FlexCAN_1 WKPU	I/O — O — — — — —	S	Tristate	—	65	N5
PJ[14]	PCR[158]	AF0 AF1 AF2 AF3	GPIO[158] CAN1TX CAN4TX CS2_7	SIUL FlexCAN_1 FlexCAN_4 DSPI_7	I/O O O O	M/S	Tristate	—	64	T4
PJ[15]	PCR[159]	AF0 AF1 AF2 AF3 —	GPIO[159] — CS1_6 — CAN1RX	SIUL — DSPI_6 — FlexCAN_1	I/O — O — —	M/S	Tristate	—	63	R4
PK[0]	PCR[160]	AF0 AF1 AF2 AF3	GPIO[160] CAN1TX CS2_6 —	SIUL FlexCAN_1 DSPI_6 —	I/O O O —	M/S	Tristate	—	62	T3
PK[1]	PCR[161]	AF0 AF1 AF2 AF3 —	GPIO[161] CS3_6 — — CAN4RX	SIUL DSPI_6 — — FlexCAN_4	I/O O — — I	M/S	Tristate	—	41	H4
PK[2]	PCR[162]	AF0 AF1 AF2 AF3 — —	GPIO[162] CAN4TX — —	SIUL FlexCAN_4 — —	I/O O — —	M/S	Tristate	—	42	L4
PK[3]	PCR[163]	AF0 AF1 AF2 AF3 — —	GPIO[163] E1UC[0] — — CAN5RX LIN8RX	SIUL eMIOS_1 — — FlexCAN_5 LINFlexD_8	I/O I/O — — I I	M/S	Tristate	—	43	N1

## Package pinouts and signal descriptions

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PK[4]	PCR[164]	AF0 AF1 AF2 AF3	GPIO[164] LIN8TX CAN5TX E1UC[1]	SIUL LINFlexD_8 FlexCAN_5 eMIOS_1	I/O O O I/O	M/S	Tristate	—	44	M3
PK[5]	PCR[165]	AF0 AF1 AF2 AF3 — —	GPIO[165] — — — CAN2RX LIN2RX	SIUL — — — FlexCAN_2 LINFlexD_2	I/O — — — I I	M/S	Tristate	—	45	M5
PK[6]	PCR[166]	AF0 AF1 AF2 AF3	GPIO[166] CAN2TX LIN2TX —	SIUL FlexCAN_2 LINFlexD_2	I/O O O	M/S	Tristate	—	46	M6
PK[7]	PCR[167]	AF0 AF1 AF2 AF3 — —	GPIO[167] — — — CAN3RX LIN3RX	SIUL — — — FlexCAN_3 LINFlexD_3	I/O — — — I I	M/S	Tristate	—	47	M7
PK[8]	PCR[168]	AF0 AF1 AF2 AF3	GPIO[168] CAN3TX LIN3TX —	SIUL FlexCAN_3 LINFlexD_3	I/O O O	M/S	Tristate	—	48	M8
PK[9]	PCR[169]	AF0 AF1 AF2 AF3 —	GPIO[169] — — — SIN_4	SIUL — — — DSPI_4	I/O — — — I	M/S	Tristate	—	197	E8
PK[10]	PCR[170]	AF0 AF1 AF2 AF3	GPIO[170] SOUT_4 — —	SIUL DSPI_4	I/O O — —	M/S	Tristate	—	198	E7
PK[11]	PCR[171]	AF0 AF1 AF2 AF3	GPIO[171] SCK_4 — —	SIUL DSPI_4	I/O I/O — —	M/S	Tristate	—	199	F8
PK[12]	PCR[172]	AF0 AF1 AF2 AF3	GPIO[172] CS0_4 — —	SIUL DSPI_4	I/O I/O — —	M/S	Tristate	—	200	G12

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PK[13]	PCR[173]	AF0 AF1 AF2 AF3 —	GPIO[173] CS3_6 CS2_7 SCK_1 CAN3RX	SIUL DSPI_6 DSPI_7 DSPI_1 FlexCAN_3	I/O O O I/O I	M/S	Tristate	—	201	H12
PK[14]	PCR[174]	AF0 AF1 AF2 AF3	GPIO[174] CAN3TX CS3_7 CS0_1	SIUL FlexCAN_3 DSPI_7 DSPI_1	I/O O O I/O	M/S	Tristate	—	202	J12
PK[15]	PCR[175]	AF0 AF1 AF2 AF3 — —	GPIO[175] — — — SIN_1 SIN_7	SIUL — — — DSPI_1 DSPI_7	I/O — — — — —	M/S	Tristate	—	203	D5
PL[0]	PCR[176]	AF0 AF1 AF2 AF3	GPIO[176] SOUT_1 SOUT_7 —	SIUL DSPI_1 DSPI_7 —	I/O O O —	M/S	Tristate	—	204	C4
PL[1]	PCR[177]	AF0 AF1 AF2 AF3	GPIO[177] — — —	SIUL — — —	I/O — — —	M/S	Tristate	—	—	F7
PL[2]	PCR[178] <sup>7</sup>	AF0 AF1 AF2 AF3	GPIO[178] — MDO0 <sup>8</sup> —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	F5
PL[3]	PCR[179]	AF0 AF1 AF2 AF3	GPIO[179] — MDO1 —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	G5
PL[4]	PCR[180]	AF0 AF1 AF2 AF3	GPIO[180] — MDO2 —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	H5
PL[5]	PCR[181]	AF0 AF1 AF2 AF3	GPIO[181] — MDO3 —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	J5
PL[6]	PCR[182]	AF0 AF1 AF2 AF3	GPIO[182] — MDO4 —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	K5

## Package pinouts and signal descriptions

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PL[7]	PCR[183]	AF0 — AF1 — AF2 — AF3 —	GPIO[183] — MDO5 —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	L5
PL[8]	PCR[184]	AF0 — AF1 — AF2 — AF3 —	GPIO[184] — — — EVTI	SIUL — — — Nexus	I/O — — — I	S	Pull-up	—	—	M9
PL[9]	PCR[185]	AF0 — AF1 — AF2 — AF3 —	GPIO[185] — MSEO —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	M10
PL[10]	PCR[186]	AF0 — AF1 — AF2 — AF3 —	GPIO[186] — MCKO —	SIUL — Nexus —	I/O — O —	F/S	Tristate	—	—	M11
PL[11]	PCR[187]	AF0 — AF1 — AF2 — AF3 —	GPIO[187] — — —	SIUL — — —	I/O — — —	M/S	Tristate	—	—	M12
PL[12]	PCR[188]	AF0 — AF1 — AF2 — AF3 —	GPIO[188] — EVTO —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	F11
PL[13]	PCR[189]	AF0 — AF1 — AF2 — AF3 —	GPIO[189] — MDO6 —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	F10
PL[14]	PCR[190]	AF0 — AF1 — AF2 — AF3 —	GPIO[190] — MDO7 —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	E12
PL[15]	PCR[191]	AF0 — AF1 — AF2 — AF3 —	GPIO[191] — MDO8 —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	E11
PM[0]	PCR[192]	AF0 — AF1 — AF2 — AF3 —	GPIO[192] — MDO9 —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	E10

**Table 4. Functional port pin descriptions (continued)**

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET config.	Pin number		
								176 LQFP	208 LQFP	256 MAPBGA
PM[1]	PCR[193]	AF0 — AF1 — AF2 — AF3 —	GPIO[193] — MDO10 —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	E9
PM[2]	PCR[194]	AF0 — AF1 — AF2 — AF3 —	GPIO[194] — MDO11 —	SIUL — Nexus —	I/O — O —	M/S	Tristate	—	—	F12
PM[3]	PCR[195]	AF0 — AF1 — AF2 — AF3 —	GPIO[195] — — —	SIUL — — —	I/O — — —	M/S	Tristate	—	—	K12
PM[4]	PCR[196]	AF0 — AF1 — AF2 — AF3 —	GPIO[196] — — —	SIUL — — —	I/O — — —	M/S	Tristate	—	—	L12
PM[5]	PCR[197]	AF0 — AF1 — AF2 — AF3 —	GPIO[197] — — —	SIUL — — —	I/O — — —	M/S	Tristate	—	—	F9
PM[6]	PCR[198]	AF0 — AF1 — AF2 — AF3 —	GPIO[198] — — —	SIUL — — —	I/O — — —	M/S	Tristate	—	—	F6

<sup>1</sup> Alternate functions are chosen by setting the values of the PCR.PA bitfields inside the SIUL module. PCR.PA = 000 → AF0; PCR.PA = 001 → AF1; PCR.PA = 010 → AF2; PCR.PA = 011 → AF3; PCR.PA = 100 → ALT4. This is intended to select the output functions; to use one of the input functions, the PCR.IBE bit must be written to '1', regardless of the values selected in the PCR.PA bitfields. For this reason, the value corresponding to an input only function is reported as "—".

- <sup>2</sup> Multiple inputs are routed to all respective modules internally. The input of some modules must be configured by setting the values of the PSMIO.PADSELx bitfields inside the SIUL module.
- <sup>3</sup> NMI[0] and NMI[1] have a higher priority than alternate functions. When NMI is selected, the PCR.PA field is ignored.
- <sup>4</sup> SXOSC's OSC32k\_XTAL and OSC32k\_EXTAL pins are shared with GPIO functionality. When used as crystal pins, other functionality of the pin cannot be used and it should be ensured that application never programs OBE and PUE bit of the corresponding PCR to "1".
- <sup>5</sup> If you want to use OSC32K functionality through PB[8] and PB[9], you must ensure that PB[10] is static in nature as PB[10] can induce coupling on PB[9] and disturb oscillator frequency.
- <sup>6</sup> Out of reset all the functional pins except PC[0:1] and PH[9:10] are available to the user as GPIO.  
PC[0:1] are available as JTAG pins (TDI and TDO respectively).  
PH[9:10] are available as JTAG pins (TCK and TMS respectively).  
It is up to the user to configure these pins as GPIO when needed.

## Electrical Characteristics

- 7 When MBIST is enabled to run ( STCU Enable = 1), the application must not drive or tie PAD[178] (MDO[0]) to 0 V before the device exits reset (external reset is removed) as the pad is internally driven to 1 to indicate MBIST operation. When MBIST is not enabled (STCU Enable = 0), there are no restriction as the device does not internally drive the pad.
- 8 These pins can be configured as Nexus pins during reset by the debugger writing to the Nexus Development Interface "Port Control Register" rather than the SIUL. Specifically, the debugger can enable the MDO[7:0], MSEO, and MCKO ports by programming NDI (PCR[MCKO\_EN] or PCR[PSTAT\_EN]). MDO[8:11] ports can be enabled by programming NDI ((PCR[MCKO\_EN] and PCR[FPM]) or PCR[PSTAT\_EN]).

## 4 Electrical Characteristics

This section contains electrical characteristics of the device as well as temperature and power considerations.

This product contains devices to protect the inputs against damage due to high static voltages. However, it is advisable to take precautions to avoid application of any voltage higher than the specified maximum rated voltages.

To enhance reliability, unused inputs can be driven to an appropriate logic voltage level ( $V_{DD}$  or  $V_{SS\_HV}$ ). This could be done by the internal pull-up and pull-down, which is provided by the product for most general purpose pins.

The parameters listed in the following tables represent the characteristics of the device and its demands on the system.

In the tables where the device logic provides signals with their respective timing characteristics, the symbol “CC” for Controller Characteristics is included in the Symbol column.

In the tables where the external system must provide signals with their respective timing characteristics to the device, the symbol “SR” for System Requirement is included in the Symbol column.

### 4.1 Parameter classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding, the classifications listed in [Table 5](#) are used and the parameters are tagged accordingly in the tables where appropriate.

**Table 5. Parameter classifications**

Classification tag	Tag description
P	Those parameters are guaranteed during production testing on each individual device.
C	Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.
T	Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category.
D	Those parameters are derived mainly from simulations.

#### NOTE

The classification is shown in the column labeled “C” in the parameter tables where appropriate.

### 4.2 NVUSRO register

Portions of the device configuration, such as high voltage supply is controlled via bit values in the Non-Volatile User Options Register (NVUSRO). For a detailed description of the NVUSRO register, see MPC5646C Reference Manual.

### 4.2.1 NVUSRO [PAD3V5V(0)] field description

Table 6 shows how NVUSRO [PAD3V5V(0)] controls the device configuration for V<sub>DD\_HV\_A</sub> domain.

**Table 6. PAD3V5V(0) field description**

Value <sup>1</sup>	Description
0	High voltage supply is 5.0 V
1	High voltage supply is 3.3 V

<sup>1</sup> '1' is delivery value. It is part of shadow flash memory, thus programmable by customer.

The DC electrical characteristics are dependent on the PAD3V5V(0,1) bit value.

### 4.2.2 NVUSRO [PAD3V5V(1)] field description

Table 7 shows how NVUSRO [PAD3V5V(1)] controls the device configuration for V<sub>DD\_HV\_B</sub> domain.

**Table 7. PAD3V5V(1) field description**

Value <sup>1</sup>	Description
0	High voltage supply is 5.0 V
1	High voltage supply is 3.3 V

<sup>1</sup> '1' is delivery value. It is part of shadow flash memory, thus programmable by customer.

The DC electrical characteristics are dependent on the PAD3V5V(0,1) bit value.

## 4.3 Absolute maximum ratings

**Table 8. Absolute maximum ratings**

Symbol	Parameter	Conditions	Value		Unit
			Min	Max	
V <sub>SS_HV</sub>	SR	Digital ground on VSS_HV pins	—	0	0
V <sub>DD_HV_A</sub>	SR	Voltage on VDD_HV_A pins with respect to ground (V <sub>SS_HV</sub> )	—	-0.3	6.0
V <sub>DD_HV_B</sub> <sup>1</sup>	SR	Voltage on VDD_HV_B pins with respect to common ground (V <sub>SS_HV</sub> )	—	-0.3	6.0
V <sub>SS_LV</sub>	SR	Voltage on VSS_LV (low voltage digital supply) pins with respect to ground (V <sub>SS_HV</sub> )	—	V <sub>SS_HV</sub> - 0.1	V <sub>SS_HV</sub> + 0.1
V <sub>RC_CTRL</sub> <sup>2</sup>		Base control voltage for external BCP68 NPN device	Relative to V <sub>DD_LV</sub>	0	V <sub>DD_LV</sub> + 1

## Electrical Characteristics

**Table 8. Absolute maximum ratings (continued)**

Symbol	Parameter	Conditions	Value		Unit	
			Min	Max		
$V_{SS\_ADC}$	SR	Voltage on $VSS\_HV\_ADC0$ , $VSS\_HV\_ADC1$ (ADC reference) pin with respect to ground ( $V_{SS\_HV}$ )	—	$V_{SS\_HV} - 0.1$	$V_{SS\_HV} + 0.1$	V
$V_{DD\_HV\_ADC0}$	SR	Voltage on $VDD\_HV\_ADC0$ with respect to ground ( $V_{SS\_HV}$ )	—	-0.3	6.0	V
			Relative to $V_{DD\_HV\_A}$ <sup>3</sup>	$V_{DD\_HV\_A} - 0.3$	$V_{DD\_HV\_A} + 0.3$	
$V_{DD\_HV\_ADC1}$ <sup>4</sup>	SR	Voltage on $VDD\_HV\_ADC1$ with respect to ground ( $V_{SS\_HV}$ )	—	-0.3	6.0	V
			Relative to $V_{DD\_HV\_A}$ <sup>2</sup>	$V_{DD\_HV\_A} - 0.3$	$V_{DD\_HV\_A} + 0.3$	
$V_{IN}$	SR	Voltage on any GPIO pin with respect to ground ( $V_{SS\_HV}$ )	Relative to $V_{DD\_HV\_A/HV\_B}$	$V_{DD\_HV\_A/HV\_B} - 0.3$	$V_{DD\_HV\_A/HV\_B} + 0.3$	V
$I_{INJPAD}$	SR	Injected input current on any pin during overload condition	—	-10	10	mA
$I_{INJSUM}$	SR	Absolute sum of all injected input currents during overload condition	—	-50	50	
$I_{AVGSEG}$ <sup>5</sup>	SR	Sum of all the static I/O current within a supply segment ( $V_{DD\_HV\_A}$ or $V_{DD\_HV\_B}$ )	$V_{DD} = 5.0 \text{ V} \pm 10\%$ , $PAD3V5V = 0$		70	mA
			$V_{DD} = 3.3 \text{ V} \pm 10\%$ , $PAD3V5V = 1$		64	
$T_{STORAGE}$	SR	Storage temperature	—	-55 <sup>6</sup>	150	°C

<sup>1</sup>  $V_{DD\_HV\_B}$  can be independently controlled from  $V_{DD\_HV\_A}$ . These can ramp up or ramp down in any order. Design is robust against any supply order.

<sup>2</sup> This voltage is internally generated by the device and no external voltage should be supplied.

<sup>3</sup> Both the relative and the fixed conditions must be met. For instance: If  $V_{DD\_HV\_A}$  is 5.9 V,  $V_{DD\_HV\_ADC0}$  maximum value is 6.0 V then, despite the relative condition, the max value is  $V_{DD\_HV\_A} + 0.3 = 6.2$  V.

<sup>4</sup> PA3, PA7, PA10, PA11 and PE12 ADC\_1 channels are coming from  $V_{DD\_HV\_B}$  domain hence  $V_{DD\_HV\_ADC1}$  should be within  $\pm 300$  mV of  $V_{DD\_HV\_B}$  when these channels are used for ADC\_1.

<sup>5</sup> Any temperature beyond 125 °C should limit the current to 50 mA (max).

<sup>6</sup> This is the storage temperature for the flash memory.

## NOTE

Stresses exceeding the recommended absolute maximum ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. During overload conditions ( $V_{IN} > V_{DD\_HV\_A/HV\_B}$  or  $V_{IN} < V_{SS\_HV}$ ), the voltage on pins with respect to ground ( $V_{SS\_HV}$ ) must not exceed the recommended values.

## 4.4 Recommended operating conditions

Table 9. Recommended operating conditions (3.3 V)

Symbol		Parameter	Conditions	Value		Unit
				Min	Max	
V <sub>SS_HV</sub>	SR	Digital ground on VSS_HV pins	—	0	0	V
V <sub>DD_HV_A</sub> <sup>1</sup>	SR	Voltage on V <sub>DD_HV_A</sub> pins with respect to ground (V <sub>SS_HV</sub> )	—	3.0	3.6	V
V <sub>DD_HV_B</sub> <sup>1</sup>	SR	Voltage on V <sub>DD_HV_B</sub> pins with respect to ground (V <sub>SS_HV</sub> )	—	3.0	3.6	V
V <sub>SS_LV</sub> <sup>2</sup>	SR	Voltage on VSS_LV (low voltage digital supply) pins with respect to ground (V <sub>SS_HV</sub> )	—	V <sub>SS_HV</sub> − 0.1	V <sub>SS_HV</sub> + 0.1	V
V <sub>RC_CTRL</sub> <sup>3</sup>		Base control voltage for external BCP68 NPN device	Relative to V <sub>DD_LV</sub>	0	V <sub>DD_LV</sub> + 1	V
V <sub>SS_ADC</sub>	SR	Voltage on VSS_HV_ADC0, VSS_HV_ADC1 (ADC reference) pin with respect to ground (V <sub>SS_HV</sub> )	—	V <sub>SS_HV</sub> − 0.1	V <sub>SS_HV</sub> + 0.1	V
V <sub>DD_HV_ADC0</sub> <sup>4</sup>	SR	Voltage on VDD_HV_ADC0 with respect to ground (V <sub>SS_HV</sub> )	—	3.0 <sup>5</sup>	3.6	V
			Relative to V <sub>DD_HV_A</sub> <sup>6</sup>	V <sub>DD_HV_A</sub> − 0.1	V <sub>DD_HV_A</sub> + 0.1	
V <sub>DD_HV_ADC1</sub> <sup>7</sup>	SR	Voltage on VDD_HV_ADC1 with respect to ground (V <sub>SS_HV</sub> )	—	3.0	3.6	V
			Relative to V <sub>DD_HV_A</sub> <sup>6</sup>	V <sub>DD_HV_A</sub> − 0.1	V <sub>DD_HV_A</sub> + 0.1	
V <sub>IN</sub>	SR	Voltage on any GPIO pin with respect to ground (V <sub>SS_HV</sub> )	—	V <sub>SS_HV</sub> − 0.1	—	V
			Relative to V <sub>DD_HV_A/HV_B</sub>	—	V <sub>DD_HV_A/HV_B</sub> + 0.1	
I <sub>INJPAD</sub>	SR	Injected input current on any pin during overload condition	—	−5	5	mA
I <sub>INJSUM</sub>	SR	Absolute sum of all injected input currents during overload condition	—	−50	50	
T <sub>VDD</sub>	SR	V <sub>DD_HV_A</sub> slope to ensure correct power up <sup>8</sup>	—	—	0.5	V/μs
			—	0.5	—	V/min
T <sub>A</sub>	SR	Ambient temperature under bias	f <sub>CPU</sub> up to 120 MHz + 2%	−40	125	°C
T <sub>J</sub>	SR	Junction temperature under bias	—	−40	150	

<sup>1</sup> 100 nF EMI capacitance need to be provided between each VDD/VSS\_HV pair.

## Electrical Characteristics

- <sup>2</sup> 100 nF EMI capacitance needs to be provided between each VDD\_LV/VSS\_LV supply pair. 10  $\mu$ F bulk capacitance needs to be provided as CREG on each VDD\_LV pin. For details refer to the Power Management chapter of the MPC5646C Reference Manual.
- <sup>3</sup> This voltage is internally generated by the device and no external voltage should be supplied.
- <sup>4</sup> 100 nF capacitance needs to be provided between V<sub>DD\_ADC</sub>/V<sub>SS\_ADC</sub> pair.
- <sup>5</sup> Full electrical specification cannot be guaranteed when voltage drops below 3.0 V. In particular, ADC electrical characteristics and I/Os DC electrical specification may not be guaranteed. When voltage drops below V<sub>LVDHVL</sub>, device is reset.
- <sup>6</sup> Both the relative and the fixed conditions must be met. For instance: If V<sub>DD\_HV\_A</sub> is 5.9 V, V<sub>DD\_HV\_ADC0</sub> maximum value is 6.0 V then, despite the relative condition, the max value is V<sub>DD\_HV\_A</sub> + 0.3 = 6.2 V.
- <sup>7</sup> PA3, PA7, PA10, PA11 and PE12 ADC\_1 channels are coming from V<sub>DD\_HV\_B</sub> domain hence V<sub>DD\_HV\_ADC1</sub> should be within  $\pm 100$  mV of V<sub>DD\_HV\_B</sub> when these channels are used for ADC\_1.
- <sup>8</sup> Guaranteed by the device validation.

**Table 10. Recommended operating conditions (5.0 V)**

Symbol	Parameter	Conditions	Value		Unit	
			Min	Max		
V <sub>SS_HV</sub>	SR	Digital ground on VSS_HV pins	—	0	0	V
V <sub>DD_HV_A</sub> <sup>1</sup>	SR	Voltage on VDD_HV_A pins with respect to ground (V <sub>SS_HV</sub> )	—	4.5	5.5	V
			Voltage drop <sup>2</sup>	3.0	5.5	
V <sub>DD_HV_B</sub>	SR	Generic GPIO functionality	—	3.0	5.5	V
		Ethernet/3.3 V functionality (See the notes in all figures in <a href="#">Section 3, "Package pinouts and signal descriptions"</a> for the list of channels operating in V <sub>DD_HV_B</sub> domain)	—	3.0	3.6	V
V <sub>SS_LV</sub> <sup>3</sup>	SR	Voltage on VSS_LV (Low voltage digital supply) pins with respect to ground (V <sub>SS_HV</sub> )	—	V <sub>SS_HV</sub> - 0.1	V <sub>SS_HV</sub> + 0.1	V
V <sub>RC_CTRL</sub> <sup>4</sup>		Base control voltage for external BCP68 NPN device	Relative to V <sub>DD_LV</sub>	0	V <sub>DD_LV</sub> + 1	V
V <sub>SS_ADC</sub>	SR	Voltage on VSS_HV_ADC0, VSS_HV_ADC1 (ADC reference) pin with respect to ground (V <sub>SS_HV</sub> )	—	V <sub>SS_HV</sub> - 0.1	V <sub>SS_HV</sub> + 0.1	V
V <sub>DD_HV_ADC0</sub> <sup>5</sup>	SR	Voltage on VDD_HV_ADC0 with respect to ground (V <sub>SS_HV</sub> )	—	4.5	5.5	V
			Voltage drop <sup>(2)</sup>	3.0	5.5	
			Relative to V <sub>DD_HV_A</sub> <sup>6</sup>	V <sub>DD_HV_A</sub> - 0.1	V <sub>DD_HV_A</sub> + 0.1	
V <sub>DD_HV_ADC1</sub> <sup>7</sup>	SR	Voltage on VDD_HV_ADC1 with respect to ground (V <sub>SS_HV</sub> )	—	4.5	5.5	V
			Voltage drop <sup>(2)</sup>	3.0	5.5	
			Relative to V <sub>DD_HV_A</sub> <sup>6</sup>	V <sub>DD_HV_A</sub> - 0.1	V <sub>DD_HV_A</sub> + 0.1	

**Table 10. Recommended operating conditions (5.0 V) (continued)**

Symbol	Parameter	Conditions	Value		Unit
			Min	Max	
$V_{IN}$	SR	Voltage on any GPIO pin with respect to ground ( $V_{SS\_HV}$ )	—	$V_{SS\_HV} - 0.1$	—
			Relative to $V_{DD\_HV\_A/HV\_B}$	—	$V_{DD\_HV\_A/HV\_B} + 0.1$
$I_{INJPAD}$	SR	Injected input current on any pin during overload condition	—	-5	5
$I_{INJSUM}$	SR	Absolute sum of all injected input currents during overload condition	—	-50	50
$TV_{DD}$	SR	$V_{DD\_HV\_A}$ slope to ensure correct power up <sup>8</sup>	—	—	0.5
			—	0.5	—
$T_A$ C-Grade Part	SR	Ambient temperature under bias	—	-40	85
$T_J$ C-Grade Part	SR	Junction temperature under bias	—	-40	110
$T_A$ V-Grade Part	SR	Ambient temperature under bias	—	-40	105
$T_J$ V-Grade Part	SR	Junction temperature under bias	—	-40	130
$T_A$ M-Grade Part	SR	Ambient temperature under bias	—	-40	125
$T_J$ M-Grade Part	SR	Junction temperature under bias	—	-40	150

<sup>1</sup> 100 nF EMI capacitance need to be provided between each VDD/VSS\_HV pair.

<sup>2</sup> Full device operation is guaranteed by design from 3.0 V–5.5 V. OSC functionality is guaranteed from the entire range 3.0V–5.5 V, the parametrics measured are at 3.0V and 5.5V (extreme voltage ranges to cover the range of operation). The parametrics might have some variation in the intermediate voltage range, but there is no impact to functionality.

<sup>3</sup> 100 nF EMI capacitance needs to be provided between each VDD\_LV/VSS\_LV supply pair. 10  $\mu$ F bulk capacitance needs to be provided as CREG on each VDD\_LV pin.

<sup>4</sup> This voltage is internally generated by the device and no external voltage should be supplied.

<sup>5</sup> 100 nF capacitance needs to be provided between  $V_{DD\_HV\_(ADC0/ADC1)}$ / $V_{SS\_HV\_(ADC0/ADC1)}$  pair.

<sup>6</sup> Both the relative and the fixed conditions must be met. For instance: If  $V_{DD\_HV\_A}$  is 5.9 V,  $V_{DD\_HV\_ADC0}$  maximum value is 6.0 V then, despite the relative condition, the max value is  $V_{DD\_HV\_A} + 0.3 = 6.2$  V.

<sup>7</sup> PA3, PA7, PA10, PA11 and PE12 ADC\_1 channels are coming from  $V_{DD\_HV\_B}$  domain hence VDD\_HV\_ADC1 should be within  $\pm 100$  mV of  $V_{DD\_HV\_B}$  when these channels are used for ADC\_1.

<sup>8</sup> Guaranteed by device validation.

## NOTE

SRAM retention guaranteed to LVD levels.

## 4.5 Thermal characteristics

### 4.5.1 Package thermal characteristics

Table 11. LQFP thermal characteristics<sup>1</sup>

Symbol	C	Parameter	Conditions <sup>2</sup>	Pin count	Value <sup>3</sup>			Unit
					Min	Typ	Max	
$R_{\theta JA}$	CC	D	Thermal resistance, junction-to-ambient natural convection <sup>4</sup>	Single-layer board—1s	176	—	—	38 <sup>5</sup> °C/W
					208	—	—	41 <sup>6</sup> °C/W
$R_{\theta JA}$	CC	D	Thermal resistance, junction-to-ambient natural convection <sup>7</sup>	Four-layer board—2s2p <sup>7</sup>	176	—	—	31 °C/W
					208	—	—	34 °C/W

<sup>1</sup> Thermal characteristics are targets based on simulation that are subject to change per device characterization.

<sup>2</sup>  $V_{DD} = 3.3 \text{ V} \pm 10\% / 5.0 \text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125$  °C.

<sup>3</sup> All values need to be confirmed during device validation.

<sup>4</sup> Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.

<sup>5</sup> Junction-to-Ambient thermal resistance determined per JEDEC JESD51-3 and JESD51-6.

<sup>6</sup> Junction-to-Ambient thermal resistance determined per JEDEC JESD51-2 and JESD51-6

<sup>7</sup> Junction-to-Board thermal resistance determined per JEDEC JESD51-8.

Table 12. 256 MAPBGA thermal characteristics<sup>1</sup>

Symbol	C	Parameter	Conditions	Value	Unit	
$R_{\theta JA}$	CC	—	Thermal resistance, junction-to-ambient natural convection	Single-layer board—1s	43 <sup>2</sup>	°C/W
				Four-layer board—2s2p	26 <sup>3</sup>	

<sup>1</sup> Thermal characteristics are targets based on simulation that are subject to change per device characterization.

<sup>2</sup> Junction-to-ambient thermal resistance determined per JEDEC JESD51-2 with the single layer board horizontal. Board meets JESD51-9 specification.

<sup>3</sup> Junction-to-ambient thermal resistance determined per JEDEC JESD51-6 with the board horizontal.

### 4.5.2 Power considerations

The average chip-junction temperature,  $T_J$ , in degrees Celsius, may be calculated using [Equation 1](#):

$$T_J = T_A + (P_D \times R_{\theta JA})$$

*Eqn. 1*

Where:

$T_A$  is the ambient temperature in °C.

$R_{\theta JA}$  is the package junction-to-ambient thermal resistance, in °C/W.

$P_D$  is the sum of  $P_{INT}$  and  $P_{I/O}$  ( $P_D = P_{INT} + P_{I/O}$ ).

$P_{INT}$  is the product of  $I_{DD}$  and  $V_{DD}$ , expressed in watts. This is the chip internal power.

$P_{I/O}$  represents the power dissipation on input and output pins; user determined.

Most of the time for the applications,  $P_{I/O} < P_{INT}$  and may be neglected. On the other hand,  $P_{I/O}$  may be significant, if the device is configured to continuously drive external modules and/or memories.

An approximate relationship between  $P_D$  and  $T_J$  (if  $P_{I/O}$  is neglected) is given by:

$$P_D = K / (T_J + 273 \text{ } ^\circ\text{C}) \quad Eqn. 2$$

Therefore, solving equations 1 and 2:

$$K = P_D \times (T_A + 273 \text{ } ^\circ\text{C}) + R_{0JA} \times P_D^2 \quad Eqn. 3$$

Where:

$K$  is a constant for the particular part, which may be determined from [Equation 3](#) by measuring  $P_D$  (at equilibrium) for a known  $T_A$ . Using this value of  $K$ , the values of  $P_D$  and  $T_J$  may be obtained by solving equations 1 and 2 iteratively for any value of  $T_A$ .

## 4.6 I/O pad electrical characteristics

### 4.6.1 I/O pad types

The device provides four main I/O pad types depending on the associated alternate functions:

- Slow pads—These pads are the most common pads, providing a good compromise between transition time and low electromagnetic emission.
- Medium pads—These pads provide transition fast enough for the serial communication channels with controlled current to reduce electromagnetic emission.
- Fast pads—These pads provide maximum speed. These are used for improved Nexus debugging capability.
- Input only pads—These pads are associated to ADC channels and 32 kHz low power external crystal oscillator providing low input leakage.
- Low power pads—These pads are active in standby mode for wakeup source.

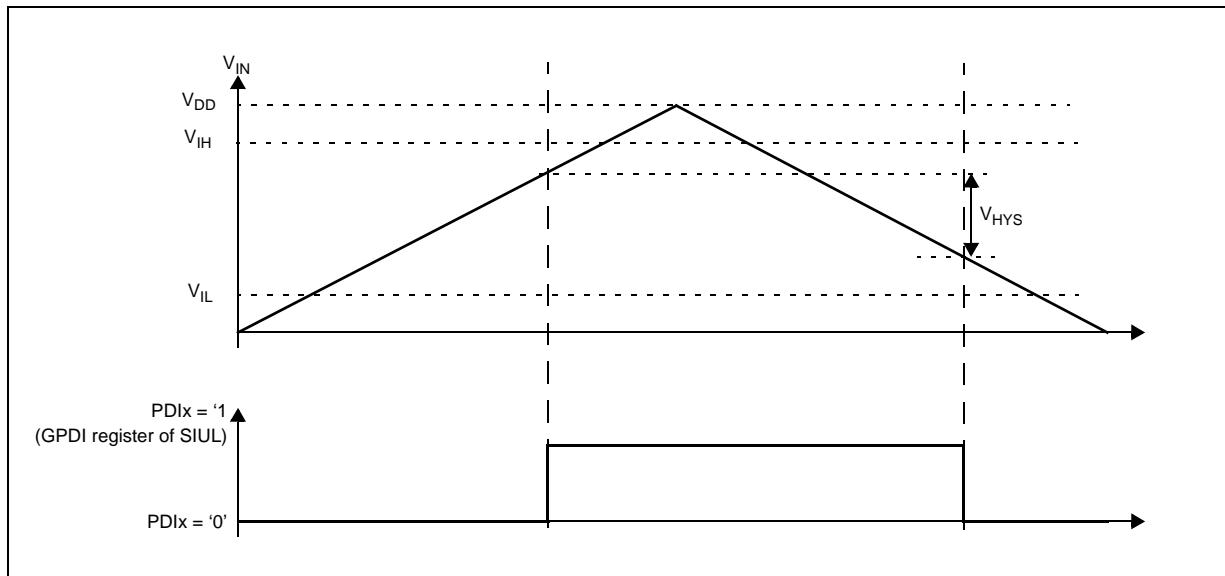
Also, medium/slow and fast/medium pads are available in design which can be configured to behave like a slow/medium and medium/fast pads depending upon the slew-rate control.

Medium and fast pads can use slow configuration to reduce electromagnetic emission, at the cost of reducing AC performance.

### 4.6.2 I/O input DC characteristics

[Table 13](#) provides input DC electrical characteristics as described in [Figure 5](#).

## Electrical Characteristics



**Figure 5. I/O input DC electrical characteristics definition**

**Table 13. I/O input DC electrical characteristics**

Symbol	C	Parameter	Conditions <sup>1</sup>	Value <sup>2</sup>			Unit	
				Min	Typ	Max		
V <sub>IH</sub>	SR	P	Input high level CMOS (Schmitt Trigger)	—	0.65V <sub>DD</sub>	—	V <sub>DD</sub> + 0.4	
V <sub>IL</sub>	SR	P	Input low level CMOS (Schmitt Trigger)	—	-0.3	—	0.35V <sub>DD</sub>	
V <sub>HYS</sub>	CC	C	Input hysteresis CMOS (Schmitt Trigger)	—	0.1V <sub>DD</sub>	—	—	
I <sub>LKG</sub>	CC	P	Digital input leakage	No injection on adjacent pin	T <sub>A</sub> = -40 °C	—	2	nA
					T <sub>A</sub> = 25 °C	—	2	
					T <sub>A</sub> = 105 °C	—	12	
					T <sub>A</sub> = 125 °C	—	500	
W <sub>FI</sub>	SR	P	Width of input pulse rejected by analog filter <sup>3</sup>	—	—	—	40 <sup>4</sup>	ns
					—	—	1000 <sup>4</sup>	
W <sub>NFI</sub>	SR	P	Width of input pulse accepted by analog filter <sup>(3)</sup>	—	—	—	—	ns

<sup>1</sup> V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.

<sup>2</sup> V<sub>DD</sub> as mentioned in the table is V<sub>DD\_HV\_A</sub>/V<sub>DD\_HV\_B</sub>. All values need to be confirmed during device validation.

<sup>3</sup> Analog filters are available on all wakeup lines.

<sup>4</sup> The width of input pulse in between 40 ns to 1000 ns is indeterminate. It may pass the noise or may not depending on silicon sample to sample variation.

### 4.6.3 I/O output DC characteristics

The following tables provide DC characteristics for bidirectional pads:





**Table 17. FAST configuration output buffer electrical characteristics (continued)**

Symbol	C	Parameter	Conditions <sup>1,2</sup>	Value			Unit		
				Min	Typ	Max			
V <sub>OL</sub>	CC	P	Output low level FAST configuration	Push Pull	I <sub>OL</sub> = 14 mA, V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0	—	—	0.1V <sub>DD</sub>	V
		C			I <sub>OL</sub> = 7 mA, V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 1 <sup>(3)</sup>	—	—	0.1V <sub>DD</sub>	
		C			I <sub>OL</sub> = 11 mA, V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1	—	—	0.5	

<sup>1</sup> V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.<sup>2</sup> V<sub>DD</sub> as mentioned in the table is V<sub>DD\_HV\_A</sub>/V<sub>DD\_HV\_B</sub>.<sup>3</sup> The configuration PAD3V5 = 1 when V<sub>DD</sub> = 5 V is only a transient configuration during power-up. All pads but RESET and Nexus outputs (MDOx, EVTO, MCKO) are configured in input or in high impedance state.

## 4.6.4 Output pin transition times

**Table 18. Output pin transition times**

Symbol	C	Parameter	Conditions <sup>1,2</sup>	Value <sup>3</sup>			Unit		
				Min	Typ	Max			
T <sub>tr</sub>	CC	D	Output transition time output pin <sup>4</sup> SLOW configuration	C <sub>L</sub> = 25 pF	V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0	—	—	50	ns
		T		C <sub>L</sub> = 50 pF		—	—	100	
		D		C <sub>L</sub> = 100 pF		—	—	125	
		D		C <sub>L</sub> = 25 pF	V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1	—	—	40	
		T		C <sub>L</sub> = 50 pF		—	—	50	
		D		C <sub>L</sub> = 100 pF		—	—	75	
		D		C <sub>L</sub> = 25 pF	V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0 SIUL.PCRx.SRC = 1	—	—	10	
T <sub>tr</sub>	CC	T		C <sub>L</sub> = 50 pF		—	—	20	
		D		C <sub>L</sub> = 100 pF		—	—	40	
		D		C <sub>L</sub> = 25 pF	V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1 SIUL.PCRx.SRC = 1	—	—	12	
		T		C <sub>L</sub> = 50 pF		—	—	25	
		D		C <sub>L</sub> = 100 pF		—	—	40	

## Electrical Characteristics

**Table 18. Output pin transition times (continued)**

Symbol	C	Parameter	Conditions <sup>1,2</sup>		Value <sup>3</sup>			Unit
					Min	Typ	Max	
T <sub>tr</sub>	CC	D	Output transition time output pin <sup>(4)</sup> FAST configuration	C <sub>L</sub> = 25 pF	V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0	—	—	4
				C <sub>L</sub> = 50 pF		—	—	6
				C <sub>L</sub> = 100 pF		—	—	12
			C <sub>L</sub> = 25 pF C <sub>L</sub> = 50 pF C <sub>L</sub> = 100 pF	V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1	—	—	4	ns
					—	—	7	
					—	—	12	

<sup>1</sup> V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.

<sup>2</sup> V<sub>DD</sub> as mentioned in the table is V<sub>DD\_HV\_A</sub>/V<sub>DD\_HV\_B</sub>.

<sup>3</sup> All values need to be confirmed during device validation.

<sup>4</sup> C<sub>L</sub> includes device and package capacitances (C<sub>PKG</sub> < 5 pF).

## 4.6.5 I/O pad current specification

The I/O pads are distributed across the I/O supply segment. Each I/O supply is associated to a V<sub>DD</sub>/V<sub>SS\_HV</sub> supply pair as described in [Table 19](#).

[Table 20](#) provides I/O consumption figures.

In order to ensure device reliability, the average current of the I/O on a single segment should remain below the I<sub>AVGSEG</sub> maximum value.

In order to ensure device functionality, the sum of the dynamic and static current of the I/O on a single segment should remain below the I<sub>DYNSEG</sub> maximum value.

**Table 19. I/O supplies**

Package	I/O Supplies							
256 MAPBGA	Equivalent to 208-pin LQFP segment pad distribution + G6, G11, H11, J11							
208 LQFP	pin6 (V <sub>DD_HV_A</sub> ) pin7 (V <sub>SS_HV</sub> )	pin27 (V <sub>DD_HV_A</sub> ) pin28 (V <sub>SS_HV</sub> )	pin73 (V <sub>SS_HV</sub> ) pin75 (V <sub>DD_HV_A</sub> )	pin101 (V <sub>DD_HV_A</sub> ) pin102 (V <sub>SS_HV</sub> )	pin132 (V <sub>SS_HV</sub> ) pin133 (V <sub>DD_HV_A</sub> )	pin147 (V <sub>SS_HV</sub> ) pin148 (V <sub>DD_HV_B</sub> )	pin174 (V <sub>SS_HV</sub> ) pin175 (V <sub>DD_HV_A</sub> )	—
176 LQFP	pin6 (V <sub>DD_HV_A</sub> ) pin7 (V <sub>SS_HV</sub> )	pin27 (V <sub>DD_HV_A</sub> ) pin28 (V <sub>SS_HV</sub> )	pin57 (V <sub>SS_HV</sub> ) pin59 (V <sub>DD_HV_A</sub> )	pin85 (V <sub>DD_HV_A</sub> ) pin86 (V <sub>SS_HV</sub> )	pin123 (V <sub>SS_HV</sub> ) pin124 (V <sub>DD_HV_B</sub> )	pin150 (V <sub>SS_HV</sub> ) pin151 (V <sub>DD_HV_A</sub> )	—	—



## Electrical Characteristics

### 4.7 RESET electrical characteristics

The device implements a dedicated bidirectional  $\overline{\text{RESET}}$  pin.

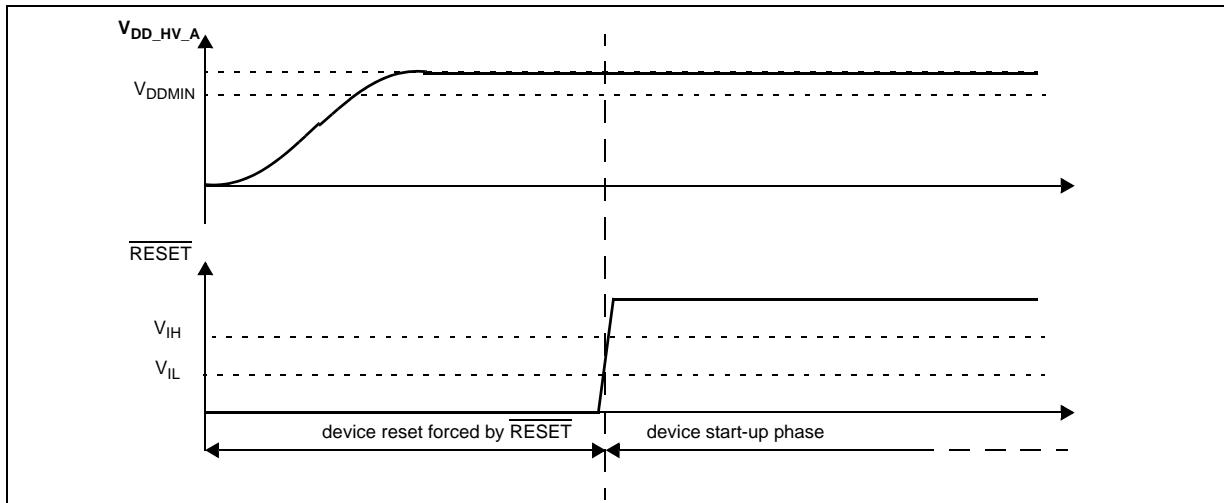


Figure 6. Start-up reset requirements

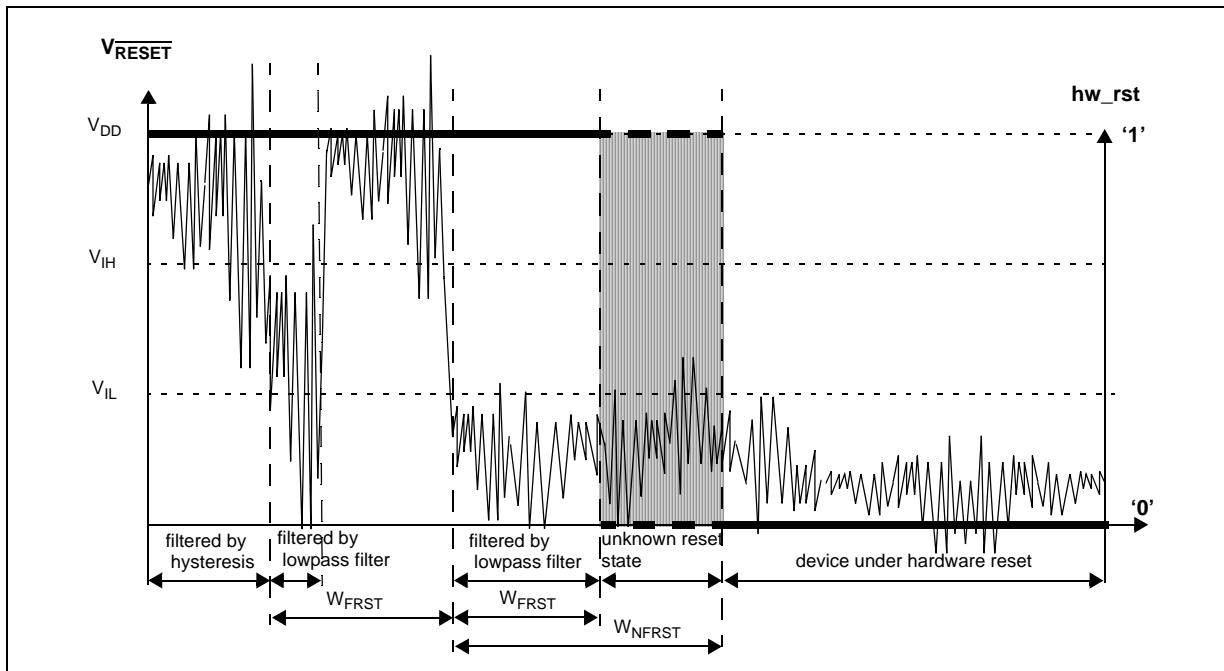


Figure 7. Noise filtering on reset signal

Table 21. Reset electrical characteristics

Symbol	C	Parameter	Conditions <sup>1</sup>	Value <sup>2</sup>			Unit
				Min	Typ	Max	
V <sub>IH</sub>	SR	P	Input High Level CMOS (Schmitt Trigger)	—	0.65V <sub>DD</sub>	—	V <sub>DD</sub> + 0.4 V

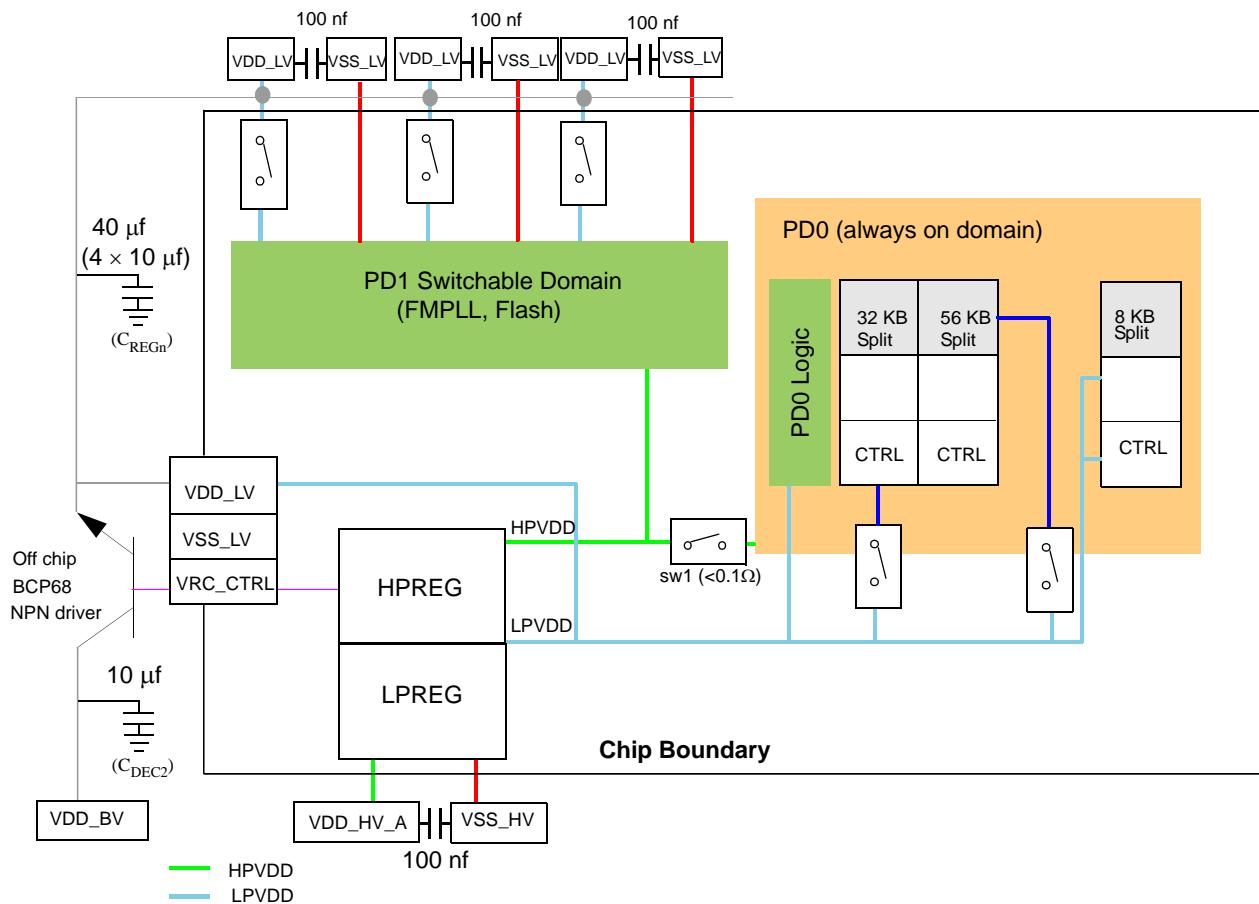


## 4.8 Power management electrical characteristics

### 4.8.1 Voltage regulator electrical characteristics

The device implements an internal voltage regulator to generate the low voltage core supply  $V_{DD\_LV}$  from the high voltage supply  $V_{DD\_HV\_A}$ . The following supplies are involved:

- HV: High voltage external power supply for voltage regulator module. This must be provided externally through  $V_{DD\_HV\_A}$  power pin.
- LV: Low voltage internal power supply for core, FMPLL and Flash digital logic. This is generated by the on-chip VREG with an external ballast (BCP68 NPN device). It is further split into four main domains to ensure noise isolation between critical LV modules within the device:
  - LV\_COR: Low voltage supply for the core. It is also used to provide supply for FMPLL through double bonding.
  - LV\_CFLA0/CFLA1: Low voltage supply for the two code Flash modules. It is shorted with LV\_COR through double bonding.
  - LV\_DFLA: Low voltage supply for data Flash module. It is shorted with LV\_COR through double bonding.
  - LV\_PLL: Low voltage supply for FMPLL. It is shorted to LV\_COR through double bonding.



**Figure 8. Voltage regulator capacitance connection**

The internal voltage regulator requires external bulk capacitance ( $C_{REGn}$ ) to be connected to the device to provide a stable low voltage digital supply to the device. Also required for stability is the  $C_{DEC2}$  capacitor at ballast collector. This is needed to



## Electrical Characteristics

**Table 22. Voltage regulator electrical characteristics (continued)**

Symbol	C	Parameter	Conditions <sup>1</sup>	Value <sup>2</sup>			Unit
				Min	Typ	Max	
I <sub>LPREG</sub>	SR	— Low power regulator current provided to V <sub>DD_LV</sub> domain	—	—	—	50	mA
I <sub>LPREGINT</sub>	CC	D Low power regulator module current consumption	I <sub>LPREG</sub> = 15 mA; T <sub>A</sub> = 55 °C	—	—	600	μA
			I <sub>LPREG</sub> = 0 mA; T <sub>A</sub> = 55 °C	—	20	—	
I <sub>VREGREF</sub>	CC	D Main LVDs and reference current consumption (low power and main regulator switched off)	T <sub>A</sub> = 55 °C	—	2	—	μA
I <sub>VREDLVD12</sub>	CC	D Main LVD current consumption (switch-off during standby)	T <sub>A</sub> = 55 °C	—	1	—	μA
I <sub>DD_HV_A</sub>	CC	D In-rush current on V <sub>DD_BV</sub> during power-up	—	—	—	600 <sup>3</sup>	mA

<sup>1</sup> V<sub>DD\_HV\_A</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = −40 to 125 °C, unless otherwise specified.

<sup>2</sup> All values need to be confirmed during device validation.

<sup>3</sup> Inrush current is seen more like steps of 600 mA peak. The startup of the regulator happens in steps of 50 mV in ~25 steps to reach ~1.2 V V<sub>DD\_LV</sub>. Each step peak current is within 600 mA

## 4.8.3 Voltage monitor electrical characteristics

The device implements a Power-on Reset module to ensure correct power-up initialization, as well as four low voltage detectors to monitor the V<sub>DD\_HV\_A</sub> and the V<sub>DD\_LV</sub> voltage while device is supplied:

- POR monitors V<sub>DD\_HV\_A</sub> during the power-up phase to ensure device is maintained in a safe reset state
- LVDHV3 monitors V<sub>DD\_HV\_A</sub> to ensure device is reset below minimum functional supply
- LVDHV5 monitors V<sub>DD\_HV\_A</sub> when application uses device in the 5.0 V±10% range
- LVDLVCOR monitors power domain No. 1 (PD1)
- LVDLVBKP monitors power domain No. 0 (PD0). VDD\_LV is same as PD0 supply.

### NOTE

When enabled, PD2 (RAM retention) is monitored through LVD\_DIGBKP.

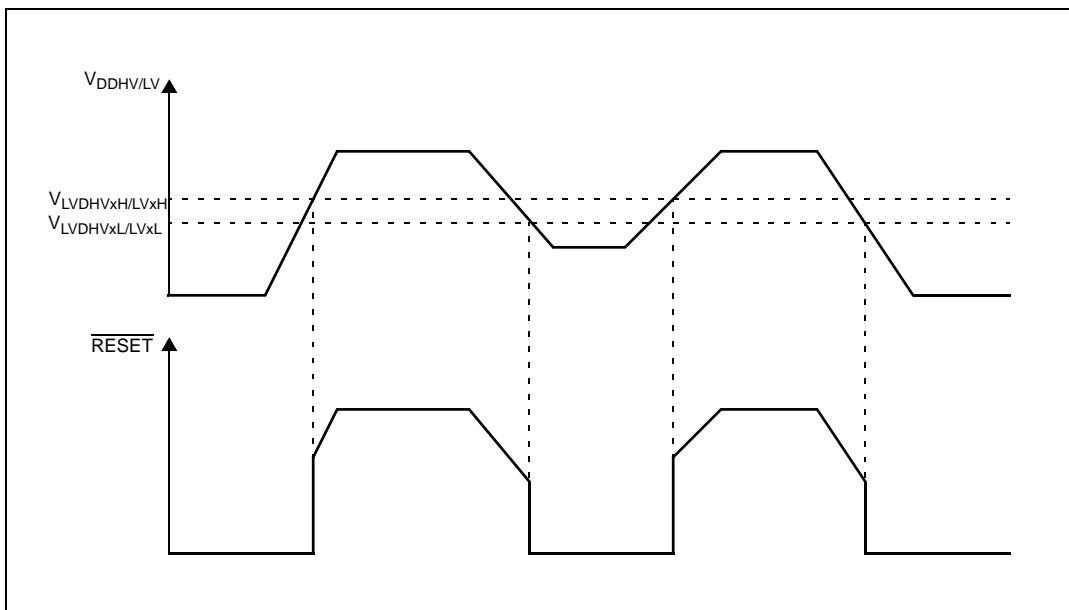


Figure 9. Low voltage monitor vs. Reset

Table 23. Low voltage monitor electrical characteristics

Symbol	C	Parameter	Conditions <sup>1</sup>	Value <sup>2</sup>			Unit
				Min	Typ	Max	
V <sub>PORUP</sub>	SR	P Supply for functional POR module	—	1.0	—	5.5	V
V <sub>PORH</sub>	CC	P Power-on reset threshold	—	1.5	—	2.6	
V <sub>LVDHV3H</sub>	CC	T LVDHV3 low voltage detector high threshold	—	2.7	—	2.85	
V <sub>LVDHV3L</sub>	CC	T LVDHV3 low voltage detector low threshold	—	2.6	—	2.74	
V <sub>LVDHV5H</sub>	CC	T LVDHV5 low voltage detector high threshold	—	4.3	—	4.5	
V <sub>LVDHV5L</sub>	CC	T LVDHV5 low voltage detector low threshold	—	4.2	—	4.4	
V <sub>LVLDLVCORL</sub>	CC	P LVLDLVCOR low voltage detector low threshold	T <sub>A</sub> = 25 °C, after trimming	1.12	1.145	1.17	
V <sub>LVDLVBKPL</sub>	CC	P LVDLVBKP low voltage detector low threshold		1.12	1.145	1.17	

<sup>1</sup> V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = –40 to 125 °C, unless otherwise specified.

<sup>2</sup> All values need to be confirmed during device validation.

## 4.9 Low voltage domain power consumption

Table 24 provides DC electrical characteristics for significant application modes. These values are indicative values; actual consumption depends on the application.









### 4.10.3 Flash memory start-up/switch-off timings

Table 30. Start-up time/Switch-off time

Symbol	C	Parameter	Conditions <sup>1</sup>	Value			Unit
				Min	Typ	Max	
$T_{FLARSTEXIT}$	CC	D	Delay for flash memory module to exit reset mode	Code flash memory	—	—	125
				Data flash memory		—	
$T_{FLALPEXIT}$	CC	T	Delay for flash memory module to exit low-power mode	Code flash memory	—	—	0.5
$T_{FLAPDEXIT}$	CC	T	Delay for flash memory module to exit power-down mode	Code flash memory	—	—	30
				Data flash memory		—	
$T_{FLALPENTRY}$	CC	T	Delay for flash memory module to enter low-power mode	Code flash memory	—	—	0.5

<sup>1</sup>  $V_{DD} = 3.3 \text{ V} \pm 10\% / 5.0 \text{ V} \pm 10\%$ ,  $T_A = -40 \text{ to } 125^\circ\text{C}$ , unless otherwise specified.

## 4.11 Electromagnetic compatibility (EMC) characteristics

Susceptibility tests are performed on a sample basis during product characterization.

### 4.11.1 Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user apply EMC software optimization and pre-qualification tests in relation with the EMC level requested for the application.

- Software recommendations – The software flowchart must include the management of runaway conditions such as:
  - Corrupted program counter
  - Unexpected reset
  - Critical data corruption (control registers)
- Pre-qualification trials – Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the reset pin or the oscillator pins for 1 second.  
To complete these trials, ESD stress can be applied directly on the device. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring.



## Electrical Characteristics

### 4.11.3.2 Static latch-up (LU)

Two complementary static tests are required on six parts to assess the latch-up performance:

- A supply over-voltage is applied to each power supply pin.
- A current injection is applied to each input, output and configurable I/O pin.

These tests are compliant with the EIA/JESD 78 IC latch-up standard.

Table 33. Latch-up results

Symbol	Parameter	Conditions	Class
LU	Static latch-up class	$T_A = 125^\circ\text{C}$ conforming to JESD 78	II level A

## 4.12 Fast external crystal oscillator (4–40 MHz) electrical characteristics

The device provides an oscillator/resonator driver. Figure 10 describes a simple model of the internal oscillator driver and provides an example of a connection for an oscillator or a resonator.

Table 34 provides the parameter description of 4 MHz to 40 MHz crystals used for the design simulations.

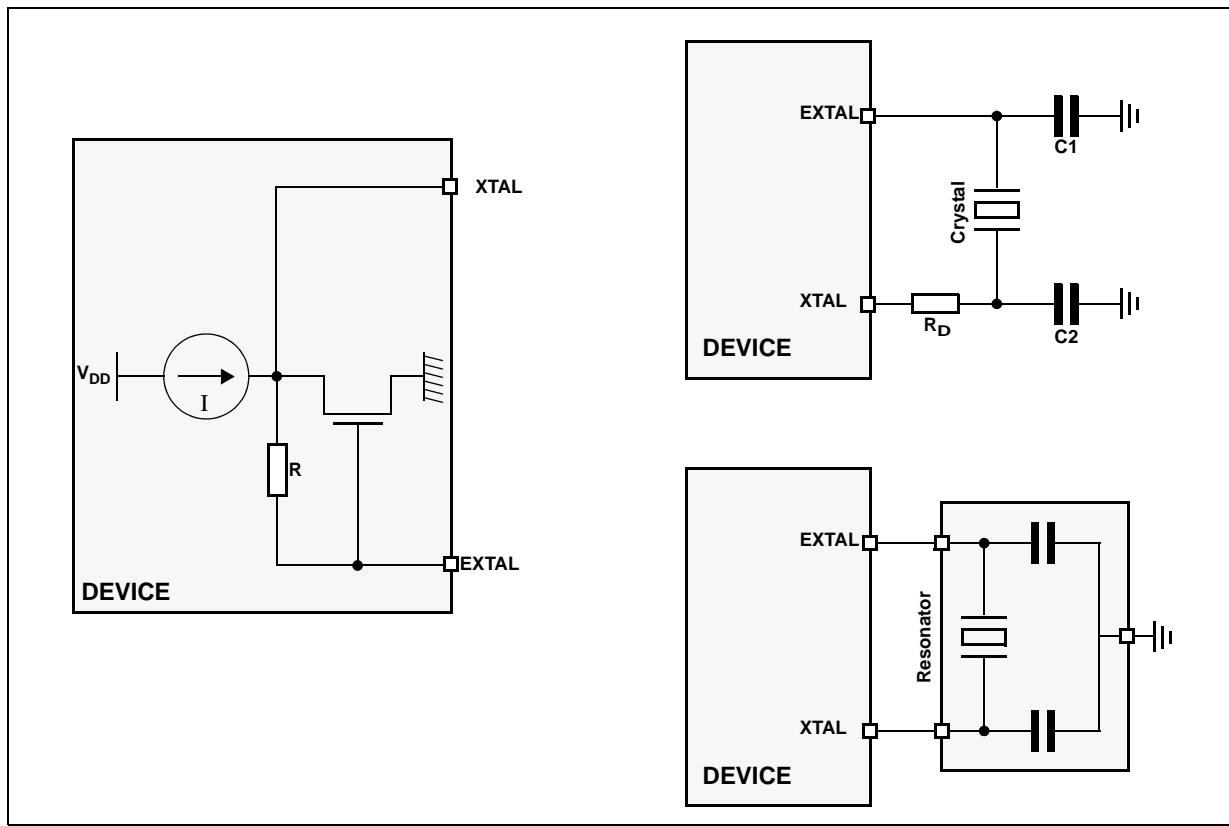


Figure 10. Crystal oscillator and resonator connection scheme

### NOTE

XTAL/EXTAL must not be directly used to drive external circuits.





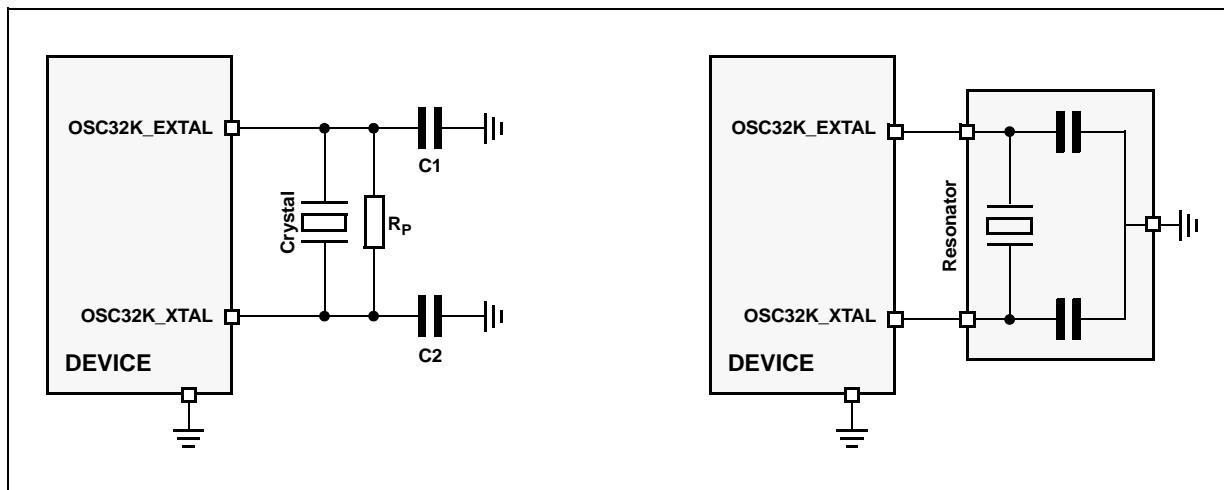


Figure 12. Crystal oscillator and resonator connection scheme

**NOTE**

OSC32K\_XTAL/OSC32K\_EXTAL must not be directly used to drive external circuits.

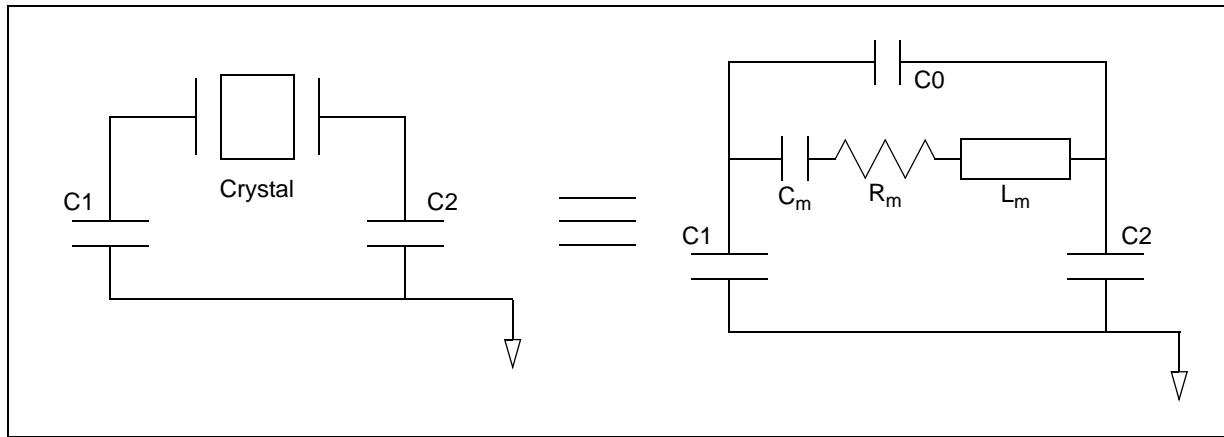


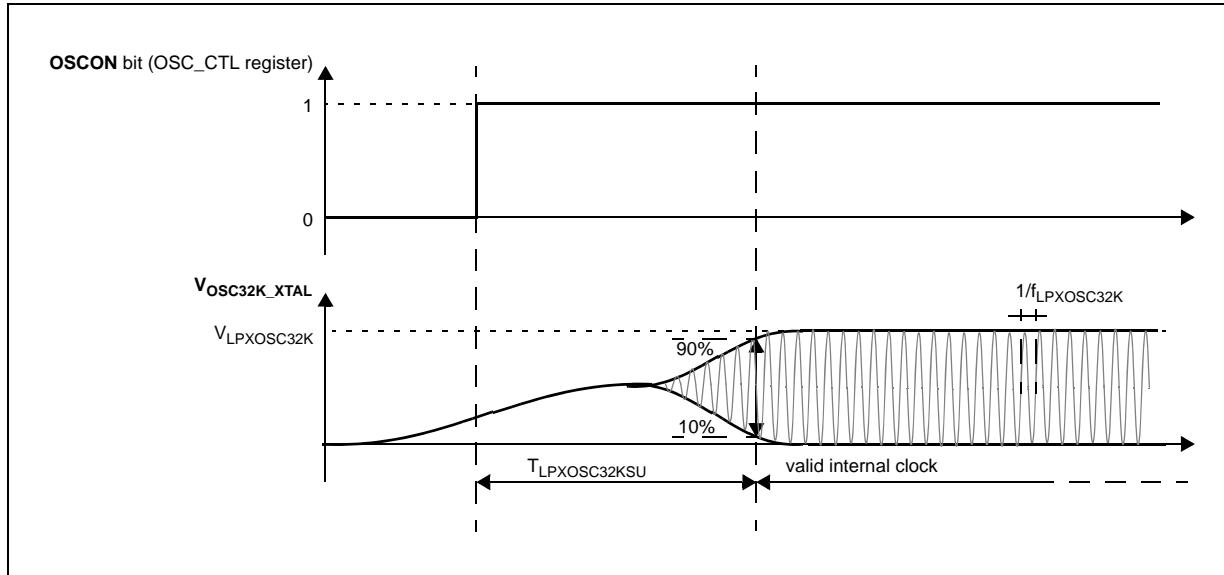
Figure 13. Equivalent circuit of a quartz crystal

Table 36. Crystal motional characteristics<sup>1</sup>

Symbol	Parameter	Conditions	Value			Unit
			Min	Typ	Max	
L <sub>m</sub>	Motional inductance	—	—	11.796	—	KH
C <sub>m</sub>	Motional capacitance	—	—	2	—	fF
C1/C2	Load capacitance at OSC32K_XTAL and OSC32K_EXTAL with respect to ground <sup>2</sup>	—	18	—	28	pF
R <sub>m</sub> <sup>3</sup>	Motional resistance	AC coupled @ C <sub>0</sub> = 2.85 pF <sup>4</sup>	—	—	65	kΩ
		AC coupled @ C <sub>0</sub> = 4.9 pF <sup>(4)</sup>	—	—	50	
		AC coupled @ C <sub>0</sub> = 7.0 pF <sup>(4)</sup>	—	—	35	
		AC coupled @ C <sub>0</sub> = 9.0 pF <sup>(4)</sup>	—	—	30	

## Electrical Characteristics

- 1 The crystal used is Epson Toyocom MC306.
- 2 This is the recommended range of load capacitance at OSC32K\_XTAL and OSC32K\_EXTAL with respect to ground. It includes all the parasitics due to board traces, crystal and package.
- 3 Maximum ESR ( $R_m$ ) of the crystal is 50 kΩ.
- 4 C0 Includes a parasitic capacitance of 2.0 pF between OSC32K\_XTAL and OSC32K\_EXTAL pins.



**Figure 14. Slow external crystal oscillator (32 kHz) electrical characteristics**

**Table 37. Slow external crystal oscillator (32 kHz) electrical characteristics**

Symbol	C	Parameter	Conditions <sup>1</sup>	Value <sup>2</sup>			Unit	
				Min	Typ	Max		
$f_{SXOSC}$	SR	Slow external crystal oscillator frequency	—	32	32.768	40	kHz	
$g_{mSXOSC}$	CC	Slow external crystal oscillator transconductance	$V_{DD} = 3.3 \text{ V} \pm 10\%$ ,	13 <sup>3</sup>	—	33 <sup>3</sup>	$\mu\text{A}/\text{V}$	
			$V_{DD} = 5.0 \text{ V} \pm 10\%$	15 <sup>3</sup>	—	35 <sup>3</sup>		
$V_{SXOSC}$	CC	T	Oscillation amplitude	—	1.2	1.4	1.7	V
$I_{SXOSCBIAS}$	CC	T	Oscillation bias current	—	1.2	—	4.4	$\mu\text{A}$
$I_{SXOSC}$	CC	T	Slow external crystal oscillator consumption	—	—	—	7	$\mu\text{A}$
$T_{SXOSCSU}$	CC	T	Slow external crystal oscillator start-up time	—	—	—	2 <sup>4</sup>	s

<sup>1</sup>  $V_{DD} = 3.3 \text{ V} \pm 10\% / 5.0 \text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125^\circ\text{C}$ , unless otherwise specified.

<sup>2</sup> All values need to be confirmed during device validation.

<sup>3</sup> Based on ATE CZ

<sup>4</sup> Start-up time has been measured with EPSON TOYOCOM MC306 crystal. Variation may be seen with other crystal.

## 4.14 FMPLL electrical characteristics

The device provides a frequency-modulated phase-locked loop (FMPLL) module to generate a fast system clock from the main oscillator driver.

**Table 38. FMPLL electrical characteristics**

Symbol	C	Parameter	Conditions <sup>1</sup>	Value <sup>2</sup>			Unit
				Min	Typ	Max	
f <sub>PLLIN</sub>	SR	—	FMPLL reference clock <sup>3</sup>	—	4	—	64 MHz
Δ <sub>PLLIN</sub>	SR	—	FMPLL reference clock duty cycle <sup>(3)</sup>	—	40	—	60 %
f <sub>PLLOUT</sub>	CC	P	FMPLL output clock frequency	—	16	—	120 MHz
f <sub>CPU</sub>	SR	—	System clock frequency	—	—	120 + 2% <sup>4</sup>	MHz
f <sub>FREE</sub>	CC	P	Free-running frequency	—	20	—	150 MHz
t <sub>LOCK</sub>	CC	P	FMPLL lock time	Stable oscillator (f <sub>PLLIN</sub> = 16 MHz)	—	40	100 μs
Δt <sub>LTJIT</sub>	CC	—	FMPLL long term jitter	f <sub>PLLIN</sub> = 40 MHz (resonator), f <sub>PLLCLK</sub> @ 120 MHz, 4000 cycles	—	—	6 (for < 1ppm) ns
I <sub>PLL</sub>	CC	C	FMPLL consumption	T <sub>A</sub> = 25 °C	—	—	3 mA

<sup>1</sup> V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.

<sup>2</sup> All values need to be confirmed during device validation.

<sup>3</sup> PLLIN clock retrieved directly from 4-40 MHz XOSC or 16 MIRC. Input characteristics are granted when oscillator is used in functional mode. When bypass mode is used, oscillator input clock should verify f<sub>PLLIN</sub> and Δ<sub>PLLIN</sub>.

<sup>4</sup> f<sub>CPU</sub> 120 + 2% MHz can be achieved at 125 °C.

## 4.15 Fast internal RC oscillator (16 MHz) electrical characteristics

The device provides a 16 MHz main internal RC oscillator. This is used as the default clock at the power-up of the device and can also be used as input to PLL.

**Table 39. Fast internal RC oscillator (16 MHz) electrical characteristics**

Symbol	C	Parameter	Conditions <sup>1</sup>	Value <sup>2</sup>			Unit	
				Min	Typ	Max		
f <sub>FIRC</sub>	CC	P	Fast internal RC oscillator high frequency	T <sub>A</sub> = 25 °C, trimmed	—	16	—	MHz
	SR	—		—	12	—	20	
I <sub>FIRCRUN</sub> <sup>3</sup>	CC	T	Fast internal RC oscillator high frequency current in running mode	T <sub>A</sub> = 25 °C, trimmed	—	—	200 μA	
I <sub>FIRCPWD</sub>	CC	D	Fast internal RC oscillator high frequency current in power down mode	T <sub>A</sub> = 25 °C	—	—	100 nA	
		D		T <sub>A</sub> = 55 °C	—	—	200 nA	
		D		T <sub>A</sub> = 125 °C	—	—	1 μA	

## Electrical Characteristics

**Table 39. Fast internal RC oscillator (16 MHz) electrical characteristics**

Symbol	C	Parameter	Conditions <sup>1</sup>	Value <sup>2</sup>			Unit
				Min	Typ	Max	
I <sub>FIRCSTOP</sub>	CC	Fast internal RC oscillator high frequency and system clock current in stop mode	T <sub>A</sub> = 25 °C	sysclk = off	—	500	—
				sysclk = 2 MHz	—	600	—
				sysclk = 4 MHz	—	700	—
				sysclk = 8 MHz	—	900	—
				sysclk = 16 MHz	—	1250	—
T <sub>FIRCSU</sub>	CC	Fast internal RC oscillator start-up time	T <sub>A</sub> = 55 °C	V <sub>DD</sub> = 5.0 V ± 10%	—	—	2.0
				V <sub>DD</sub> = 3.3 V ± 10%	—	—	5
			T <sub>A</sub> = 125 °C	V <sub>DD</sub> = 5.0 V ± 10%	—	—	2.0
				V <sub>DD</sub> = 3.3 V ± 10%	—	—	5
Δ <sub>FIRCPRE</sub>	CC	C	Fast internal RC oscillator precision after software trimming of f <sub>FIRC</sub>	T <sub>A</sub> = 25 °C	—1	—	+1
Δ <sub>FIRCTRIM</sub>	CC	C	Fast internal RC oscillator trimming step	T <sub>A</sub> = 25 °C	—	1.6	—
Δ <sub>FIRCVAR</sub>	CC	C	Fast internal RC oscillator variation over temperature and supply with respect to f <sub>FIRC</sub> at T <sub>A</sub> = 25 °C in high-frequency configuration	—	—5	—	+5

<sup>1</sup> V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = –40 to 125 °C, unless otherwise specified.

<sup>2</sup> All values need to be confirmed during device validation.

<sup>3</sup> This does not include consumption linked to clock tree toggling and peripherals consumption when RC oscillator is ON.

## 4.16 Slow internal RC oscillator (128 kHz) electrical characteristics

The device provides a 128 kHz low power internal RC oscillator. This can be used as the reference clock for the RTC module.

**Table 40. Slow internal RC oscillator (128 kHz) electrical characteristics**

Symbol	C	Parameter	Conditions <sup>1</sup>	Value <sup>2</sup>			Unit	
				Min	Typ	Max		
f <sub>SIRC</sub>	CC	P	Slow internal RC oscillator low frequency	T <sub>A</sub> = 25 °C, trimmed	—	128	—	kHz
	SR			untrimmed, across temperatures	84	—	205	
I <sub>SIRC</sub> <sup>3</sup>	CC	C	Slow internal RC oscillator low frequency current	T <sub>A</sub> = 25 °C, trimmed	—	—	5	μA
T <sub>SIRCSU</sub>	CC	P	Slow internal RC oscillator start-up time	T <sub>A</sub> = 25 °C, V <sub>DD</sub> = 5.0 V ± 10%	—	8	12	μs

**Table 40. Slow internal RC oscillator (128 kHz) electrical characteristics (continued)**

Symbol	C	Parameter	Conditions <sup>1</sup>	Value <sup>2</sup>			Unit
				Min	Typ	Max	
$\Delta_{SIRCPRE}$	CC	C	Slow internal RC oscillator precision after software trimming of $f_{SIRC}$	$T_A = 25^\circ C$	-2	—	+2
$\Delta_{SIRCTRIM}$	CC	C	Slow internal RC oscillator trimming step	—	—	2.7	—
$\Delta_{SIRCVAR}$	CC	C	Variation in $f_{SIRC}$ across temperature and fluctuation in supply voltage, post trimming	—	-10	—	+10

<sup>1</sup>  $V_{DD} = 3.3 V \pm 10\% / 5.0 V \pm 10\%$ ,  $T_A = -40$  to  $125^\circ C$ , unless otherwise specified.

<sup>2</sup> All values need to be confirmed during device validation.

<sup>3</sup> This does not include consumption linked to clock tree toggling and peripherals consumption when RC oscillator is ON.

## 4.17 ADC electrical characteristics

### 4.17.1 Introduction

The device provides two Successive Approximation Register (SAR) analog-to-digital converters (10-bit and 12-bit).

#### NOTE

Due to ADC limitations, the two ADCs cannot sample a shared channel at the same time i.e., their sampling windows cannot overlap if a shared channel is selected. If this is done, neither of the ADCs can guarantee their conversion accuracies.

## Electrical Characteristics

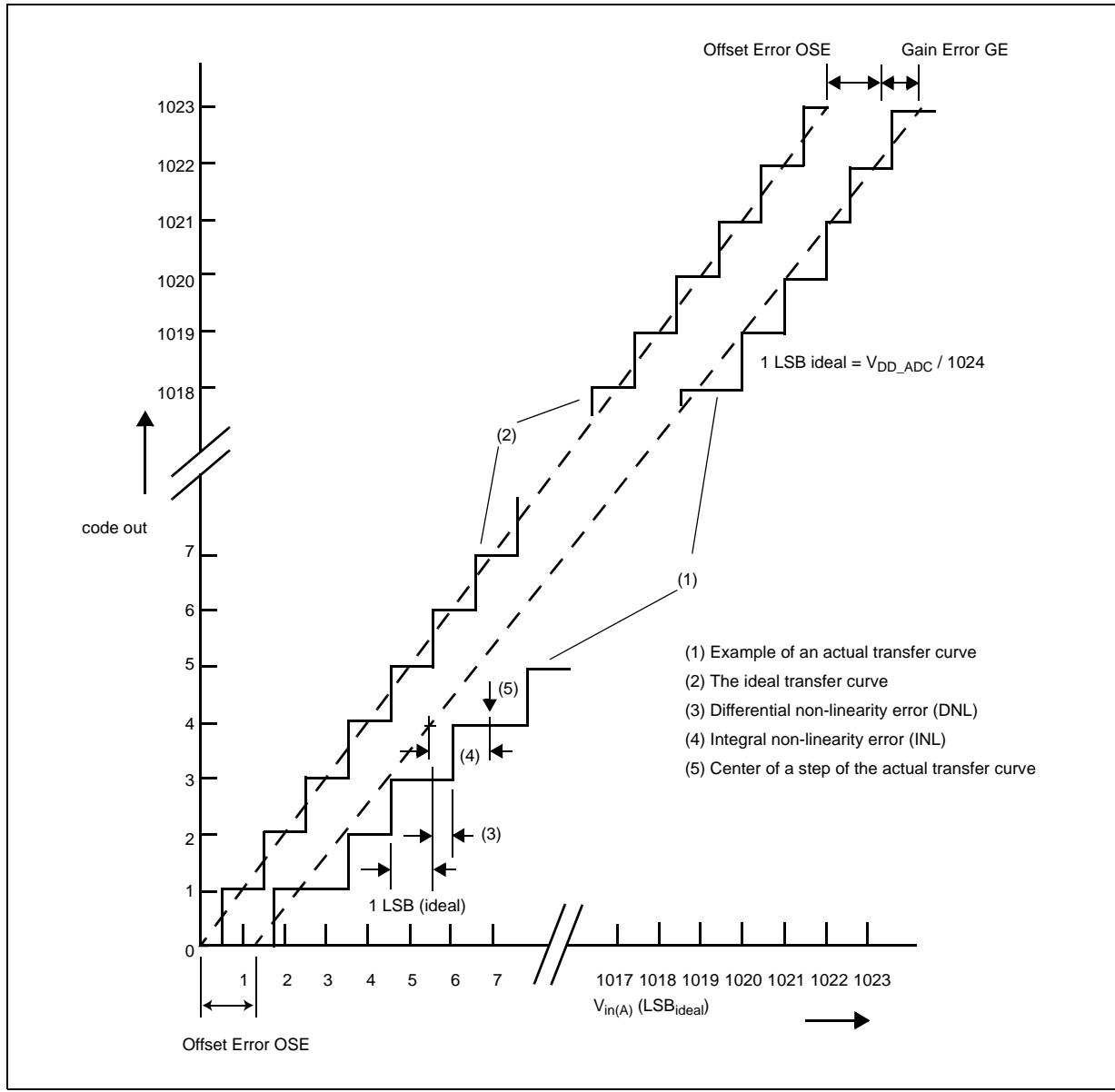


Figure 15. ADC\_0 characteristic and error definitions

### 4.17.1.1 Input impedance and ADC accuracy

To preserve the accuracy of the A/D converter, it is necessary that analog input pins have low AC impedance. Placing a capacitor with good high frequency characteristics at the input pin of the device, can be effective: the capacitor should be as large as possible, ideally infinite. This capacitor contributes to attenuating the noise present on the input pin; furthermore, it sources charge during the sampling phase, when the analog signal source is a high-impedance source. A real filter, can typically be obtained by using a series resistance with a capacitor on the input pin (simple RC Filter). The RC filtering may be limited according to the value of source impedance of the transducer or circuit supplying the analog signal to be measured. The filter at the input pins must be designed taking into account the dynamic characteristics of the input signal (bandwidth) and the equivalent input impedance of the ADC itself.

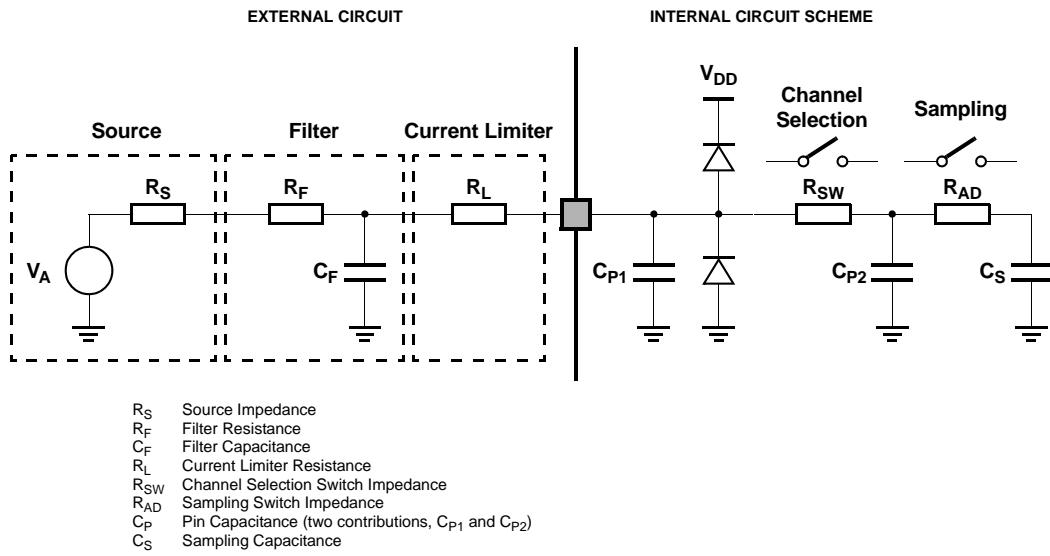
In fact a current sink contributor is represented by the charge sharing effects with the sampling capacitance: being  $CS$  and  $Cp_2$  substantially two switched capacitances, with a frequency equal to the conversion rate of the ADC, it can be seen as a resistive

path to ground. For instance, assuming a conversion rate of 1MHz, with  $CS + CP_2$  equal to 3pF, a resistance of 330K $\Omega$  is obtained ( $Reqiv = 1 / (fc * (CS + CP_2))$ ), where  $fc$  represents the conversion rate at the considered channel). To minimize the error induced by the voltage partitioning between this resistance (sampled voltage on  $CS + CP_2$ ) and the sum of  $R_S + R_F$ , the external circuit must be designed to respect the following relation

**Eqn. 4**

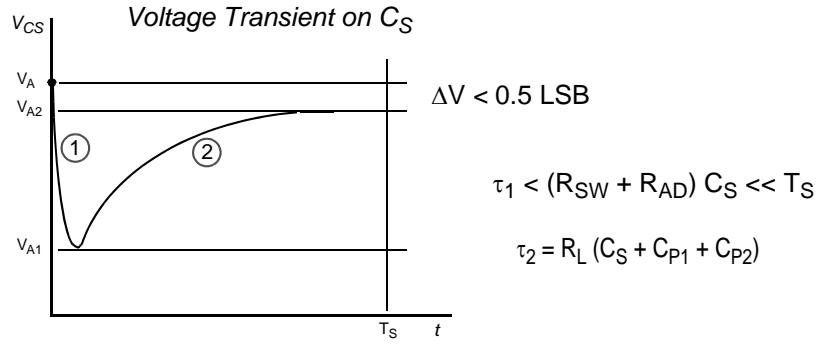
$$V_A \cdot \frac{R_S + R_F}{R_{EQ}} < \frac{1}{2} \text{ LSB}$$

The formula above provides a constraint for external network design, in particular on resistive path.



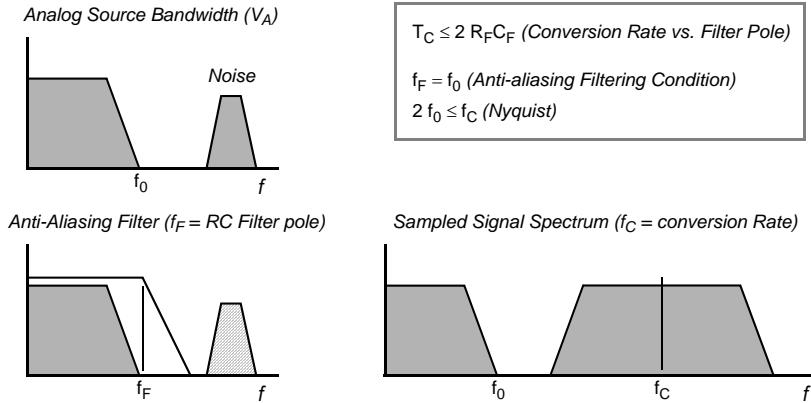
**Figure 16. Input equivalent circuit**

A second aspect involving the capacitance network shall be considered. Assuming the three capacitances  $C_F$ ,  $C_{P1}$  and  $C_{P2}$  initially charged at the source voltage  $V_A$  (refer to the equivalent circuit reported in Figure 15): when the sampling phase is started (A/D switch close), a charge sharing phenomena is installed.



**Figure 17. Transient behavior during sampling phase**





**Figure 18. Spectral representation of input signal**

Calling  $f_0$  the bandwidth of the source signal (and as a consequence the cut-off frequency of the anti-aliasing filter,  $f_F$ ), according to the Nyquist theorem the conversion rate  $f_C$  must be at least  $2f_0$ ; it means that the constant time of the filter is greater than or at least equal to twice the conversion period ( $T_C$ ). Again the conversion period  $T_C$  is longer than the sampling time  $T_S$ , which is just a portion of it, even when fixed channel continuous conversion mode is selected (fastest conversion rate at a specific channel): in conclusion it is evident that the time constant of the filter  $R_F C_F$  is definitively much higher than the sampling time  $T_S$ , so the charge level on  $C_S$  cannot be modified by the analog signal source during the time in which the sampling switch is closed.

The considerations above lead to impose new constraints on the external circuit, to reduce the accuracy error due to the voltage drop on  $C_S$ ; from the two charge balance equations above, it is simple to derive [Equation 11](#) between the ideal and real sampled voltage on  $C_S$ :

**Eqn. 11**

$$\frac{V_A}{V_{A2}} = \frac{C_{P1} + C_{P2} + C_F + C_S}{C_{P1} + C_{P2} + C_F}$$

From this formula, in the worst case (when  $V_A$  is maximum, that is for instance 5 V), assuming to accept a maximum error of half a count, a constraint is evident on  $C_F$  value:

**ADC\_0 (10-bit)**

**Eqn. 12**

$$C_F > 2048 \cdot C_S$$

**ADC\_1 (12-bit)**

**Eqn. 13**

$$C_F > 8192 \cdot C_S$$



**Table 42. ADC conversion characteristics (10-bit ADC\_0) (continued)**

Symbol	C	Parameter	Conditions <sup>1</sup>	Value			Unit	
				Min	Typ	Max		
R <sub>SW2</sub>	CC	D	Internal resistance of analog source	—	—	2	kΩ	
R <sub>AD</sub>	CC	D	Internal resistance of analog source	—	—	2	kΩ	
I <sub>INJ</sub>	SR	—	Input current Injection  Current injection on one ADC_0 input, different from the converted one	V <sub>DD</sub> = 3.3 V ± 10%	-5	—	mA	
				V <sub>DD</sub> = 5.0 V ± 10%	-5	—	5	
INL	CC	T	Absolute value for integral non-linearity	No overload	—	0.5	1.5	LSB
DNL	CC	T	Absolute differential non-linearity	No overload	—	0.5	1.0	LSB
OFS	CC	T	Absolute offset error	—	—	0.5	—	LSB
GNE	CC	T	Absolute gain error	—	—	0.6	—	LSB
TUEP	CC	P	Total unadjusted error <sup>7</sup> for precise channels, input only pins	Without current injection	-2	0.6	2	LSB
		T		With current injection	-3		3	
TUEX	CC	T	Total unadjusted error <sup>(7)</sup> for extended channel	Without current injection	-3	1	3	LSB
		T		With current injection	-4		4	

<sup>1</sup> V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = -40 to 125 °C, unless otherwise specified.

<sup>2</sup> Analog and digital V<sub>SS\_HV</sub> must be common (to be tied together externally).

<sup>3</sup> V<sub>AIX</sub> may exceed V<sub>SS\_ADC0</sub> and V<sub>DD\_ADC0</sub> limits, remaining on absolute maximum ratings, but the results of the conversion will be clamped respectively to 0x000 or 0x3FF.

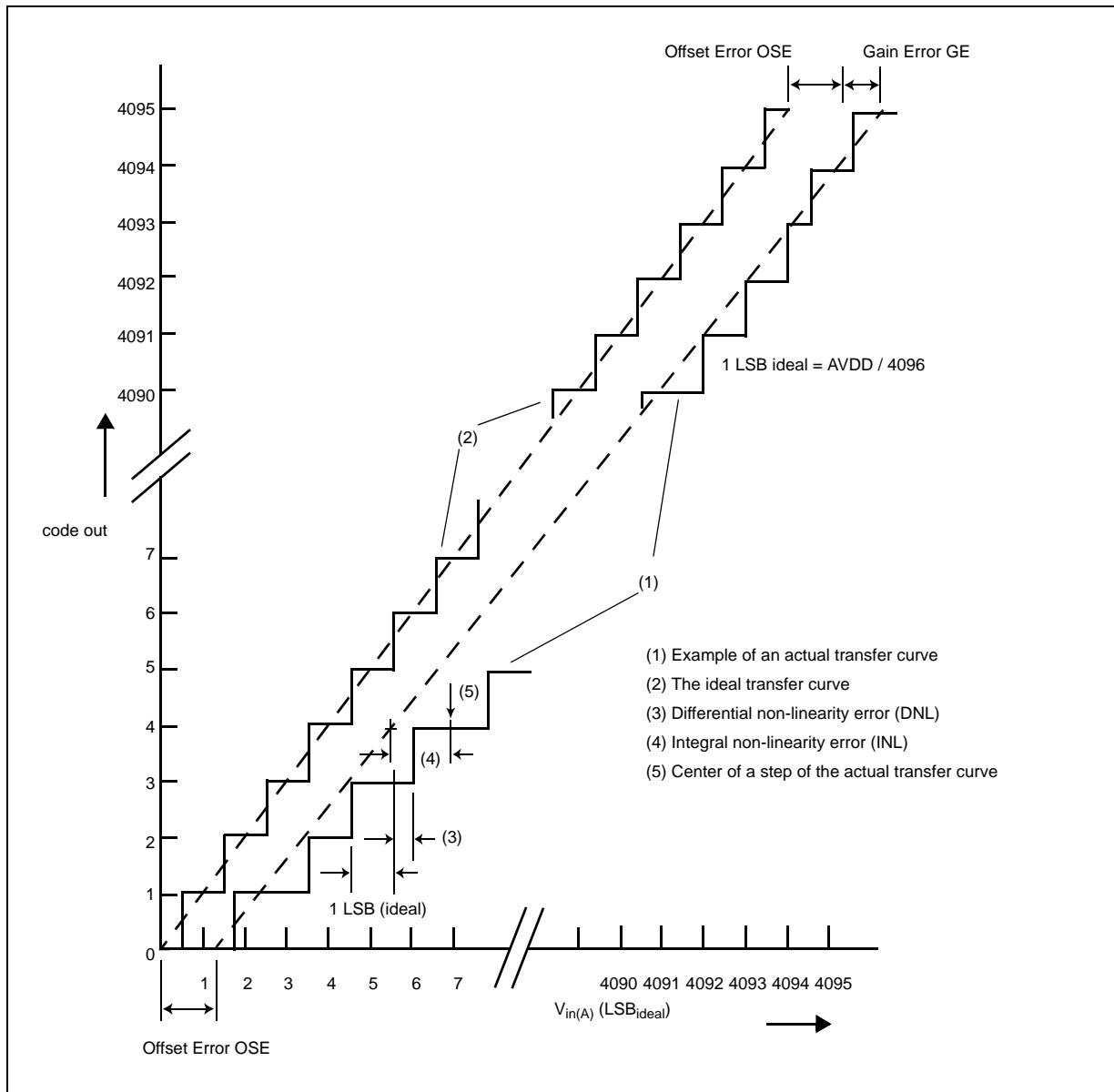
<sup>4</sup> During the sample time the input capacitance C<sub>S</sub> can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within t<sub>ADC0\_S</sub>. After the end of the sample time t<sub>ADC0\_S</sub>, changes of the analog input voltage have no effect on the conversion result. Values for the sample clock t<sub>ADC0\_S</sub> depend on programming.

<sup>5</sup> This parameter does not include the sample time t<sub>ADC0\_S</sub>, but only the time for determining the digital result and the time to load the result's register with the conversion result

<sup>6</sup> Refer to ADC conversion table for detailed calculations.

<sup>7</sup> Total Unadjusted Error: The maximum error that occurs without adjusting Offset and Gain errors. This error is a combination of Offset, Gain and Integral Linearity errors.

## Electrical Characteristics



**Figure 19. ADC\_1 characteristic and error definitions**

**Table 43. Conversion characteristics (12-bit ADC\_1)**

Symbol	Parameter	Conditions <sup>1</sup>	Value			Unit
			Min	Typ	Max	
V <sub>SS_ADC1</sub>	SR	Voltage on V <sub>SS_HV_ADC1</sub> (ADC_1 reference) pin with respect to ground (V <sub>SS_HV</sub> ) <sup>2</sup>	—	-0.1		0.1

Table 43. Conversion characteristics (12-bit ADC\_1) (continued)

Symbol	Parameter	Conditions <sup>1</sup>	Value			Unit	
			Min	Typ	Max		
V <sub>DD_ADC1</sub> <sup>3</sup>	SR	Voltage on VDD_HV_ADC1 pin (ADC_1 reference) with respect to ground (V <sub>SS_HV</sub> )	—	V <sub>DD_HV_A</sub> - 0.1		V <sub>DD_HV_A</sub> + 0.1	V
V <sub>AINx</sub> <sup>3,4</sup>	SR	Analog input voltage <sup>5</sup>	—	V <sub>SS_ADC1</sub> - 0.1		V <sub>DD_ADC1</sub> + 0.1	V
f <sub>ADC1</sub>	SR	ADC_1 analog frequency	—	8 + 2%		32 + 2%	MHz
t <sub>ADC1_PU</sub>	SR	ADC_1 power up delay	—	1.5			μs
t <sub>ADC1_S</sub>	CC	Sample time <sup>6</sup> VDD=5.0 V	—	440			ns
		Sample time <sup>(6)</sup> VDD=3.3 V	—	530			
t <sub>ADC1_C</sub>	CC	Conversion time <sup>7, 8</sup> VDD=5.0 V	f <sub>ADC1</sub> = 32 MHz	2			μs
		Conversion time <sup>(7), (6)</sup> VDD =5.0 V	f <sub>ADC 1</sub> = 30 MHz	2.1			
		Conversion time <sup>(7), (6)</sup> VDD=3.3 V	f <sub>ADC 1</sub> = 20 MHz	3			
		Conversion time <sup>(7), (6)</sup> VDD =3.3 V	f <sub>ADC1</sub> = 15 MHz	3.01			
C <sub>S</sub>	CC	ADC_1 input sampling capacitance	—	5			pF
C <sub>P1</sub>	CC	ADC_1 input pin capacitance 1	—	3			pF
C <sub>P2</sub>	CC	ADC_1 input pin capacitance 2	—	1			pF
C <sub>P3</sub>	CC	ADC_1 input pin capacitance 3	—	1.5			pF
R <sub>SW1</sub>	CC	Internal resistance of analog source	—			1	kΩ
R <sub>SW2</sub>	CC	Internal resistance of analog source	—			2	kΩ
R <sub>AD</sub>	CC	Internal resistance of analog source	—			0.3	kΩ

## Electrical Characteristics

**Table 43. Conversion characteristics (12-bit ADC\_1) (continued)**

Symbol		Parameter	Conditions <sup>1</sup>		Value			Unit
					Min	Typ	Max	
$I_{INJ}$	SR	Input current Injection	Current injection on one ADC_1 input, different from the converted one	$V_{DD} = 3.3$ $V \pm 10\%$	-5	—	5	mA
				$V_{DD} = 5.0$ $V \pm 10\%$	-5	—	5	
INLP	CC	Absolute Integral non-linearity-Precis e channels	No overload			1	3	LSB
INLS	CC	Absolute Integral non-linearity- Standard channels	No overload			1.5	5	LSB
DNL	CC	Absolute Differential non-linearity	No overload			0.5	1	LSB
OFS	CC	Absolute Offset error	—			2		LSB
GNE	CC	Absolute Gain error	—			2		LSB
TUEP <sup>9</sup>	CC	Total Unadjusted Error for precise channels, input only pins						
			Without current injection		-6		6	LSB
			With current injection		-8		8	LSB
TUES <sup>(9)</sup>	CC	Total Unadjusted Error for standard channel						
			Without current injection		-10		10	LSB
			With current injection		-12		12	LSB

<sup>1</sup>  $V_{DD} = 3.3 \text{ V} \pm 10\% / 5.0 \text{ V} \pm 10\%$ ,  $T_A = -40 \text{ to } 125^\circ\text{C}$ , unless otherwise specified.

<sup>2</sup> Analog and digital  $V_{SS\_HV}$  **must** be common (to be tied together externally).

<sup>3</sup> PA3, PA7, PA10, PA11 and PE12 ADC\_1 channels are coming from  $V_{DD\_HV\_B}$  domain hence  $VDD\_HV\_ADC1$  should be within  $\pm 100 \text{ mV}$  of  $VDD\_HV\_B$  when these channels are used for ADC\_1.

<sup>4</sup>  $VDD\_HV\_ADC1$  can operate at 5V condition while  $V_{DD\_HV\_B}$  can operate at 3.3V provided that ADC\_1 channels coming from  $V_{DD\_HV\_B}$  domain are limited in max swing as  $V_{DD\_HV\_B}$ .

<sup>5</sup>  $V_{AINx}$  may exceed  $V_{SS\_ADC1}$  and  $V_{DD\_ADC1}$  limits, remaining on absolute maximum ratings, but the results of the conversion will be clamped respectively to 0x000 or 0xFFFF.

<sup>6</sup> During the sample time the input capacitance  $C_S$  can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within  $t_{ADC1\_S}$ . After the end of the sample time  $t_{ADC1\_S}$ , changes of the analog input voltage have no effect on the conversion result. Values for the sample clock  $t_{ADC1\_S}$  depend on programming.

<sup>7</sup> Conversion time = Bit evaluation time + Sampling time + 1 Clock cycle delay.

<sup>8</sup> Refer to ADC conversion table for detailed calculations.

- <sup>9</sup> Total Unadjusted Error: The maximum error that occurs without adjusting Offset and Gain errors. This error is a combination of Offset, Gain and Integral Linearity errors.

## 4.18 Fast Ethernet Controller

MII signals use CMOS signal levels compatible with devices operating at 3.3 V. Signals are not TTL compatible. They follow the CMOS electrical characteristics.

### 4.18.1 MII Receive Signal Timing (RXD[3:0], RX\_DV, RX\_ER, and RX\_CLK)

The receiver functions correctly up to a RX\_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. In addition, the system clock frequency must exceed four times the RX\_CLK frequency in 2:1 mode and two times the RX\_CLK frequency in 1:1 mode.

Table 44. MII Receive Signal Timing

Spec	Characteristic	Min	Max	Unit
M1	RXD[3:0], RX_DV, RX_ER to RX_CLK setup	5	—	ns
M2	RX_CLK to RXD[3:0], RX_DV, RX_ER hold	5	—	ns
M3	RX_CLK pulse width high	35%	65%	RX_CLK period
M4	RX_CLK pulse width low	35%	65%	RX_CLK period

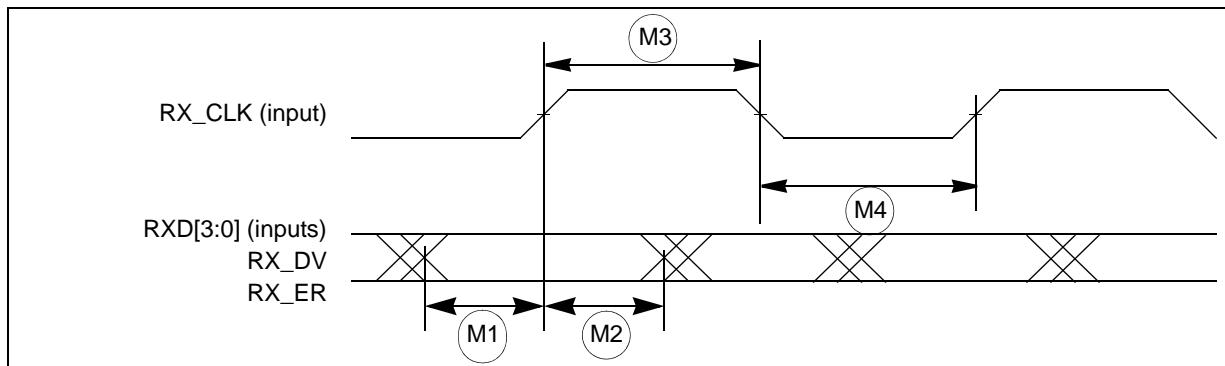


Figure 20. MII receive signal timing diagram

### 4.18.2 MII Transmit Signal Timing (TXD[3:0], TX\_EN, TX\_ER, TX\_CLK)

The transmitter functions correctly up to a TX\_CLK maximum frequency of 25 MHz +1%. There is no minimum frequency requirement. In addition, the system clock frequency must exceed four times the TX\_CLK frequency in 2:1 mode and two times the TX\_CLK frequency in 1:1 mode.

The transmit outputs (TXD[3:0], TX\_EN, TX\_ER) can be programmed to transition from either the rising or falling edge of TX\_CLK, and the timing is the same in either case. This option allows the use of non-compliant MII PHYs.

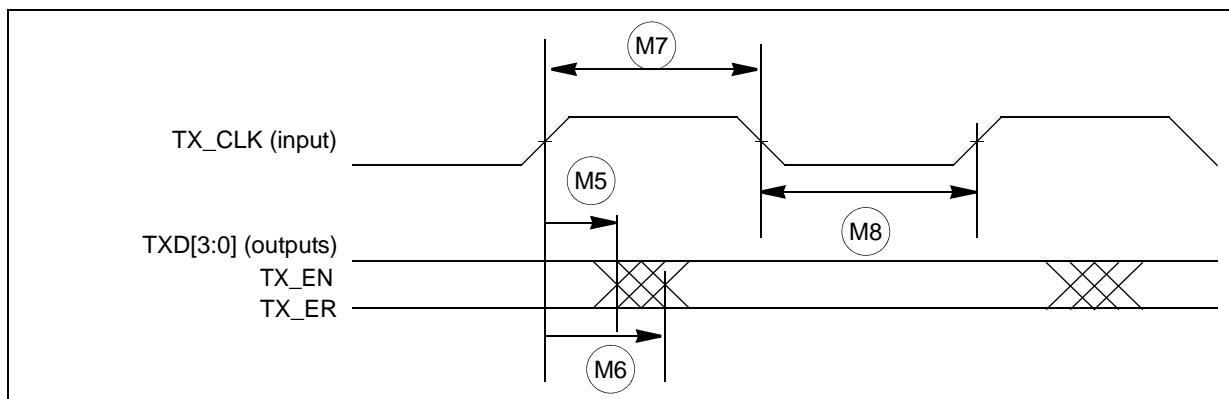
Refer to the Fast Ethernet Controller (FEC) chapter of the MPC5646C Reference Manual for details of this option and how to enable it.

## Electrical Characteristics

**Table 45. MII transmit signal timing<sup>1</sup>**

Spec	Characteristic	Min	Max	Unit
M5	TX_CLK to TXD[3:0], TX_EN, TX_ER invalid	5	—	ns
M6	TX_CLK to TXD[3:0], TX_EN, TX_ER valid	—	25	ns
M7	TX_CLK pulse width high	35%	65%	TX_CLK period
M8	TX_CLK pulse width low	35%	65%	TX_CLK period

<sup>1</sup> Output pads configured with SRE = 0b11.



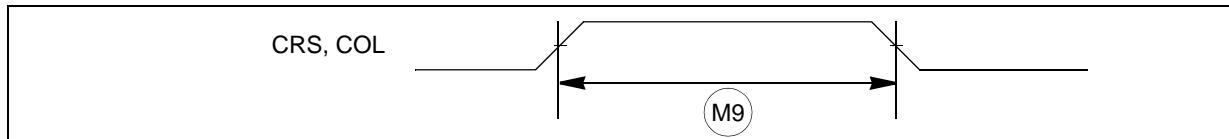
**Figure 21. MII transmit signal timing diagram**

## 4.18.3 MII Async Inputs Signal Timing (CRS and COL)

**Table 46. MII Async Inputs Signal Timing<sup>1</sup>**

Spec	Characteristic	Min	Max	Unit
M9	CRS, COL minimum pulse width	1.5	—	TX_CLK period

<sup>1</sup> Output pads configured with SRE = 0b11.



**Figure 22. MII async inputs timing diagram**

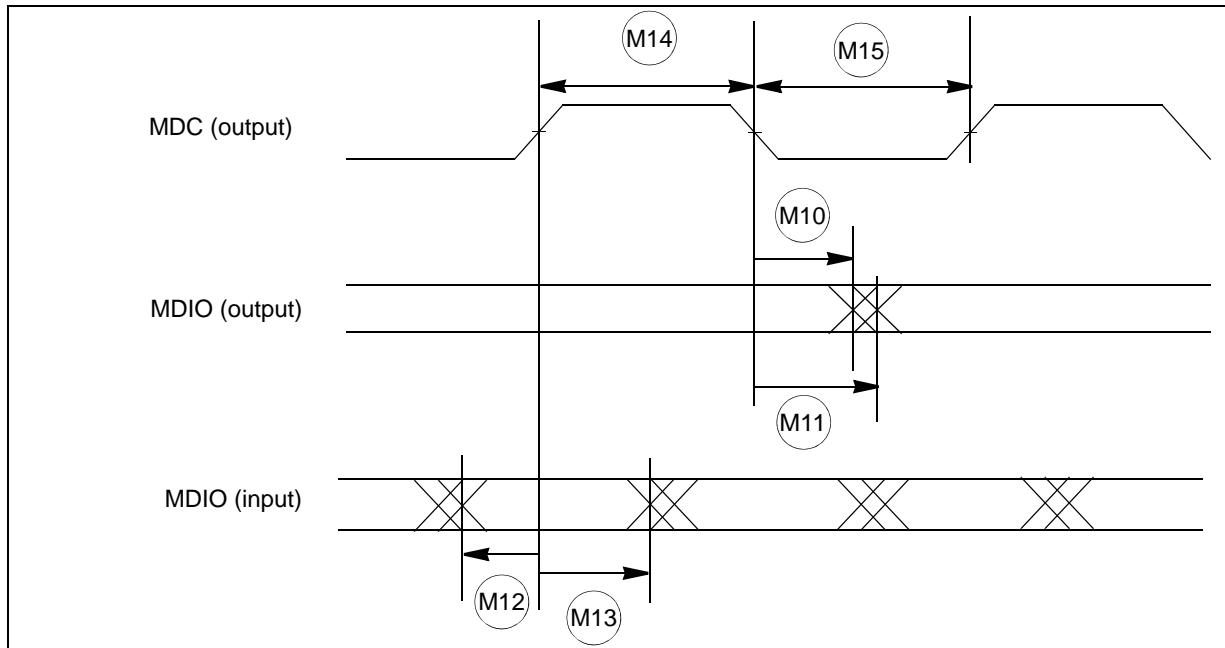
## 4.18.4 MII Serial Management Channel Timing (MDIO and MDC)

The FEC functions correctly with a maximum MDC frequency of 2.5 MHz.

**Table 47. MII serial management channel timing<sup>1</sup>**

Spec	Characteristic	Min	Max	Unit
M10	MDC falling edge to MDIO output invalid (minimum propagation delay)	0	—	ns
M11	MDC falling edge to MDIO output valid (max prop delay)	—	25	ns
M12	MDIO (input) to MDC rising edge setup	28	—	ns
M13	MDIO (input) to MDC rising edge hold	0	—	ns
M14	MDC pulse width high	40%	60%	MDC period
M15	MDC pulse width low	40%	60%	MDC period

<sup>1</sup> Output pads configured with SRE = 0b11.

**Figure 23. MII serial management channel timing diagram**

## 4.19 On-chip peripherals

### 4.19.1 Current consumption

Table 48. On-chip peripherals current consumption<sup>1</sup>

Symbol	C	Parameter	Conditions	Value <sup>2</sup>		Unit	
				Typ	Value <sup>2</sup>		
$I_{DD\_HV\_A(CAN)}$	CC	D	CAN (FlexCAN) supply current on $V_{DD\_HV\_A}$	500 Kbps	Total (static + dynamic) consumption: FlexCAN in loop-back mode XTAL@8 MHz used as CAN engine clock source Message sending period is 580 $\mu$ s	$7.652 \times f_{periph} + 84.73$	
				125 Kbps		$8.0743 \times f_{periph} + 26.757$	
$I_{DD\_HV\_A(eMOS)}$	CC	D	eMOS supply current on $V_{DD\_HV\_A}$	Static consumption: eMOS channel OFF Global prescaler enabled		$28.7 \times f_{periph}$	
				Dynamic consumption: It does not change varying the frequency (0.003 mA)		3	
$I_{DD\_HV\_A(SCI)}$	CC	D	SCI (LINFlex) supply current on $V_{DD\_HV\_A}$	Total (static + dynamic) consumption: LIN mode Baudrate: 20 Kbps		$4.7804 \times f_{periph} + 30.946$	
$I_{DD\_HV\_A(SPI)}$	CC	D	SPI (DSPI) supply current on $V_{DD\_HV\_A}$	Ballast static consumption (only clocked)		1	
				Ballast dynamic consumption (continuous communication): Baudrate: 2 Mbit Transmission every 8 $\mu$ s Frame: 16 bits		$16.3 \times f_{periph}$	
$I_{DD\_HV\_A(ADC)}$	CC	D	ADC supply current on $V_{DD\_HV\_A}$	$V_{DD} = 5.5$ V	Ballast static consumption (no conversion)	$0.0409 \times f_{periph}$	mA
				$V_{DD} = 5.5$ V	Ballast dynamic consumption (continuous conversion)	$0.0049 \times f_{periph}$	
$I_{DD\_HV\_ADC0}$	CC	D	ADC_0 supply current on $V_{DD\_HV\_ADC0}$	$V_{DD} = 5.5$ V	Analog static consumption (no conversion)	—	$\mu$ A
					Analog dynamic consumption (continuous conversion)	—	

**Table 48. On-chip peripherals current consumption<sup>1</sup>**

Symbol	C	Parameter	Conditions		Value <sup>2</sup>	Unit	
					Typ		
IDD_HV_ADC1	CC	D	ADC_1 supply current on V <sub>DD_HV_ADC1</sub>	V <sub>DD</sub> = 5.5 V	Analog static consumption (no conversion)	300 × f <sub>periph</sub>	µA
				V <sub>DD</sub> = 5.5 V	Analog dynamic consumption (continuous conversion)	6	
I <sub>DD_HV(FLASH)</sub>	CC	D	CFlash + DFlash supply current on V <sub>DD_HV_ADC</sub>	V <sub>DD</sub> = 5.5 V	—	13.25	mA
I <sub>DD_HV(PLL)</sub>	CC	D	PLL supply current on V <sub>DD_HV</sub>	V <sub>DD</sub> = 5.5 V	—	0.0031 × f <sub>periph</sub>	

<sup>1</sup> Operating conditions: T<sub>A</sub> = 25 °C, f<sub>periph</sub> = 8 MHz to 120 MHz.

<sup>2</sup> f<sub>periph</sub> is in absolute value.

## 4.19.2 DSPI characteristics

Table 49. DSPI timing

Spec	Characteristic	Symbol			Unit
			Min	Max	
1	DSPI Cycle Time	$t_{SCK}$	Refer note <sup>1</sup>	—	ns
—	Internal delay between pad associated to SCK and pad associated to CSn in master mode for CSn1->0	$\Delta t_{CSC}$	—	115	ns
—	Internal delay between pad associated to SCK and pad associated to CSn in master mode for CSn1->1	$\Delta t_{ASC}$	15	—	ns
2	CS to SCK Delay <sup>2</sup>	$t_{CSC}$	7	—	ns
3	After SCK Delay <sup>3</sup>	$t_{ASC}$	15	—	ns
4	SCK Duty Cycle	$t_{SDC}$	$0.4 \times t_{SCK}$	$0.6 \times t_{SCK}$	ns
—	Slave Setup Time (SS active to SCK setup time)	$t_{SUSS}$	5	—	ns
—	Slave Hold Time (SS active to SCK hold time)	$t_{HSS}$	10	—	ns
5	Slave Access Time (SS active to SOUT valid) <sup>4</sup>	$t_A$	—	42	ns
6	Slave SOUT Disable Time (SS inactive to SOUT High-Z or invalid)	$t_{DIS}$	—	25	ns
7	CSx to $\overline{PCSS}$ time	$t_{PCSC}$	0	—	ns
8	$\overline{PCSS}$ to PCSx time	$t_{PASC}$	0	—	ns

Table 49. DSPI timing (continued)

Spec	Characteristic	Symbol			Unit
			Min	Max	
9	Data Setup Time for Inputs Master (MTFE = 0) Slave Master (MTFE = 1, CPHA = 0) <sup>5</sup> Master (MTFE = 1, CPHA = 1)	t <sub>SUI</sub>	36	—	ns
			5	—	ns
			36	—	ns
			36	—	ns
10	Data Hold Time for Inputs Master (MTFE = 0) Slave Master (MTFE = 1, CPHA = 0) <sup>5</sup> Master (MTFE = 1, CPHA = 1)	t <sub>HI</sub>	0	—	ns
			4	—	ns
			0	—	ns
			0	—	ns
11	Data Valid (after SCK edge) Master (MTFE = 0) Slave Master (MTFE = 1, CPHA = 0) Master (MTFE = 1, CPHA = 1)	t <sub>SUO</sub>	—	12	ns
			—	37	ns
			—	12	ns
			—	12	ns
12	Data Hold Time for Outputs Master (MTFE = 0) Slave Master (MTFE = 1, CPHA = 0) Master (MTFE = 1, CPHA = 1)	t <sub>HO</sub>	0 <sup>6</sup>	—	ns
			9.5	—	ns
			0 <sup>7</sup>	—	ns
			0 <sup>8</sup>	—	ns

<sup>1</sup> This value of this parameter is dependent upon the external device delays and the other parameters mentioned in this table.

<sup>2</sup> The maximum value is programmable in DSPI\_CTARn[PSSCK] and DSPI\_CTARn[CSSCK]. For MPC5646C, the spec value of t<sub>CSC</sub> will be attained only if T<sub>DSPI</sub> x PSSCK x CSSCK > Δt<sub>CSC</sub>.

<sup>3</sup> The maximum value is programmable in DSPI\_CTARn[PASC] and DSPI\_CTARn[ASC]. For MPC5646C, the spec value of t<sub>ASC</sub> will be attained only if T<sub>DSPI</sub> x PASC x ASC > Δt<sub>ASC</sub>.

<sup>4</sup> The parameter value is obtained from t<sub>SUSS</sub> and t<sub>SUO</sub> for slave.

<sup>5</sup> This number is calculated assuming the SMPL\_PT bitfield in DSPI\_MCR is set to 0b00.

<sup>6</sup> For DSPI1, the Data Hold Time for Outputs in Master (MTFE = 0) is -2 ns.

<sup>7</sup> For DSPI1, the Data Hold Time for Outputs in Master (MTFE = 1, CPHA = 0) is -2 n.

<sup>8</sup> For DSPI1, the Data Hold Time for Outputs in Master (MTFE = 1, CPHA = 1) is -2 ns.

## Electrical Characteristics

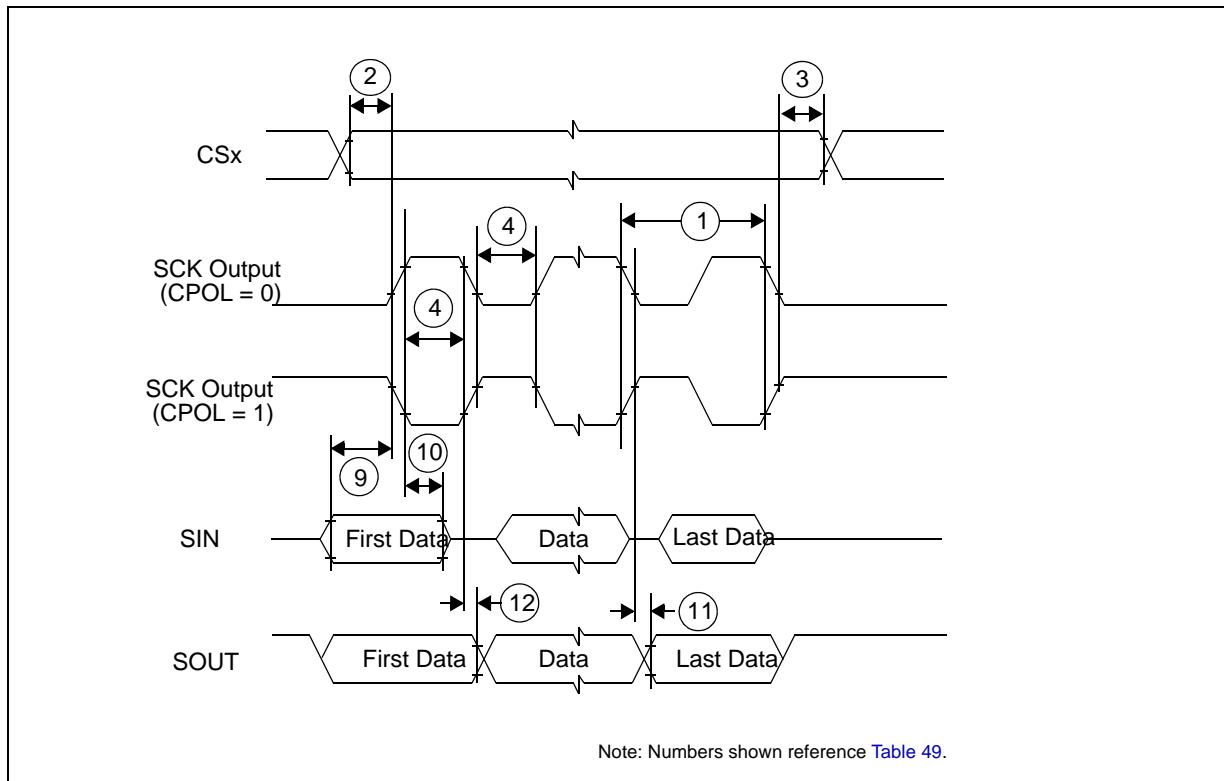


Figure 24. DSPI classic SPI timing—master, CPHA = 0

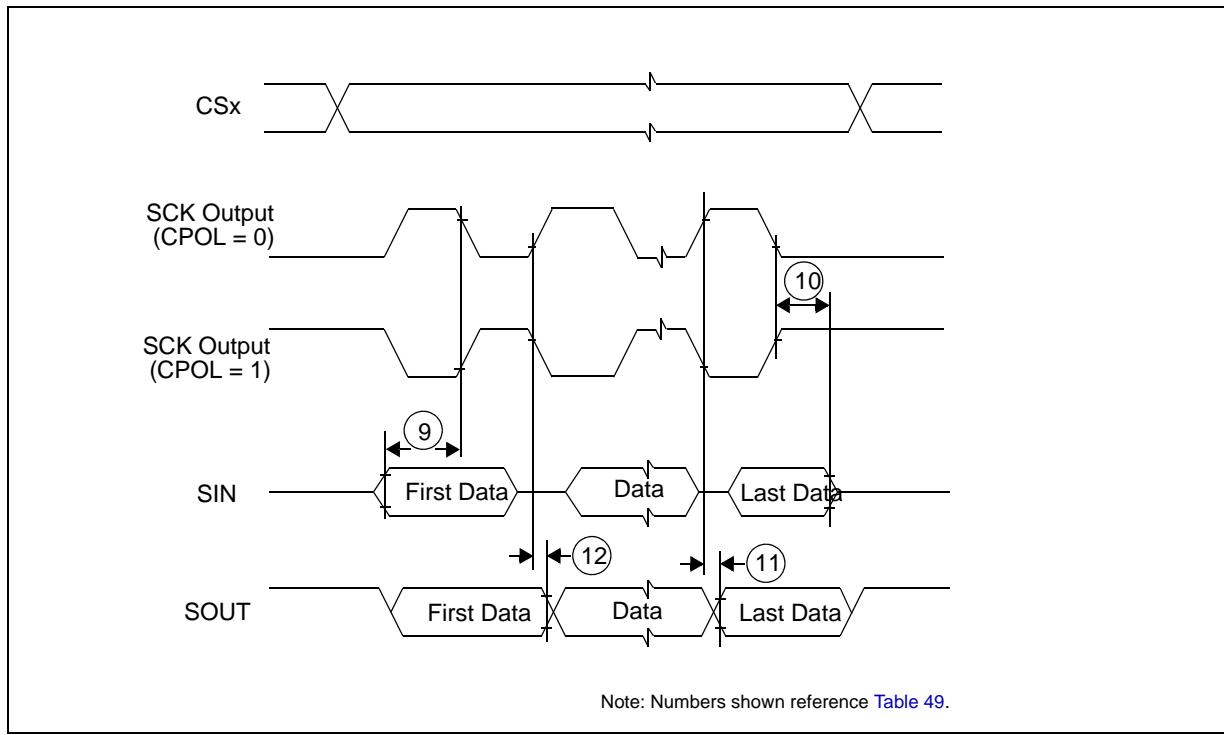
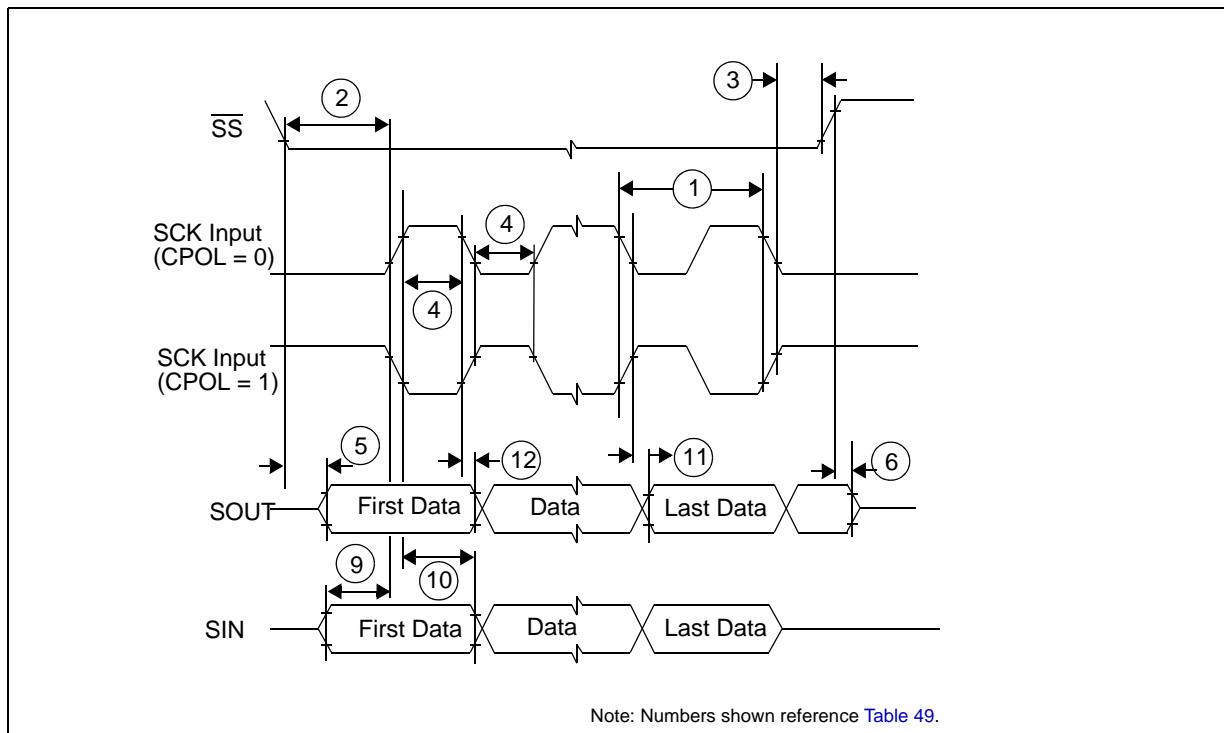
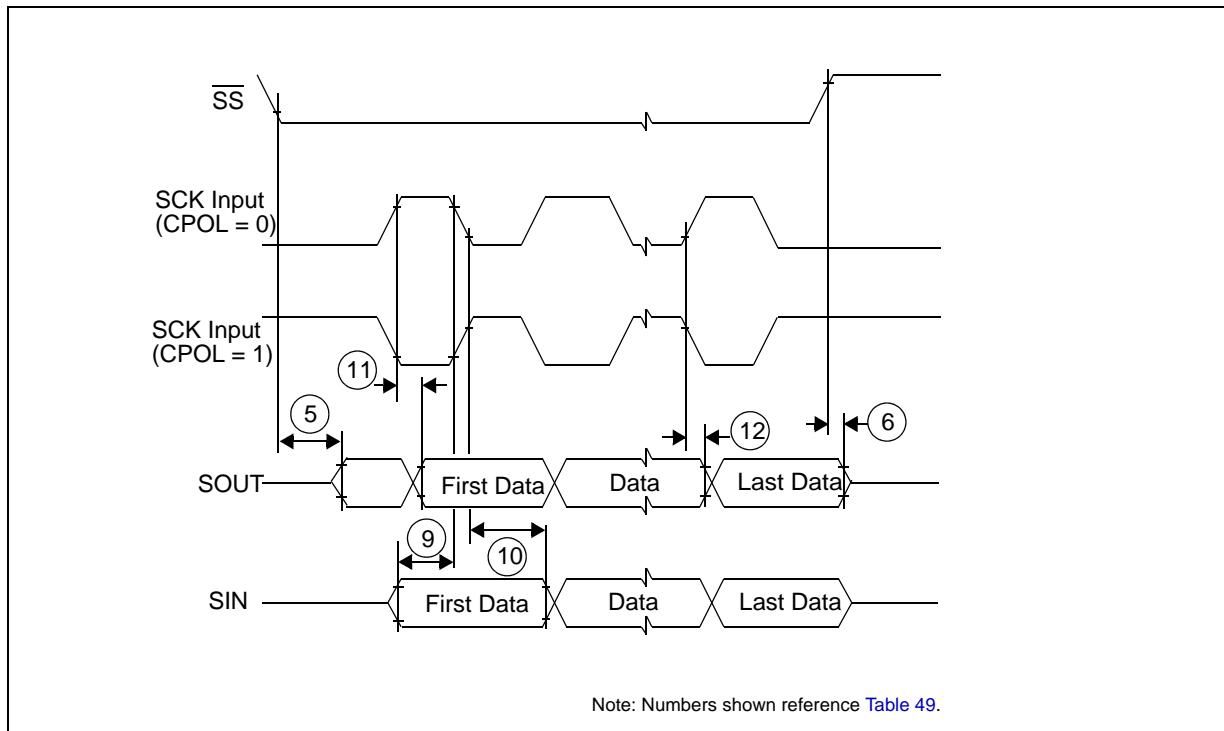


Figure 25. DSPI classic SPI timing—master, CPHA = 1



**Figure 26. DSPI classic SPI timing—slave, CPHA = 0**

## Electrical Characteristics



**Figure 27. DSPI classic SPI timing—slave, CPHA = 1**

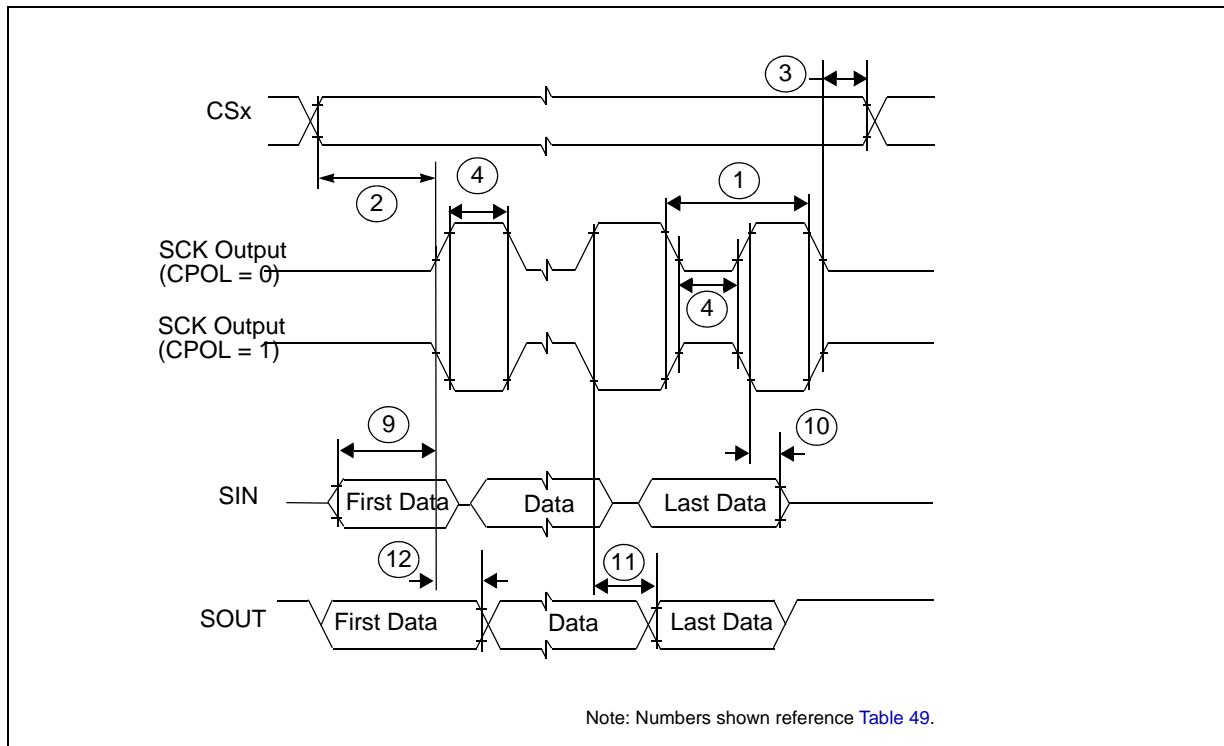


Figure 28. DSPI modified transfer format timing—master, CPHA = 0

## Electrical Characteristics

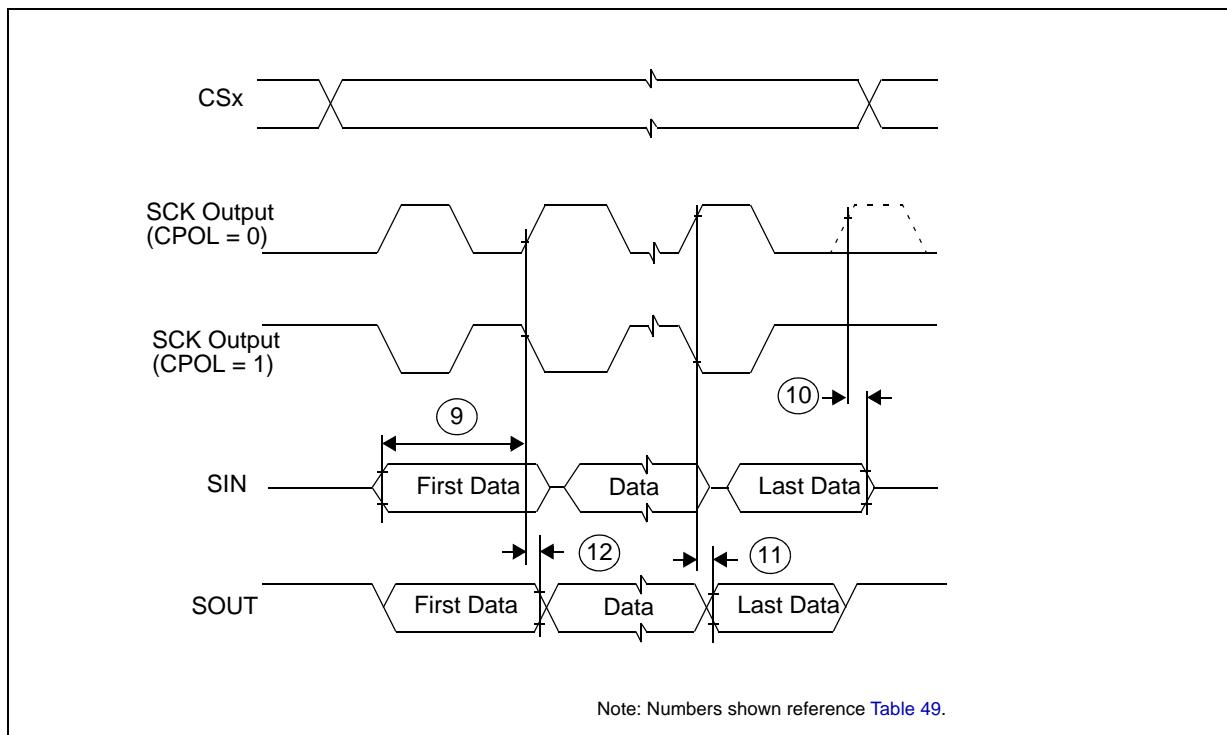


Figure 29. DSPI modified transfer format timing—master, CPHA = 1

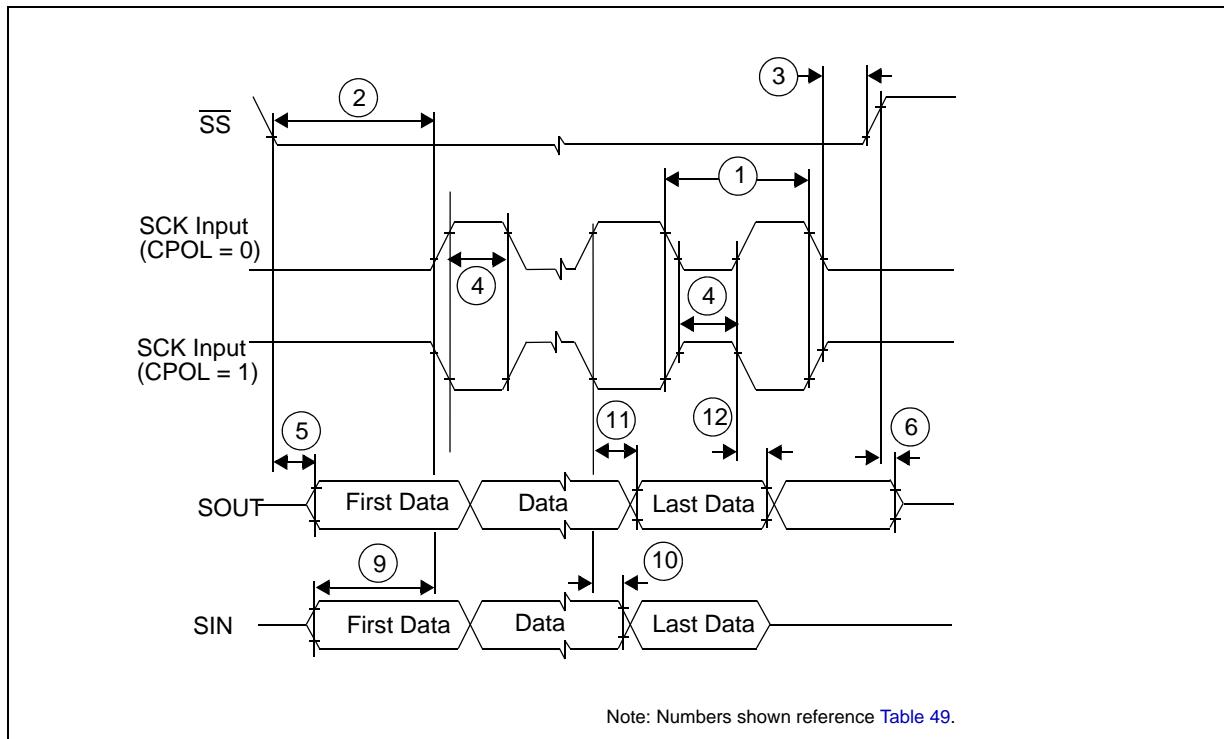


Figure 30. DSPI modified transfer format timing—slave, CPHA = 0

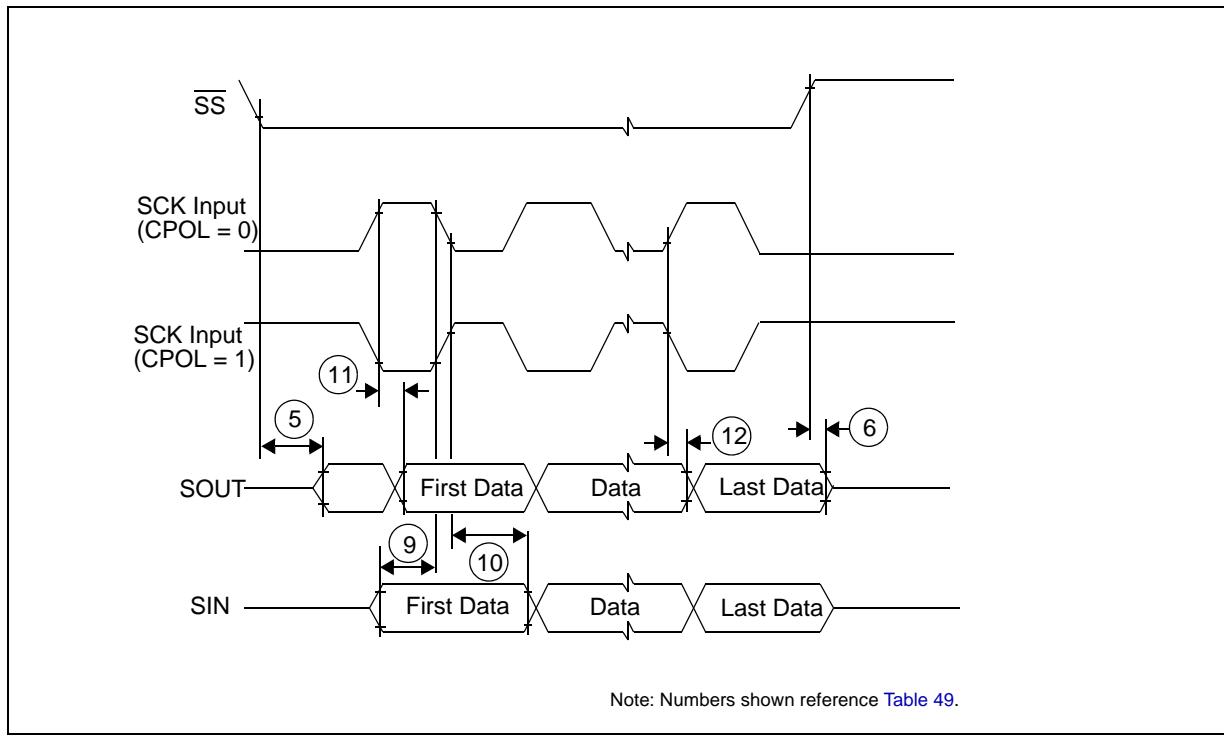


Figure 31. DSPI modified transfer format timing—slave, CPHA = 1

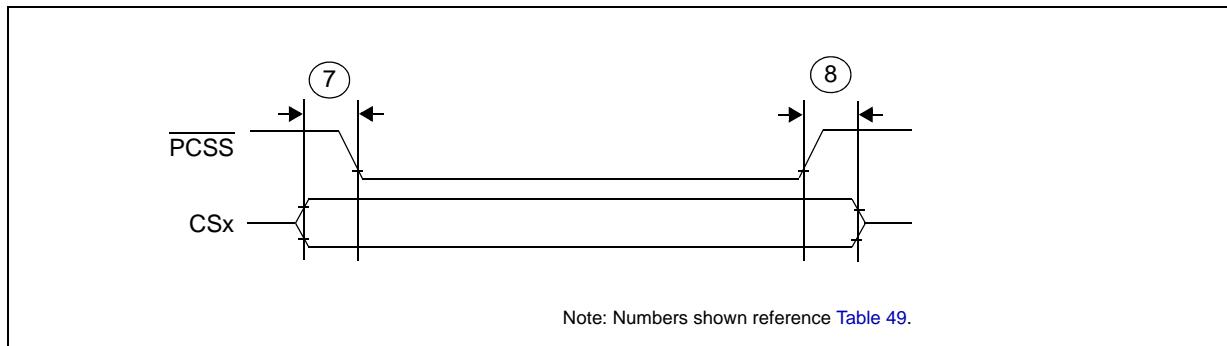


Figure 32. DSPI PCS strobe (PCSS) timing

### 4.19.3 Nexus characteristics

Table 50. Nexus debug port timing<sup>1</sup>

Spec	Characteristic	Symbol	Min	Max	Unit
1	MCKO Cycle Time <sup>2</sup>	$t_{MCYC}$	16.3	—	ns
2	MCKO Duty Cycle	$t_{MDC}$	40	60	%
3	MCKO Low to MDO, MSEO, EVTO Data Valid <sup>3</sup>	$t_{MDOV}$	-0.1	0.25	$t_{MCYC}$
4	$\overline{EVTO}$ Pulse Width	$t_{EVTOPW}$	4.0	—	$t_{TCYC}$
5	$\overline{EVTO}$ Pulse Width	$t_{EVTOPW}$	1	—	$t_{MCYC}$
6	TCK Cycle Time <sup>4</sup>	$t_{TCYC}$	40	—	ns
7	TCK Duty Cycle	$t_{TDC}$	40	60	%
8	TDI, TMS Data Setup Time	$t_{NTDIS}, t_{NTMSS}$	8	—	ns
9	TDI, TMS Data Hold Time	$t_{NTDIH}, t_{NTMSH}$	5	—	ns
10	TCK Low to TDO Data Valid	$t_{JOV}$	0	25	ns

<sup>1</sup> JTAG specifications in this table apply when used for debug functionality. All Nexus timing relative to MCKO is measured from 50% of MCKO and 50% of the respective signal. Nexus timing specified at  $V_{DDE} = 4.0 - 5.5$  V,  $T_A = T_L$  to  $T_H$ , and  $C_L = 30$  pF with SRC = 0b11.

<sup>2</sup> MCKO can run up to 1/2 of full system frequency. It can also run at system frequency when it is <60 MHz.

<sup>3</sup> MDO, MSEO, and EVTO data is held valid until next MCKO low cycle.

<sup>4</sup> The system clock frequency needs to be three times faster than the TCK frequency.

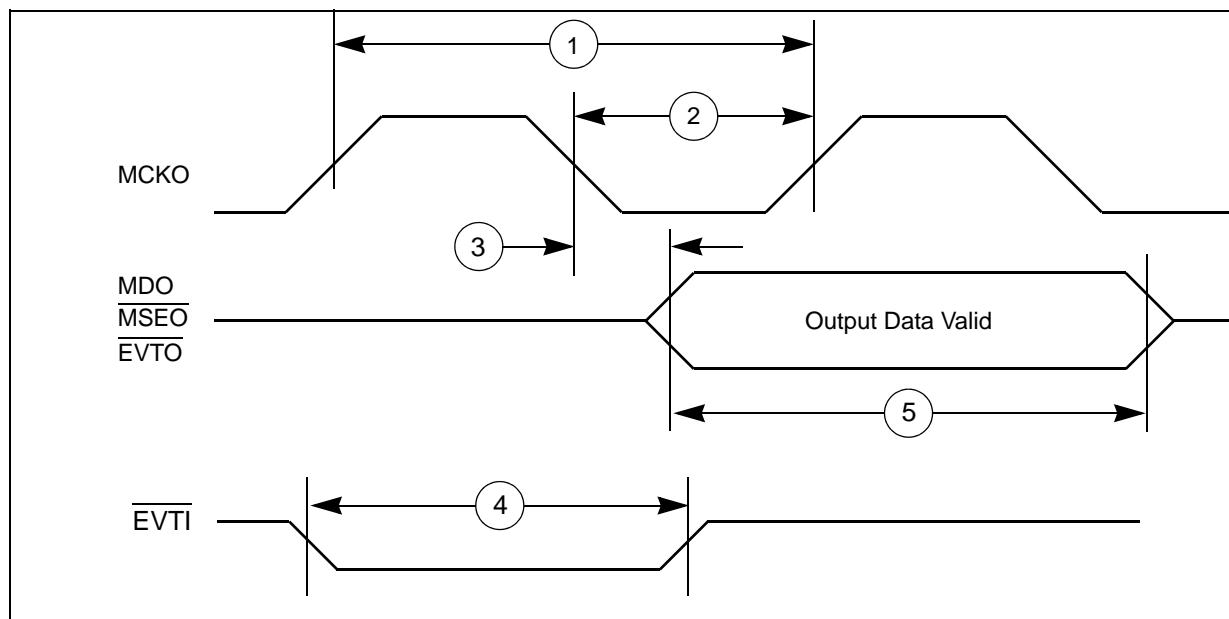


Figure 33. Nexus output timing

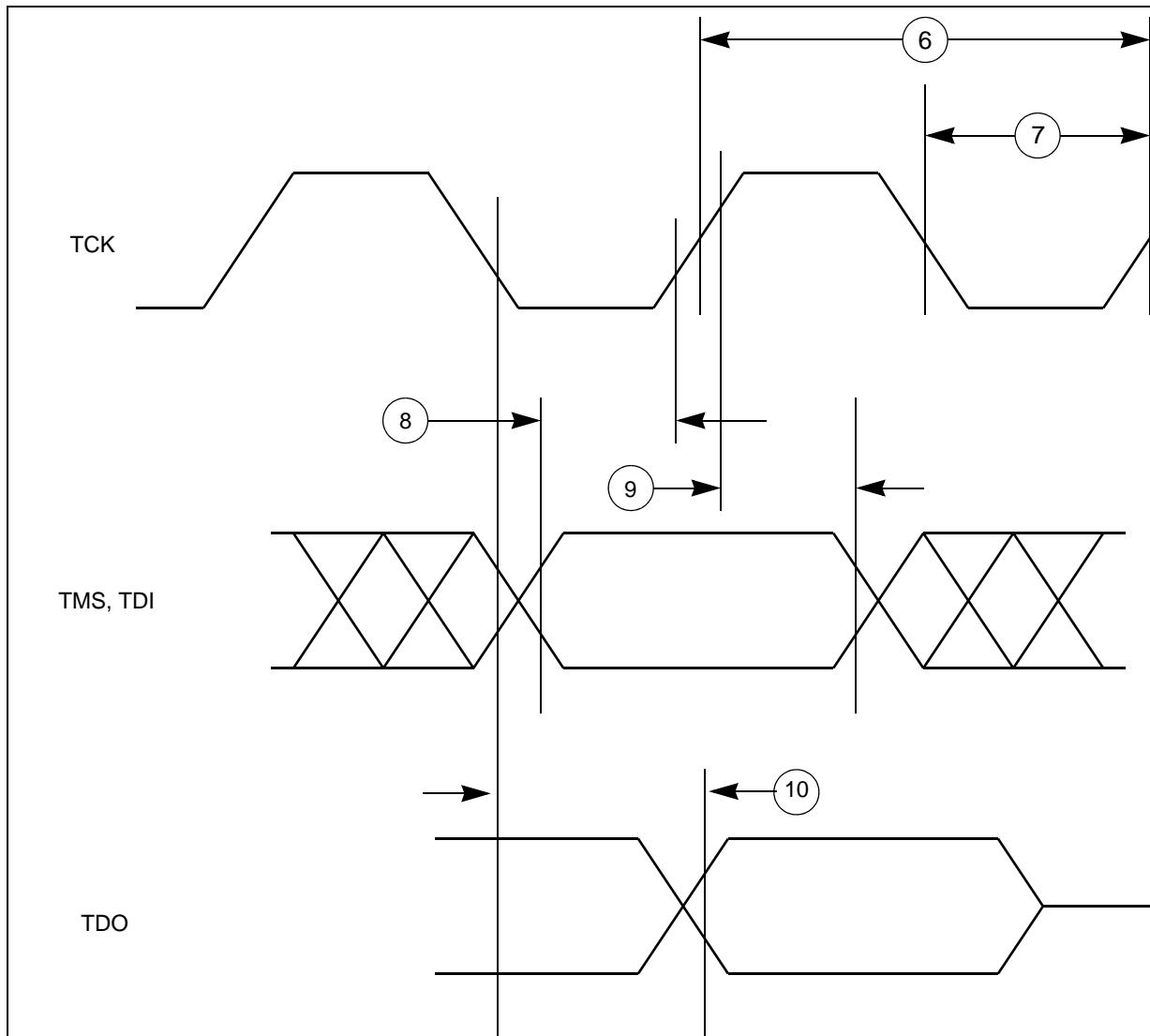


Figure 34. Nexus TDI, TMS, TDO timing

#### 4.19.4 JTAG characteristics

Table 51. JTAG characteristics

No.	Symbol	C	Parameter	Value			Unit	
				Min	Typ	Max		
1	$t_{JCYC}$	CC	D	TCK cycle time	64	—	—	ns
2	$t_{TDIS}$	CC	D	TDI setup time	10	—	—	ns
3	$t_{TDIH}$	CC	D	TDI hold time	5	—	—	ns
4	$t_{TMSS}$	CC	D	TMS setup time	10	—	—	ns
5	$t_{TMSH}$	CC	D	TMS hold time	5	—	—	ns

Table 51. JTAG characteristics (continued)

No.	Symbol	C	Parameter	Value			Unit
				Min	Typ	Max	
6	$t_{TDOV}$	CC	TCK low to TDO valid	—	—	33	ns
7	$t_{TDOI}$	CC	TCK low to TDO invalid	6	—	—	ns
—	$t_{TDC}$	CC	TCK Duty Cycle	40	—	60	%
—	$t_{TCKRISE}$	CC	TCK Rise and Fall Times	—	—	3	ns

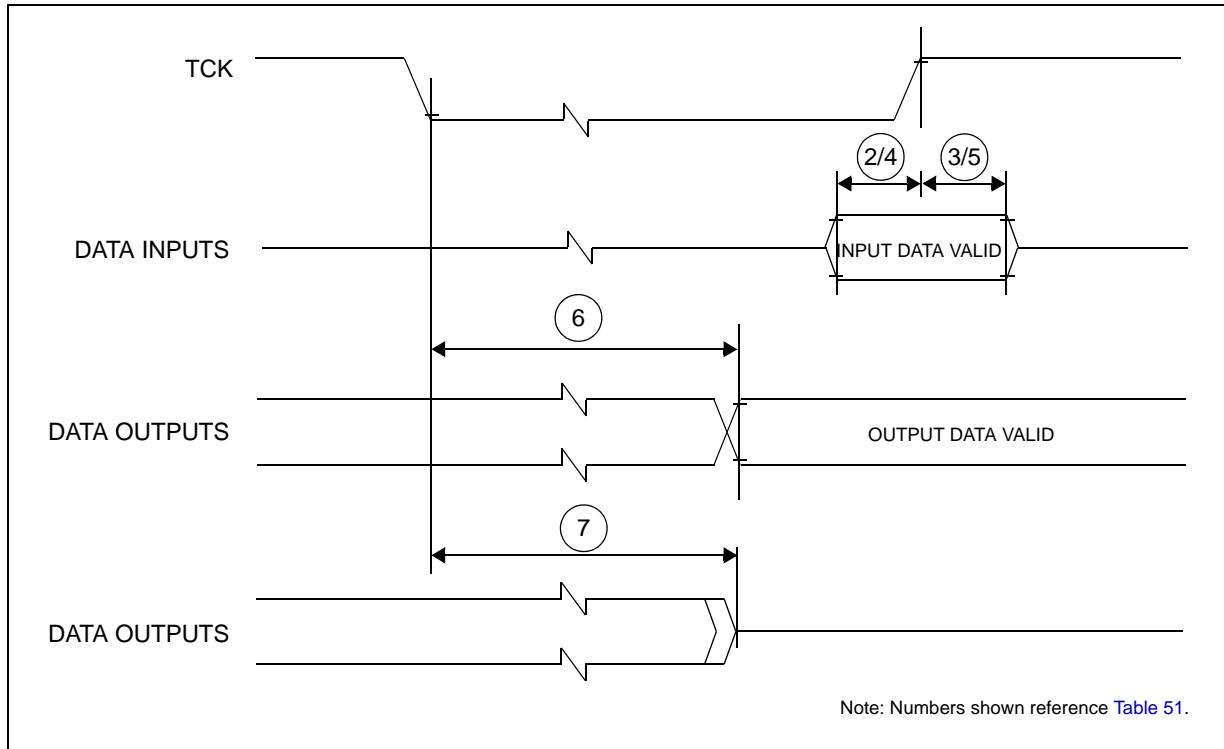


Figure 35. Timing diagram - JTAG boundary scan

## 5 Package characteristics

### 5.1 Package mechanical data

#### 5.1.1 176 LQFP package mechanical drawing

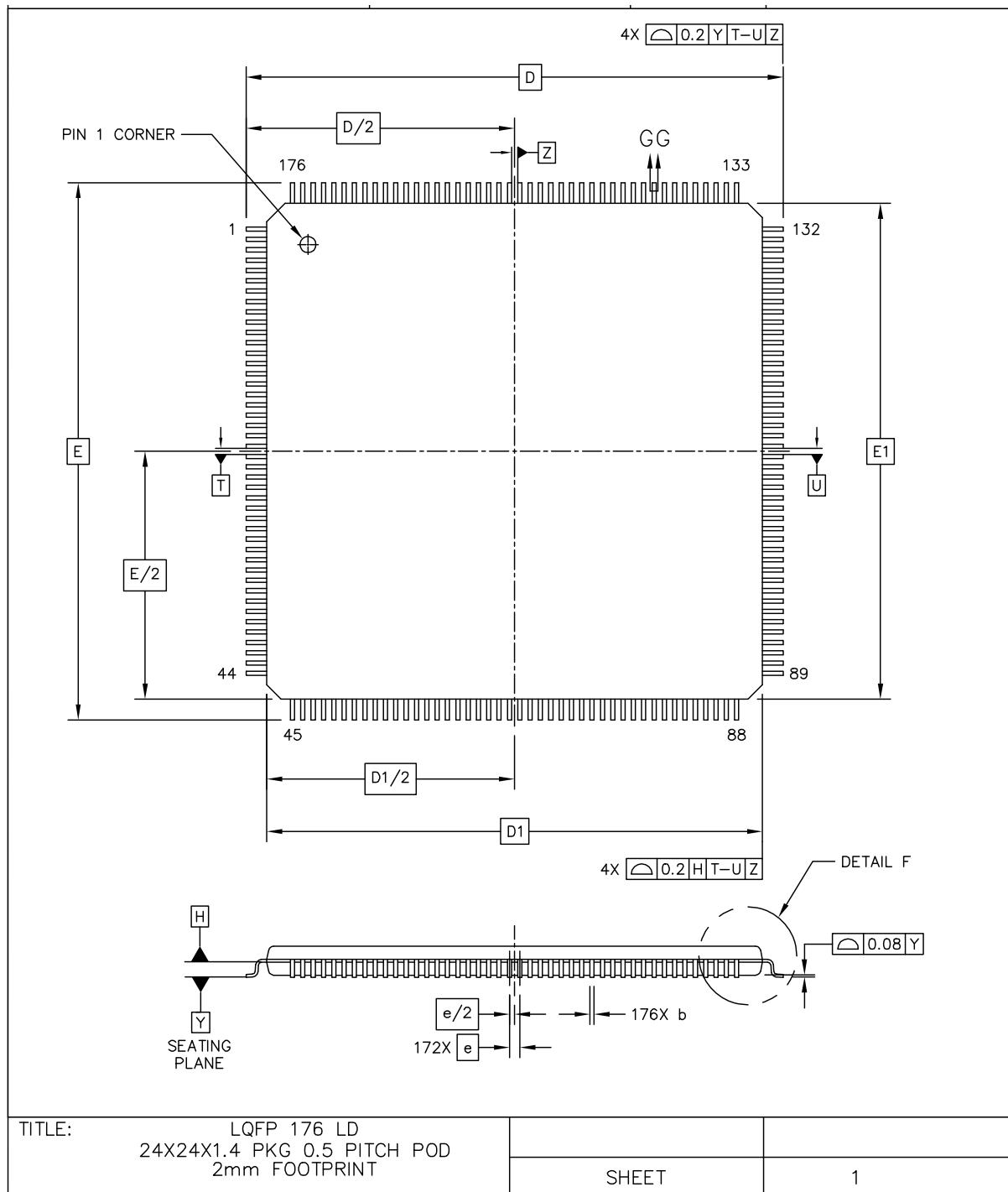


Figure 36. 176 LQFP mechanical drawing (Part 1 of 3)

## Package characteristics

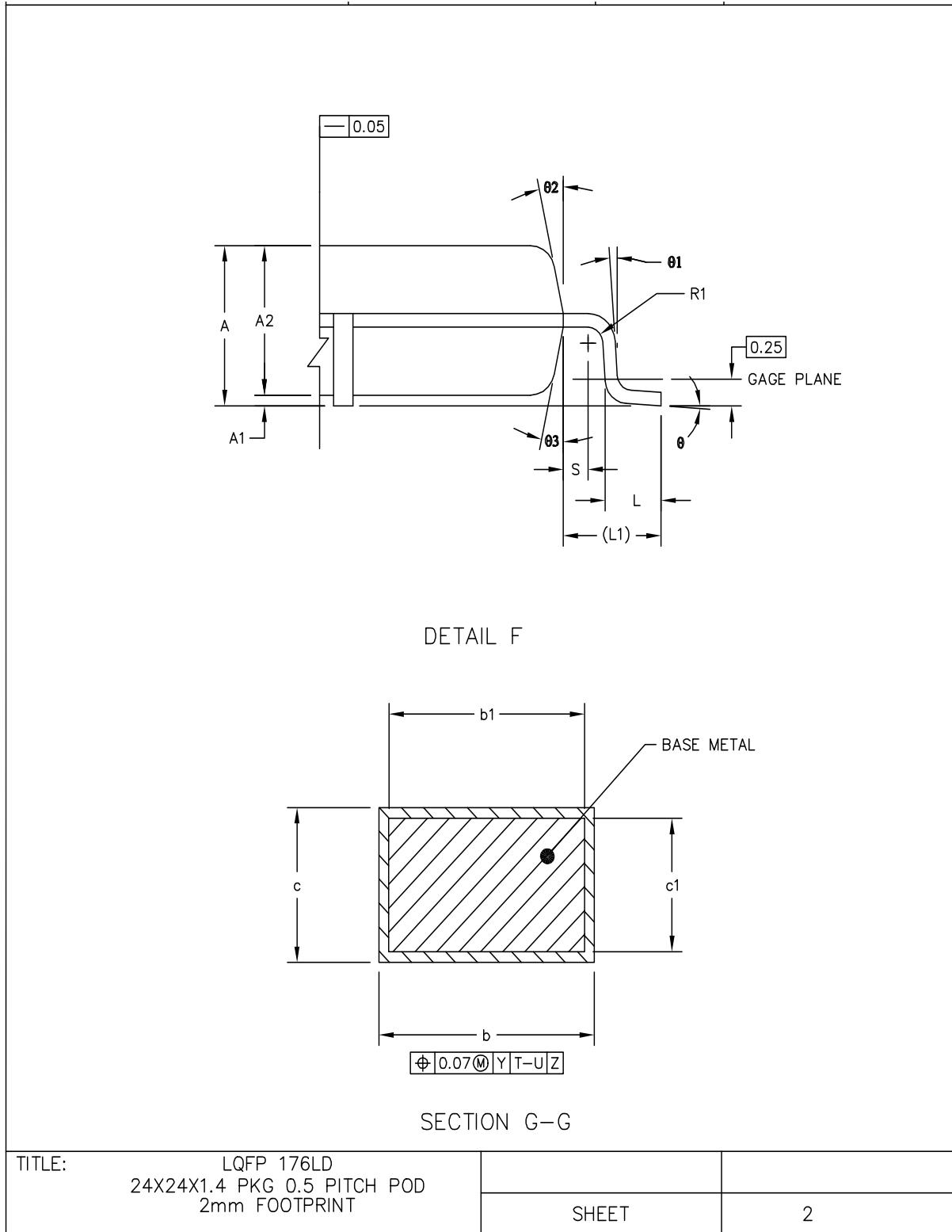


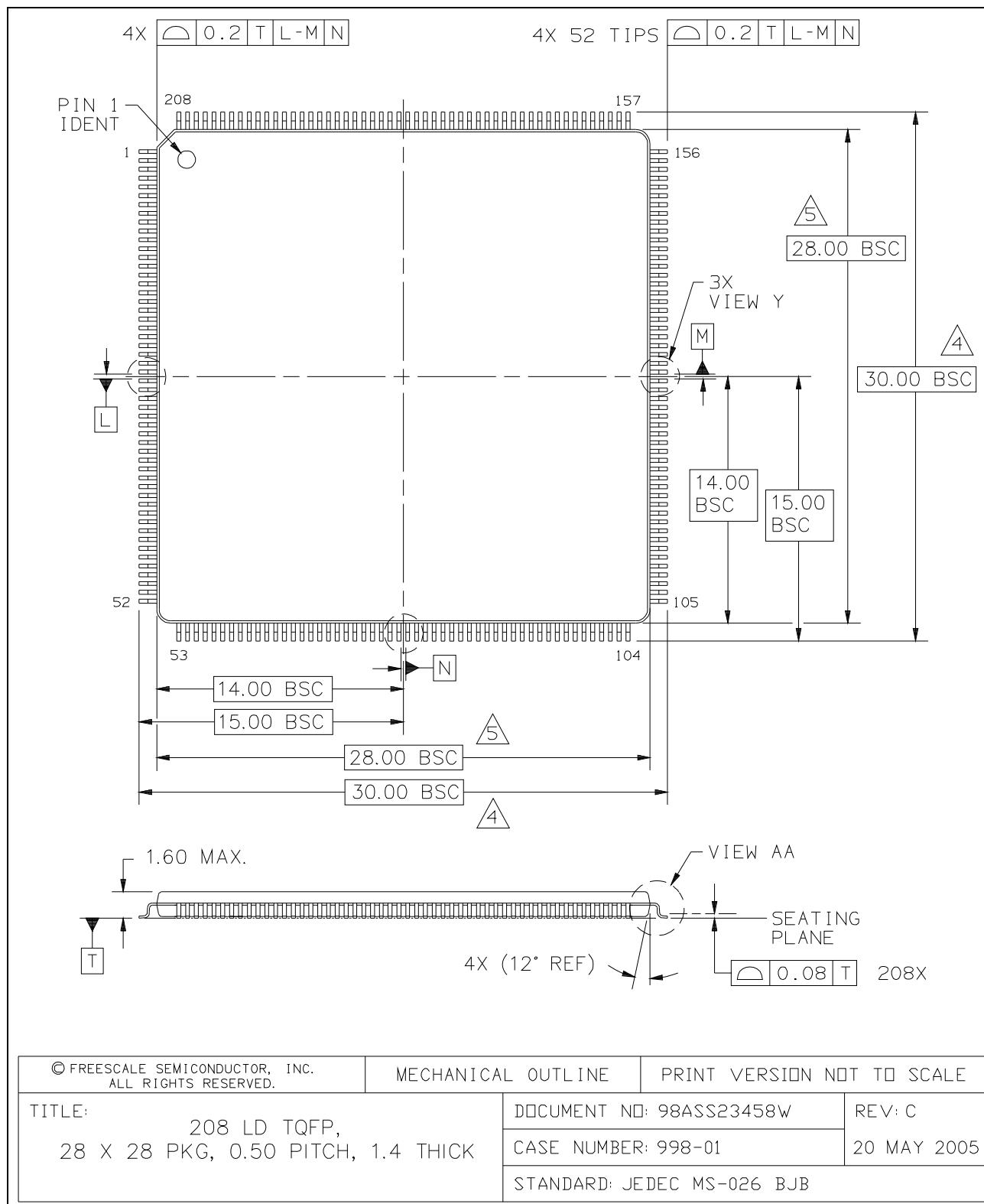
Figure 37. 176 LQFP mechanical drawing (Part 2 of 3)

NOTES:											
DIM	MIN	NOM	MAX	DIM	MIN	NOM	MAX	DIM	MIN	NOM	MAX
A	---	1.6		L1	1	REF					
A1	0.05	0.15		R1	0.08	---					
A2	1.35	1.4	1.45	R2	0.08	0.2					
b	0.17	0.22	0.27	S	0.2	REF					
b1	0.17	0.2	0.23	Ø	0°	3.5°	7°				
c	0.09	0.2		Ø1	0°	---					
c1	0.09	0.16		Ø2	11°	12°	13°				
D	26	BSC		Ø3	11°	12°	13°				
D1	24	BSC									
e	0.5	BSC									
E	26	BSC									
E1	24	BSC									
L	0.45	0.6	0.75		UNIT	DIMENSION AND TOLERANCES		REFERENCE DOCUMENT			
					MM	ASME Y14.5M		64-06-280-1392			
TITLE: LQFP 176LD 24X24X1.4 PKG 0.5 PITCH POD 2mm FOOTPRINT									SHEET		
									3		

Figure 38. 176 LQFP mechanical drawing (Part 3 of 3)

## 5.1.2 208 LQFP package mechanical drawing

## Package characteristics



**Figure 39. 208 LQFP mechanical drawing (Part 1 of 3)**

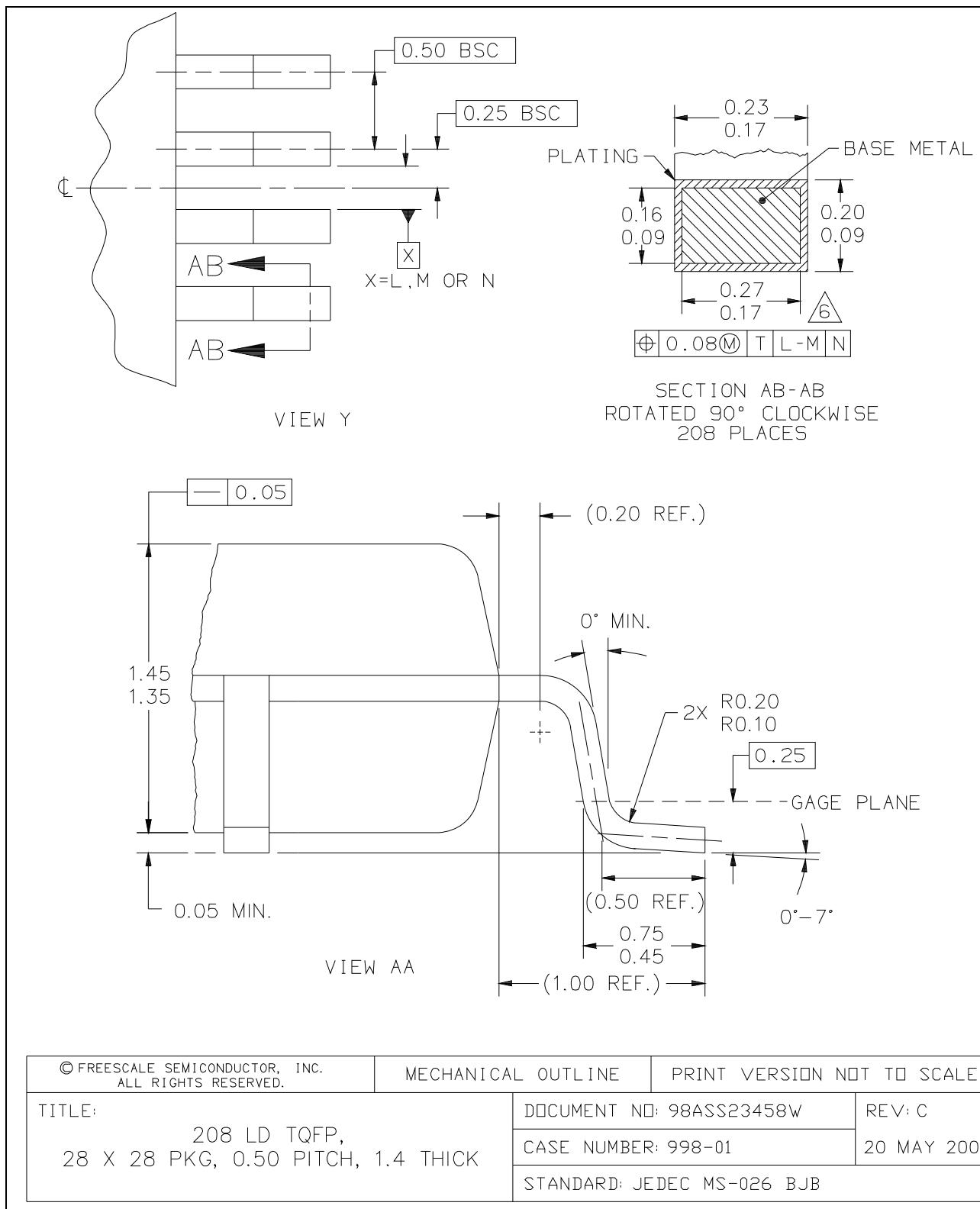


Figure 40. 208 LQFP mechanical drawing (Part 2 of 3)

## Package characteristics

### NOTES

1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M-1994.
2. DIMENSIONS IN MILLIMETERS.
3. DATUMS L, M AND N TO BE DETERMINED AT THE SEATING PLANE, DATUM T.
4. DIMENSIONS TO BE DETERMINED AT SEATING PLANE, DATUM T.
5. DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 PER SIDE. DIMENSIONS INCLUDE MOLD MISMATCH.
6. DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED 0.35. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD 0.07.

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TITLE:  208 LD TQFP, 28 X 28 PKG, 0.50 PITCH, 1.4 THICK	DOCUMENT NO: 98ASS23458W	REV: C
	CASE NUMBER: 998-01	20 MAY 2005
	STANDARD: JEDEC MS-026 BJB	

Figure 41. 208 LQFP mechanical drawing (Part 3 of 3)



## Package characteristics

### 5.1.3 256 MAPBGA package mechanical drawing

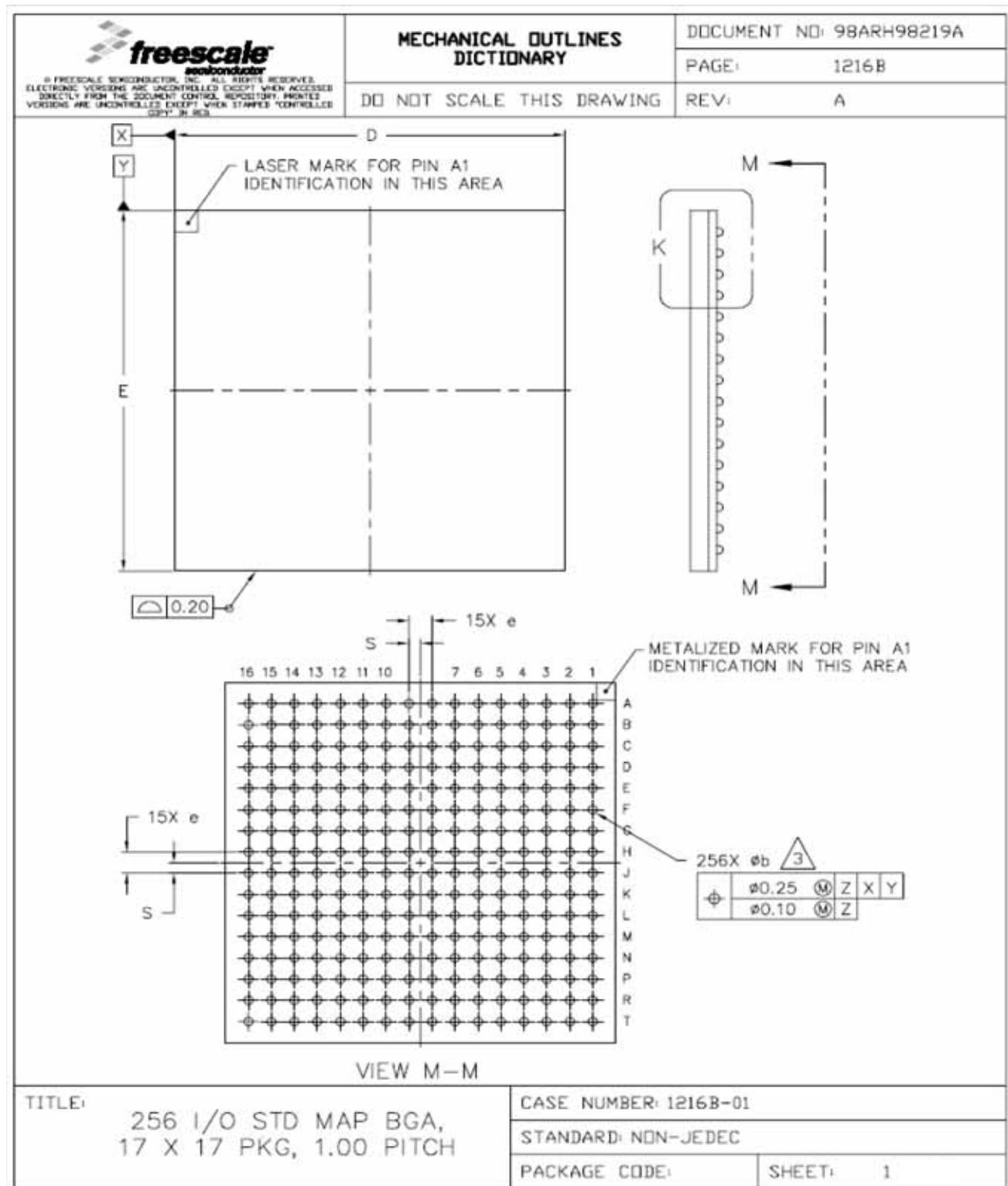


Figure 42. 256 MAPBGA mechanical drawing (Part 1 of 2)

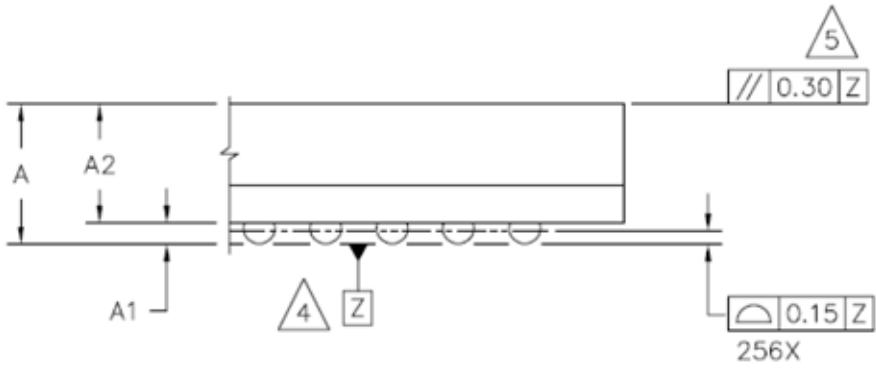
 <p>© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED. ELECTRONIC VERSIONS ARE UNCONTROLED. EXCEPT WHEN ACCESSED DIRECTLY FROM THE DOCUMENT CONTROL REPOSITORY, PRINTED VERSIONS ARE UNCONTROLED EXCEPT WHEN STAMPED "CONTROLLED COPY" IN RED.</p>	MECHANICAL OUTLINES DICTIONARY		DOCUMENT NO: 98ARH98219A																																			
	DO NOT SCALE THIS DRAWING		PAGE: 1216B																																			
			REV: A																																			
 <p>DETAIL K ROTATED 90° CLOCKWISE</p> <table border="1"> <thead> <tr> <th>DIM</th><th>MIN</th><th>MAX</th><th>NOTES</th></tr> </thead> <tbody> <tr> <td>A</td><td>1.25</td><td>1.60</td><td>1. DIMENSIONS ARE IN MILLIMETERS.</td></tr> <tr> <td>A1</td><td>0.27</td><td>0.47</td><td>2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.</td></tr> <tr> <td>A2</td><td>1.16 REF</td><td></td><td></td></tr> <tr> <td>b</td><td>0.40</td><td>0.60</td><td>3 DIMENSION b IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER, PARALLEL TO DATUM PLANE Z.</td></tr> <tr> <td>D</td><td>17.00 BSC</td><td></td><td></td></tr> <tr> <td>E</td><td>17.00 BSC</td><td></td><td>4 DATUM Z (SEATING PLANE) IS DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.</td></tr> <tr> <td>e</td><td>1.00 BSC</td><td></td><td></td></tr> <tr> <td>S</td><td>0.50 BSC</td><td></td><td>5 PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.</td></tr> </tbody> </table>	DIM	MIN	MAX	NOTES	A	1.25	1.60	1. DIMENSIONS ARE IN MILLIMETERS.	A1	0.27	0.47	2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.	A2	1.16 REF			b	0.40	0.60	3 DIMENSION b IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER, PARALLEL TO DATUM PLANE Z.	D	17.00 BSC			E	17.00 BSC		4 DATUM Z (SEATING PLANE) IS DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.	e	1.00 BSC			S	0.50 BSC		5 PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.	<p>TITLE: 256 I/O STD MAP BGA, 17 X 17 PKG, 1.00 PITCH</p> <p>CASE NUMBER: 1216B-01</p> <p>STANDARD: NON-JEDEC</p> <p>PACKAGE CODE: SHEET: 2</p>	
DIM	MIN	MAX	NOTES																																			
A	1.25	1.60	1. DIMENSIONS ARE IN MILLIMETERS.																																			
A1	0.27	0.47	2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.																																			
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e	1.00 BSC																																					
S	0.50 BSC		5 PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.																																			

Figure 43. 256 MAPBGA mechanical drawing (Part 2 of 2)

## 6 Ordering information

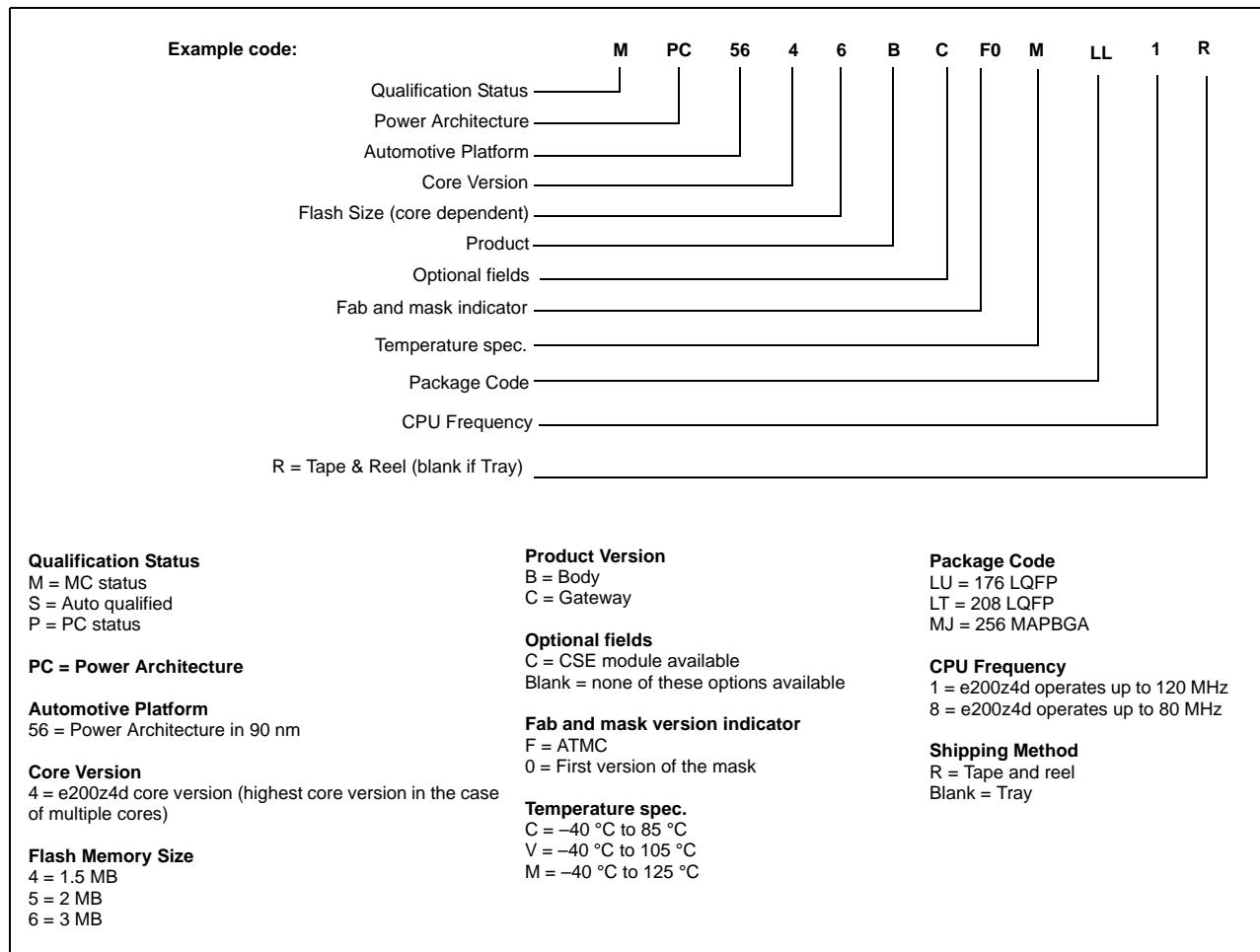


Figure 44. Commercial product code structure

## 7 Revision history

Table 52 summarizes revisions to this document.

**Table 52. Revision history**

Revision	Date	Changes
1	15 April 2010	Initial Release
2	17 Aug 2010	<ul style="list-style-type: none"> <li>• Editing and formatting updates throughout the document.</li> <li>• Updated Voltage regulator capacitance connection figure.</li> <li>• Added a new sub-section “V<sub>DD_BV</sub> Options”</li> <li>• Program and erase specifications: <ul style="list-style-type: none"> <li>-Updated Tdwprogram TYP to 22 us</li> <li>-Updated T128Kperase Max to 5000 ms</li> <li>-Added t<sub>ESUS</sub> parameter</li> </ul> </li> <li>• Added 208 MAPBGA thermal characteristics</li> <li>• Added recommendation in the Voltage regulator electrical characteristics section.</li> <li>• Added Crystal description table in Fast external crystal oscillator (4 to 140 MHz) electrical characteristics section and corrected the cross-reference to the same.</li> <li>• Added new sections - Pad types, System pins and functional ports</li> <li>• Updated TYP numbers in the Flash program and erase specifications table</li> <li>• Added a new table: Program and erase specifications (Data Flash)</li> <li>• Flash read access timing table: Added Data flash memory numbers</li> <li>• Flash power supply DC electrical characteristics table: Updated IDFREAD and IDFMOD values for Data flash, Removed IDFLPW parameter</li> <li>• Updated feature list.</li> <li>• Bolero 3M family comparison table: Updated ADC channels and added ADC footnotes.</li> <li>• Bolero 3M block diagram: Updated ADC channels and added legends.</li> <li>• Bolero 3M series block summary: Added new blocks.</li> <li>• Functional Port Pin Descriptions table: Added OSC32k_XTAL and OSC32k_EXTAL function at PB8 and PB9 port pins.</li> <li>• Electrical Characteristics: Replaced VSS with VSS_HV throughout the section.</li> <li>• Absolute maximum ratings, Recommended operating conditions (3.3 V) and Recommended operating conditions (5.0 V) tables: VRC_CTRL min is updated to "0".</li> <li>• Recommended operating conditions (3.3 V) and Recommended operating conditions (5.0 V) tables: Clarified VIN parameter, clarified footnote 2 in both tables.</li> <li>• LQFP thermal characteristics section: Updated numbers for LQFP packages.</li> <li>• Low voltage power domain electrical characteristics table: Clarified footnotes based upon review comments.</li> <li>• Code flash memory—Program and erase specifications: Updated tESRT to 20 ms.</li> <li>• ADC electrical characteristics section: Replace ADC0 with ADC_0 and ADC1 with ADC_1 throughout the document.</li> <li>• DSPI characteristics section: Replaced PCSx with CSx in all figures and tables.</li> </ul>

## Revision history

**Table 52. Revision history (continued)**

Revision	Date	Changes
3	28 April 2011	<ul style="list-style-type: none"> <li>• Replaced VIL min from <math>-0.4\text{ V}</math> to <math>-0.3\text{ V}</math> in the following tables:           <ul style="list-style-type: none"> <li>- I/O input DC electrical characteristics</li> <li>- Reset electrical characteristics</li> <li>- Fast external crystal oscillator (4 to 40 MHz) electrical characteristics</li> </ul> </li> <li>• Updated Crystal oscillator and resonator connection scheme figure</li> <li>• Specified NPN transistor as the recommended BCP68 transistor throughout the document</li> <li>• Code and Data flash memory—Program and erase specifications tables:           <ul style="list-style-type: none"> <li>Renamed the parameter <math>t_{ESUS}</math> to <math>T_{Teslat}</math></li> <li>Revised the footnotes in the “Functional port pin descriptions” table.</li> </ul> </li> <li>• In the “System pin descriptions” table, added a footnote to the A pads regarding not using IBE. For ports PB[12–15], changed ANX to ADC0_X.</li> <li>• Revised the presentation of the ADC functions on the following ports:  <math>\text{PB}[4\text{--}7]</math>  <math>\text{PD}[0\text{--}11]</math> </li> <li>• ADC conversion characteristics (10-bit ADC_0) table and Conversion characteristics (12-bit ADC_1) table- Updated footnote 5 and 7 respectively for the definition of the conversion time.</li> <li>• Data flash memory—Program and erase specifications: Updated <math>T_{wprogram}</math> to 500 <math>\mu\text{s}</math> and <math>T_{16\text{K}perase}</math> to 500 <math>\mu\text{s}</math>. Corrected Teslat classification from “C” to “D”.</li> <li>• Code flash memory—Program and erase specifications: Corrected Teslat classification from “C” to “D”.</li> <li>• Flash Start-up time/Switch-off time: Changed <math>T_{FLARSTEXIT}</math> classification from “C” to “D”.</li> <li>• Functional port pin description: Added a footnote at the PB [9] port pin.</li> <li>• Absolute maximum ratings table: Added footnote 1.</li> <li>• Low voltage power domain electrical characteristics table: Updated IDDHALT, IDDSTOP, IDDSTBY3, IDDSTDBY2, IDDSTDBY1.</li> <li>• Slow external crystal oscillator (32 kHz) electrical characteristics table: Updated <math>9_{\text{m}}\text{SXOSC}</math>, <math>V_{\text{SXOSC}}</math>, <math>I_{\text{SXOSCBIAS}}</math> and <math>I_{\text{SXOSC}}</math>.</li> <li>• FMPLL electrical characteristics table: Updated <math>\Delta t_{LTJIT}</math>.</li> <li>• Fast internal RC oscillator (16 MHz) electrical characteristics table: Updated TFIRCSU and IFIRCPWD.</li> <li>• MII serial management channel timing table: Updated M12</li> <li>• JTAG characteristics table: Updated <math>t_{TDOV}</math>.</li> <li>• Low voltage monitor electrical characteristics table: Updated VLVDHV3H, VLVDHV3L, VLVDHV5H, VLVDHV5L.</li> <li>• DSPI electricals table: Updated spec 1, 5, 6. Updated footnote 2 and 3. Added <math>\Delta t_{CSC}</math>, <math>\Delta t_{ASC}</math>, <math>t_{SUSS}</math>, <math>t_{HSS}</math>.</li> <li>• IO consumption table: Updated all parameter values.</li> <li>• DSPI electricals: Updated <math>\Delta t_{CSC}</math> max to 115 ns.</li> <li>• Low voltage power domain electrical characteristics table: Added footnote 9.</li> <li>• ADC electrical characteristics: Added 2 notes above 10-bit and 12-bit conversion tables.</li> </ul>

**Table 52. Revision history (continued)**

Revision	Date	Changes
4	23 June 2011	<ul style="list-style-type: none"> <li>• Interchanged the denominator with numerator in Equation 11 of Input impedance and ADC accuracy section</li> <li>• Removed the note (All ADC conversion characteristics described in the table below are applicable only for the precision channels. The data for semi-precision and extended channels is awaited and same will be subsequently updated in later revs.) in the ADC electrical characteristics section.</li> <li>• In On-chip peripherals current consumption table, replaced IDD_HV_ADC with IDD_HV_ADC0 and IDD_HV_ADC1 values as per ADC specs</li> <li>• In ADC conversion characteristics (10-bit ADC_0) table, the minimum sample time of ADC0 changed to 500 at 32 MHz</li> <li>• In ADC conversion characteristics (10-bit ADC_0) table, removed the entry for sample time at 30 MHz</li> <li>• In Conversion characteristics (12-bit ADC_1)table, changed TUEX to TUES and INLX to INLS (Extended channels are not supported by the device. So, changed to standard channel.)</li> </ul>

## Revision history

**Table 52. Revision history (continued)**

Revision	Date	Changes
5	21 June 2012	<ul style="list-style-type: none"> <li>• Updated the pins 23 and 24 of <a href="#">Figure 2</a>.176-pin LQFP configuration</li> <li>• Updated unit of measure in <a href="#">Table 43</a> Conversion characteristics (12-bit ADC_1)</li> <li>• Modified the value to typical value in <a href="#">Table 48</a> On-chip peripherals current consumption</li> <li>• Added footnote to <math>t_{ESRT}</math> parameter in <a href="#">Table 25</a> Code flash memory—Program and erase specifications</li> <li>• Added footnote to <math>t_{ESRT}</math> parameter in <a href="#">Table 26</a> Data flash memory—Program and erase specifications</li> <li>• Updated <a href="#">Table 28</a> Flash memory read access timing.</li> <li>• Updated Notes 2 and Notes 3 of <a href="#">Table 9</a> Recommended operating conditions (3.3 V) and <a href="#">Table 10</a> Recommended operating conditions (5.0 V) respectively.</li> <li>• Updated the footnote1 of <a href="#">Table 9</a> Recommended operating conditions (3.3 V) and <a href="#">Table 10</a> Recommended operating conditions (5.0 V)</li> <li>• Updated <math>V_{DD\_HV\_A}</math> to <math>V_{DD\_BV}</math> for <math>C_{DEC2}</math> and <math>I_{DD\_HV\_A}</math> in <a href="#">Table 22</a> Voltage regulator electrical characteristics and deleted footnote3</li> <li>• Updated the dedicated number of channels for 12-bit ADC in family comparison tables</li> <li>• Updated the values of <math>f_{SIRC}</math>, parameters and conditions of <math>\Delta_{SIRCVAR}</math> in <a href="#">Table 40</a> Slow internal RC oscillator (128 kHz) electrical characteristics</li> <li>• Updated second footnote in <a href="#">Table 10</a>, Recommended operating conditions (5.0 V)</li> <li>• Updated the value of <math>t_{ADC0\_PU}</math> in <a href="#">Table 42</a>, ADC conversion characteristics (10-bit ADC_0)</li> <li>• Updated the IDD values in <a href="#">Table 24</a>, Low voltage power domain electrical characteristics</li> <li>• Added footnote to <a href="#">Table 24</a>, Low voltage power domain electrical characteristics related to current drawn from <math>V_{DD\_HV\_A}</math> and <math>V_{DD\_HV\_B}</math></li> <li>• Updated entire <a href="#">Section 4.17.1.1</a>, “Input impedance and ADC accuracy”- Updated the values of VLPREG in <a href="#">Table 22</a>, Voltage regulator electrical characteristics.</li> <li>• Updated the values of <math>V_{LPREG}</math> in <a href="#">Table 22</a>, Voltage regulator electrical characteristics.</li> <li>• Added <math>T_A = 25^\circ C</math>, min and max values of <math>V_{MREG}</math> in <a href="#">Table 22</a>, Voltage regulator electrical characteristics</li> <li>• Added <math>T_A = 25^\circ C</math>, min and max values of <math>V_{LPREG}</math> in <a href="#">Table 22</a>, Voltage regulator electrical characteristics</li> <li>• Updated the min, max and typical values of <math>V_{LVDLVCORL}</math> and <math>V_{LVDLVBKPL}</math> in <a href="#">Table 23</a>, Low voltage monitor electrical characteristics</li> <li>• Updated values of gmFXOSC in <a href="#">Table 35</a>, Fast external crystal oscillator (4 to 40 MHz) electrical characteristicsUpdated values of gmSXOSC in <a href="#">Table 37</a>, Slow external crystal oscillator (32 kHz) electrical characteristics</li> <li>• Updated the footnote 5 for <math>T_{ADC0\_C}</math> in <a href="#">Table 42</a>, ADC conversion characteristics (10-bit ADC_0)</li> <li>• Updated the footnotes of <a href="#">Table 24</a>, Low voltage power domain electrical characteristics</li> </ul>
5.1	15 Aug 2012	<ul style="list-style-type: none"> <li>• Removed Footer: Preliminary tag</li> </ul>

## NOTE

This revision history uses clickable cross-references for ease of navigation. The numbers and titles in each cross-reference are relative to the latest published release.

# Appendix A

## Abbreviations

Table 53 lists abbreviations used but not defined elsewhere in this document.

**Table 53. Abbreviations**

Abbreviation	Meaning
CS	Chip select
EVTO	Event out
MCKO	Message clock out
MDO	Message data out
MSEO	Message start/end out
MTFE	Modified timing format enable
SCK	Serial communications clock
SOUT	Serial data out
TBD	To be defined
TCK	Test clock input
TDI	Test data input
TDO	Test data output
TMS	Test mode select



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